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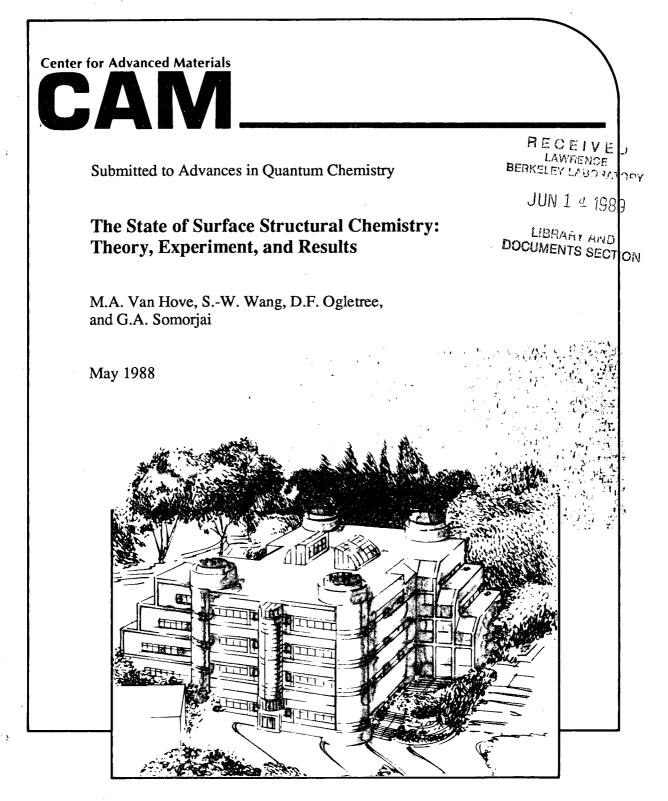
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### The State of Surface Structural Chemistry: Theory, Experiment, and Results

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### THE STATE OF SURFACE STRUCTURAL CHEMISTRY THEORY, EXPERIMENT AND RESULTS

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#### 1. INTRODUCTION

2

### 2. EXPERIMENTAL TECHNIQUES FOR SURFACE STRUCTURE DETERMINATION

- 2.1. Electron Diffraction Techniques
- 2.2. Fine Structure Techniques
- 2.3. Surface Topography Techniques

2.4. Ion Scattering

2.5. Complementary Techniques

3. THE THEORY OF MODERN TECHNIQUES FOR SURFACE STRUCTURE ANALYSIS

- 3.1. General Four-Step Description of
  - · Electron-Diffraction Techniques

3.2. Structural Information

3.3. Theoretical Aspects of Individual Techniques

3.4. Formalism for Individual Processes

3.5. Unifying and Distinguishing Features

4. THE THEORY OF SURFACE CHEMISTRY AND BONDING

4.1. The Extended Hückel Theory and Applications

4.2. The SCF  $X\alpha$  Scattered Wave Method

4.3. SCF- $X\alpha$ -SW Calculations

4.4. Results of the  $X\alpha$ -Method

4.5. The Hartree-Fock-Slater Method and Its Applications

4.6. The ab initio Quantum Chemical Calculation

4.7. Conclusion

5. RESULTS OF SURFACE CRYSTALLOGRAPHY

5.1. Ordering Principles

5.2. Notation for surface lattices

5.3. Numbers and types of solved surface structures

5.4. Major trends among surface structures

6. FUTURE NEEDS AND DIRECTIONS OF SURFACE STUDIES

#### 1. INTRODUCTION

The atomic and molecular structures of clean solid surfaces and of monolayers of adsorbed molecules are at the heart of most problems in surface science. The surface chemical bond can be investigated by determining the bond distances and bond angles of surface atoms with respect to their neighbors. Changes of surface structure with temperature, adsorbate coverage and surface composition are important ingredients of surface phenomena, including catalysis, corrosion, surface phase transformations (reconstruction, sintering, crystal growth and evaporation) and lubrication. During the last ten years profound changes have occurred in surface science that resulted in the rapid improvement of our understanding of surface structure. Electron, atom and ion scattering techniques proved to be very sensitive to the surface monolayer structure and composition. High intensity photon fluxes can also be employed in ways to obtain high surface structure sensitivity.

Low energy electron diffraction (LEED) has produced most of the information on surface structure, while other techniques increasingly contribute to the data base. From these studies we learned that clean and flat solid surfaces often restructure; atoms often "relax" to shorten the first interlayer distance or seek new equilibrium positions that alter the long range order of the surface (reconstruction). Atoms of more open, rough surfaces relax more readily and often exhibit periodic steps of one atom in height. The surface composition of polyatomic solids (alloys, oxides, sulfides, etc.) can be very different from that in the bulk, resulting in altered atomic surface structures. Adsorbed atoms and molecules often form ordered two-dimensional layers. The structure and bonding in these layers changes with coverage and temperature.

The two-dimensional world of surface structural chemistry is rich, diverse, and full of surprises that reflect our incomplete knowledge of bonding and chemical interactions in the surface phase. This review attempts to summarize much of the knowledge that was gained in recent years.

We first discuss the various experimental methods of surface structure determination. Next we discuss the theoretical questions that arise when experimental data are analyzed to obtain surface chemical bond distances and angles, in particular the problem of electron propagation in solids, and the progress that has been made in answering these questions. A number of important techniques in addition to LEED rely on a proper understanding of electron propagation in solids to enable surface structure determination. This is followed by a discussion of the application of theoretical quantum chemistry to the calculation of the structure and bonding of chemisorbed atoms and molecules. Various calculational methods are reviewed, along with the results that have been obtained. The last section of this review surveys the surface structural results that have become available, ranging from clean surfaces to reconstructed

3

surfaces, multi-component systems and chemisorbed atoms and molecules. In conclusion we indicate the needs and possible directions for future studies of . surface structural chemistry.

### 2. EXPERIMENTAL TECHNIQUES FOR SURFACE STRUCTURE DETERMINATION

Most quantitative information on surface structure and chemical bonding comes from studies of the solid-vacuum interface. In large part this is because the most powerful probes of surface structure rely on the propagation of electron, ion or atom beams. New developments such as the scanning tunneling microscope (STM), which can also investigate the solid-gas and solid-liquid interface, and new optical techniques, which can potentially investigate all types of surfaces and interfaces, may greatly extend our understanding of surface structural chemistry in the future. At this time, however, the solid-vacuum interface is the focus of most active investigations in surface structural chemistry. In this chapter we review the major experimental methods used in the study of surface structure and their application, along with recent experimental developments.

The majority of the known surface structures have been solved by comparing experimental data with theoretical predictions based on models of the surface. A theoretical description of the interaction of the probe with the surface is used to calculate spectra for a given model geometry (see part 3). Different geometries are tried, and structural parameters within a given model are varied, until a good fit is obtained between the experimental data and the theoretically calculated spectra. This basic approach has been used to interpret results from low-energy electron diffraction (LEED) and other electron diffraction techniques, as well as from helium diffraction and ion scattering.

Structural information has also been obtained by matching the observed frequencies of surface vibrational and electronic excitations with spectra calculated from structural models (see part 4). This approach has been applied to the frequencies of electronic states as measured by angle-resolved ultra-violet photo-emission (ARUPS) and to the frequencies of vibrational excitations as measured by high-resolution electron energy-loss spectroscopy (HREELS).

There has been an ongoing search for a way to "image" surface structure directly from experimental results without fitting experimental data to theoretical calculations for model systems. So far this search has not been successful, although certain techniques yield more direct information for some special cases. Structure sensitive techniques such as scanning tunneling microscopy (STM) and field ionization microscopy (FIM) do give results that can be interpreted directly, but these results do not provide complete information on atomic coordinates in the near-surface region. Extended fine-structure techniques provide direct information on bond-lengths in many cases, but this is sometimes insufficient to fully determine the surface structure.

Most surface structural studies combine results from several different surface science techniques applied to the same system. For an approach based on model calculations to be successful, it is necessary to construct reasonable structural models of surfaces. The application of techniques which cannot give explicit information on the arrangement of atoms in the near-surface region is often necessary to develop good surface structural models.

A wide range of techniques have been developed to study surfaces in vacuum, and many techniques are commonly referred to by acronyms. Table I lists acronyms and brief descriptions of most common techniques used in surface science.

#### 2.1. Electron Diffraction Techniques

The majority of known surface structures have been solved with electron diffraction techniques. Low energy electrons (below  $\sim 400 \text{ eV}$ ) interact strongly with atoms through both elastic and inelastic processes. Inelastic scattering in solids limits electrons with energies below a few hundred eV to a mean free path of  $\sim 2-20$  Å. Elastic interactions are strong enough that multiple scattering is important in this energy range, so elastically scattered electrons are sensitive to

5

TABLE	I.	Surface	Science	Techniques

Acronym	Name	Description
AD	Atom or Helium	Monoenergetic beams of thermal en-
	Diffraction	ergy neutral atoms are elasticly scat-
• ,		tered off of ordered surfaces and
		detected as a function of scattering angle. This gives structural informa-
		tion on the outermost layer of the
		surface. Atom diffraction is extreme-
		ly sensitive to surface ordering and
		defects.
AEAPS	Auger Electron Ap-	The EAPFS cross-section is moni-
• .	pearance Potential	tored by Auger electron intensity.
. · ·	Spectroscopy	Also known as APAES.
AES	Auger Electron Spec-	Core-hole excitations are created,
	troscopy	usually by 1-10 KeV incident elec-
		trons, and Auger electrons of charac-
•	•	teristic energies are emitted through
		a two-electron process as excited
•		atoms decay to their ground state.
•		AES gives information on the near-
	•	surface chemical composition.
	· · · · · · · · · · · · · · · · · · ·	
AFM	Atomic Force Micros-	Similar to STM. An extremely deli-
	copy	cate mechanical probe is used to scan
		the topography of a surface, and a
		STM-type tunneling-current probe is
		used to measure the deflection of the
		mechanical surface probe. This is
		meenanten entrace proces. and is

designed to provide STM-type im-

ages of insulating surfaces.

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Acronym	Name	Description
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APAES	Appearance Potential	See AEAPS.
	Auger Electron Spec-	
	troscopy	
APXPS	Appearance Potential	The EAPFS excitation cross-section
	X-ray Photoemission	is monitored by fluorescence from
	Spectroscopy	core-hole decay (also known as SXAPS).
ARAES	Angle-Resolved Auger	Auger electrons are detected as a
	Electron Spectroscopy	function of angle to provide informa
•		tion on the spatial distribution or en
		vironment of the excited atoms (see AES).
ARPEFS	Angle-Resolved	Electrons are detected at given an-
	Photo-Emission Fine	gles after being photoemitted by po
• •	Structure	larized synchrotron radiation. The
		interference in the detected photoen
		ission intensity as a function of elec-
	:	tron energy $\sim$ 100-500 eV above the
	<i>6</i> .	excitation threshold gives structural
		information.

Acronym	Name	Description
ARPES	Angle-Resolved Photo-Emission Spec- troscopy	A general term for structure sensitive photoemission techniques, including ARPEFS, ARXPS, ARUPS, and ARXPD.
ARUPS	Angle-Resolved Ultra- violet Photoemission Spectroscopy	Electrons photoemitted from the valence and conduction bands of a surface are detected as a function of angle. This gives information on the dispersion of these bands (which is related to surface structure), and also structural information from the diffraction of the emitted electrons.
ARXPD	Angle-Resolved X-ray Photoemission Diffraction	Similar to ARXPS and ARPEFS. The angular variation in the pho- toemission intensity is measured at a fixed energy above the excitation threshold to provide structural infor- mation.
ARXPS	Angle-Resolved X-ray Photoemission Spec- troscopy	The diffraction of electrons photoem- itted from core-levels gives structural information on the surface.

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Acronym Name Description

CEMS

Conversion-Electron Mössbauer Spectroscopy A surface-sensitive version of Mössbauer spectroscopy. Like Mössbauer Spectroscopy, this technique is limited to some isotopes of certain metals. After a nucleus is excited by ray absorbtion, it can undergo inverse  $\beta$ -decay, creating a corehole. The decay of core-holes by Auger processes within an electron mean free path of the surface produces a signal. Detecting emitted electrons as a function of energy gives some depth-profile information, because of the changing electron mean free path.

The EAPFS cross-section is monitored by variations in the intensity of electrons elasticly back-scattered from the surface.

DAPS

Dis-Appearance Potential Spectroscopy

Acronym	Name	Description
EAPFS	Electron Appearance	A fine-structure technique (see EX-
<b>D</b> . <b>H</b> I 5	Potential Fine-	AFS). Core-holes are excited by
	Structure	monoenergetic electrons at $\sim 1$ KeV.
	Structure	The modulation in the excitation
<i>,</i>		cross section may be monitored
	•	through adsorption, fluorescence, or
	алы	Auger emission.
· .	•	Auger emission.
ELNES	Electron energy-Loss	Similar to NEXAFS, except monoen-
	Near-Edge Structure	ergetic high-energy electrons $\sim$ 60-
		300 KeV excite core-holes.
ELS	Electron Energy Loss	Monoenergetic electrons $\sim$ 5-50 eV
	Spectroscopy	are scattered off a surface the energy
		losses are measured. This gives in-
		formation on the electronic excita-
		tions of the surface and adsorbed
· · ·		molecules (see HREELS). Sometimes
	·	called EELS.
ESCA	Electron Spectroscopy	Now generally called XPS.
	for Chemical Analysis	
	• •	
	· · · ·	

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Acronym	Name	· :	Description	
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Electron Stimulated Desorption Ion Angular Distribution

EXAFS

ESDIAD

Extended X-ray Adsorption Fine-Structure Electrons break chemical bonds in adsorbed atoms or molecules, causing ionized atoms or radicals to be ejected from the surface along the axis of the broken bond by Coulomb repulsion. The angular distribution of these ions gives information on the bonding geometry of adsorbed molecules.

Monoenergetic photons excite a core-hole. The modulation of the adsorption cross-section with energy  $\sim$ 100-500 eV above the excitation threshold yields information on the radial distances to neighboring atoms. The cross-section can be monitored by fluorescence as core-holes decay or by the attenuation of the transmitted photon beam. EXAFS is one of many "fine-structure" techniques. This is not intrinsicly surface sensitive (see SEXAFS).

Acronym	Name	Description
		······
EXELFS	Extended X-ray Ener-	A fine-structure technique similar to
	gy Loss Fine Struc-	EXAFS, except that 60-300 KeV
	ture .	electrons rather than photons excite
	· · · · · ·	core-holes. Like EXAFS, this tech-
		niques is not explicitly surface sensi-
		tive.
FIM	Field-Ionization Mi-	A strong electric field $\sim$
	croscopy	volts/angstrom is created at the tip
		of a sharp, single crystal wire. Gas
	· ·	atoms, usually He, are polarized and
		attracted to the tip by the strong
		electrostatic field, and then ionized
· .	· · ·	by electrons tunneling from the gas
· ·		atoms into the tip. These ions, ac-
		celerated along radial trajectories by
	· · · · · · · · · · · · · · · · · · ·	Coulomb repulsion, map out the
		variations in the electric-field
		variations in the electric-held

variations in the electric-field strength across the surface with atomic resolution, showing the surface topography.

Acronym	Name	Description
	<u></u>	
FTIR	Fourier-Transform	Broad-band IRAS experiments are
	Infra-Red spectros-	performed, and the IR adsorption
	сору	spectrum is deconvoluted by using a
		doppler-shifted source and Fourier analysis of the data. This technique
		is not restricted to surfaces.
HEIS	High-Energy Ion	High-energy ions, above $\sim 500~{ m KeV},$
	Scattering	are scattered off of a single crystal
	<ul> <li>A state of the sta</li></ul>	surface. The "channeling" and
		"blocking" of scattered ions within
		the crystal can be used to triangulate deviations from the bulk structure.
		HEIS has been used in particular to study surface reconstructions and the
		thermal vibrations of surface atoms
	1 - 1 <sup>2</sup> - 1	(see also MEIS, ISS)
HREELS	High-Resolution Elec-	A monoenergetic electron beam, usu-
	tron Energy Loss	ally $\sim$ 2-10 eV, is scattered off a sur-
	Spectroscopy	face and energy losses below $\sim 0.5$
		eV to bulk and surface phonons and
		vibrational excitations of adsorbates
		are measured as a function of angle
		and energy (also called EELS).

13

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Acronym	Name	Description
		· · · · · · · · · · · · · · · · · · ·
		•
1110	<b>T T</b>	a, +
INS	Ion Neutralization	Slow ionized atoms, typically He <sup>+</sup> ,

Ion Neutralization Spectroscopy

> ejected electrons are detected as a function of energy, and the surface density of states can be determined from the energy distribution. The interpretation of the data is more complicated than for SPI or UPS.

are incident on a surface where they are neutralized in a two-electron process which can eject a surface electron, a process similar to Auger emission from the valence band. The

Monoenergetic IR photons are reflected off a surface, and the attenuation of the IR intensity is measured as a function of frequency. This yields a spectrum of the vibrational excitations of adsorbed molecules. Recent improvements in the sensitivity of this technique allow IRAS measurements to be made on single crystal surfaces.

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IRAS

Infrared Reflection Adsorption Spectroscopy

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Acronym	Name	Description
IRES	Infra-Red Emission	The vibrational modes of adsorbed
INES	Spectroscopy	molecules on a surface are studied by
	Specificatopy	detecting the spontaneous emission
		of infra-red radiation from thermally
: •		excited vibrational modes as a func-
		tion of energy.
ISS	Ion-Scattering Spec-	Ions are inelasticly scattered from a
· ·	troscopy	surface, and the chemical composi-
		tion of the surface is determined
		from the momentum transfer to sur-
	· · · · · · · · · · · · · · · · · · ·	face atoms. The energy range is $\sim 1$
	• •	${ m KeV}$ to 10 ${ m MeV}$ , and the lower ener-
;		gies are more surface sensitive. At
		higher energies this technique is also
		known as Rutherford Back-
		Scattering (RBS).
LEED	Low Energy Electron	Monoenergetic electrons below $\sim 500$
	Diffraction	eV are elasticly back-scattered from
		a surface and detected as a function
		of energy and angle. This gives in-
	the Alexandree State	formation on the structure of the

near surface region.

Acronym	Name	 Description		 <u> </u>
		 	· · · · · ·	 <u> </u>

LEIS

### Low-Energy Ion Scattering

Low-energy ions, below  $\sim 5$  KeV, are scattered from a surface, and the ion "shadowing" gives information on surface structure. At these low energies the surface atom ion scattering cross-section is very large, resulting in large surface sensitivity. Accuracy is limited because the low energy ion scattering cross-sections are not well known.

Similar to LEED with positrons as the incident particle. The interaction potential for positrons is somewhat different than for electrons, so the form of the structural information is modified.

Similar to LEED, except the energy range is higher,  $\sim$  300-1000 eV. LEED calculational methods break down in this energy range. New methods are being developed for glancing angle scattering, which emphasizes forward scattering.

MEED

LEPD

### Medium Energy Electron Diffraction

Low Energy Positron

Diffraction

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Acronym	Name	Description
MEIS	Medium-Energy Ion	Similar to HEIS, except that incident
	Scattering	ion energies are $\sim$ 50-500 KeV.
·	Neutron Diffraction	Neutron diffraction is not an explicit-
		ly surface-sensitive technique, but
	: :	neutron diffraction experiments on large surface-area samples have pro-
		vided important structural informa-
		tion on adsorbed molecules, and also on surface phase transitions.
· .		
NEXAFS	Near-Edge X-ray Ad-	A core-hole is excited as in fine-
	sorption Fine Struc-	structure techniques (see EXAFS),
· · · ·	ture	except the fine-structure within $\sim 30$ eV of the excitation threshold is
	<b>V</b> (	measured. Multiple scattering is
		much stronger at low electron ener-
		gies, so this technique is sensitive to the local 3-dimensional geometry,
		not just the radial separation
		between the source atom and its
		neighbors. The excitation cross-
•		section may be monitored by detect- ing the photoemitted electrons or the
		Auger electrons emitted during core-
		hole decay.

TABLE I (continued)

Acronym	Name	Description
NMR	Nuclear Magnetic	NMR is not an explicitly surface-
· · · · ·	Resonance	sensitive technique, but NMR data
		on large surface-area samples has
		provided useful data on molecular
	· · · ·	adsorption geometries.
NIDD		
NPD	Normal Photoelectron	Similar to ARPEFS with a somewhat
· · ·	Diffraction	lower energy range.
RBS	Rutherford Back-	Similar to ISS, except the main focus
	Scattering	is on depth-profiling and composi-
· .		tion. The momentum transfer in
		back-scattering collisions between
		nuclei is used to identify the nuclear
· .	7. V	masses in the sample, and the small-
1 · ·		er, gradual momentum-loss of the in-
	· · · · · · · · · · · · · · · · · · ·	cident nucleus through electron-
*		nucleus interactions provides depth-
		profile information.
		·
* :		

Acronym	Name	Description	
Actonym	i vanite	Description	
· .			

RHEED

Reflection High Energy Electron Diffraction

SEELFS

Surface Electron Energy Loss Fine Structure

SERS

Surface Enhanced Raman Spectroscopy Monoenergetic electrons of  $\sim 1-20$ KeV are elasticly scattered from a surface at glancing incidence, and detected as a function of angle and energy for small forward-scattering angles. Back-scattering is less important at high energies, and glancing incidence is used to enhance surface sensitivity.

A fine structure technique similar to  $\sim$  EXELFS, except the incident electron energies are  $\sim 100-3000$  eV. SEELFS is surface sensitive because of the lower excitation energy.

Some surface geometries (rough surfaces) concentrate the electric fields of incident light sufficiently to enhance the Raman scattering crosssection so that it is surface sensitive. This gives information on surface vibrational modes, and some information on geometry via selection rules.

Acronym	Name	Description	
		• • • • • • • • • • • • • • • • • • •	
-	•		

SEXAFS

Surface Extended Xray Adsorption Fine-Structure

SHG

### Second Harmonic Generation

A surface-sensitive version of EX-AFS, where the excitation crosssection fine-structure is monitored by detecting the photoemitted electrons (PE-SEXAFS), Auger electrons emitted during core-hole decay (Auger-SEXAFS), or ions excited by photoelectrons and desorbed from the surface (PSD-SEXAFS).

A surface is illuminated with a highintensity laser, and photons are generated at the second-harmonic frequency through non-linear optical process. For many materials only the surface region has the appropriate symmetry to produce a SHG signal. The non-linear polarizability tensor depends on the nature and geometry of adsorbed atoms and molecules.

1.4

Acronym	Name	Description
SIMS	Secondary Ion Mass	Ions and ionized clusters ejected from
	Spectroscopy	a surface during ion bombardment
		are detected with a mass spectrome-
:	· 	ter. Surface chemical composition
		and some information on bonding
		can be extracted from SIMS ion frag
		ment distributions.
•		-
SPI	Surface Penning Ioni-	Neutral atoms, usually He, in excited
	zation	states are incident on a surface at
		thermal energies. A surface electron
		may tunnel into the unoccupied elec-
		tronic level, causing the incident
		atom to become ionized and eject an
		electron, which is then detected. Thi
		technique measures the density of
		states near the Fermi-level, and is
		highly surface sensitive.
SPLEED	Spin-Polarized Low	Similar to LEED, except the inciden
	Energy Electron	electron beam is spin-polarized. This
	Diffraction	
		surface magnetism and magnetic ord
	* 1.47 -	ering.

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(continued)

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Acronym	Name	Description
STM	Scanning Tunneling	The topography of a surface is meas
· · · ·	Microscopy	ured by mechanically scanning a
		probe over a surface with Angstrom
		resolution. The distance from the
		probe to the surface is measured by
· .		the probe-surface tunneling current.
	•	Also known as Scanning Electron
		Tunneling Microscopy (SETM).
SXAPS	Soft X-ray Appear-	Another name for APXPS.
	ance Potential Spec-	
	troscopy	
TEM	Transmission Electron	TEM can provide surface informa-
,	Microscopy	tion for carefully prepared and
		oriented bulk samples. Real images
		have been formed of the edges of cry
		stals where surface planes and sur-
		face diffusions have been observed.
•		Diffraction patterns of reconstructed
		surfaces, superimposed on the bulk
	•	diffraction pattern, have also provid
		ed surface structural information.

Acronym	Name	Description
TDS	Thermal Desorption	An adsorbate-covered surface is heat
	Spectroscopy	ed, usually at a linear rate, and the desorbing atoms or molecules are
		detected with a mass spectrometer.
	· · · ·	This gives information on the nature
		of adsorbate species and some infor-
• • • •		mation on adsorption energies.
TPD	Temperature Pro-	Similar to TDS, except the surface
	grammed Desorption	may be heated at a non-uniform rate
	• •	to get more selective information on
	· . · ·	adsorption energies.
	• .	
UPS	Ultra-violet Photoem-	Electrons photoemitted from the
•	ission Spectroscopy	valence and conduction bands are
		detected as a function of energy to
		measure the electronic density of
· .		states near the surface. This gives
		information on the bonding of adsor-
	an a	bates to the surface (see ARUPS).
WF	Work Function meas-	Changes in the work-function during
	urements	the adsorption of atoms and
	· · · ·	molecules provide information on
	- : · · · ·	charge-transfer and chemical bond-
	•	ing.

Acronym	Name	Description
XANES	X-ray Adsorption	Another name for NEXAFS.
•	Near-Edge Structure	
XPS	X-ray Photoemission	Electrons photoemitted from atomic
	Spectroscopy	core levels are detected as a function
		of energy. The shifts of core level en-
		ergies gives information on the chem-
		ical environment of the atoms (see
· ·		ARXPS, ARXPD).
XRD	X-Ray Diffraction	X-ray diffraction has been carried out
	·	at extreme glancing angles of in-
		cidence where total reflection assures
		surface sensitivity. This provides
		structural information that can be
		interpreted by well-known methods.
		An extremely high x-ray flux is re-
;		quired to get useful data from single
		crystal surfaces. Bulk x-ray
	•	diffraction is used to determine the
		structure of organo-metallic clusters,
,		which provide comparisons to
		molecules adsorbed on surfaces. X-
		ray diffraction has also given struc-
		tural information on large surface-
		area samples.

the three-dimensional geometry of the near-surface region. Electron scattering also depends on the chemical identity of the scattering atoms, so electron diffraction techniques are sensitive to both chemical composition and structure throughout the near-surface region. Therefore low-energy electrons are an ideal probe of surface structural chemistry. The main difficulty with electron diffraction methods is that the strong electron-surface interaction makes data analysis difficult -- it is not possible in most cases to "invert" diffraction data to obtain the original surface structure.

2.1.1. Low energy electron diffraction

and the second states

In a conventional LEED experiment a focused beam of monoenergetic electrons is reflected off an ordered single crystal surface and the elastically backscattered electrons are detected. Several types of information can be extracted from LEED patterns. First, the symmetry of the LEED pattern is related to the symmetry of the surface, so changes in surface symmetry because of reconstruction or chemisorption are immediately detected. Second, imperfections and deviations in long-range order change the shape of diffraction beams. This can be used to study the process of ordering in phase transitions or the growth of ordered domains within overlayers. Finally, the integrated intensity of diffraction beams depends on the detailed bonding structure of the surface. This information is most important for the study of surface chemical bonding. The intensity of LEED beam is a function of the incident electron beam energy and angles of incidence on the surface.

The intensity of a given diffraction beam can be measured as the incident electron energy or beam voltage is varied, producing an intensity-voltage or I-V curve; or as the angle of the incident electron beam relative to the surface is varied, producing an I- $\theta$  or rocking curve; or as the crystal is rotated around its own normal at a given angle of incidence, producing an I- $\phi$  curve. For structure determination LEED data are most often recorded in the form of I-V curves with the incident electron beam at normal incidence or lying in a mirror plane of the surface. This form of data are usually simpler to work with both experimentally and theoretically.

25

One advantage of LEED is that the diffraction process filters out effects due to local defects or deviations from long-range order. The contribution of defects to I-V curves is proportional to the first power of the number of defects, while the contribution of the part of the surface with long-range order is proportional to the square of the number of atoms involved, so the LEED beam integrated intensity reflects the equilibrium geometry of the ordered surface structure.

LEED has been used to determine the structure of a wide variety of surfaces, including clean and reconstructed surfaces of metals and semiconductors, and atomic and molecular physisorption and chemisorption on many different substrates (see part 5). As the theoretical and experimental tools of LEED have improved, the structure of systems with larger and more complex unit cells have been determined. Successful LEED structure determinations have been carried out for systems with several molecules adsorbed in unit cells up to 16 times larger than the substrate unit cell,/1/ and for reconstructed surfaces where the structural rearrangement involves several surface layers./2/

There are still a number of surface systems where the structure cannot be determined by LEED for theoretical and experimental reasons. High Miller-index surfaces, such as stepped or kinked surfaces, have layers separated by very small distances normal to the surface. The calculational tools normally used for LEED break down in this case, and no new approach has yet been developed to solve this problem. Experimental difficulties restrict the study of insulator surfaces, because of charging problems, and of molecular crystal surfaces, because of beam damage problems.

A reliable LEED structure determination requires a large data base, usually a number of different I-V curves collected at more than one angle of incidence. Electron beam damage to the surface must be prevented during data acquisition.

Over the last decade both the speed and accuracy of data acquisition and the sensitivity of the LEED experiment have been significantly improved. In most structure determination experiments the LEED patterns are displayed on a phosphor screen. LEED I-V curves are then measured by photometric or photographic means. Fast data acquisition systems have been developed that record LEED patterns with video cameras interfaced to computers and generate I-V curves during the experiment./3,4/ The sensitivity of LEED is also being greatly increased with the development of instruments that can detect single diffracted electrons, which completely solves the problem of electron beam damage./5,6,7/ Such instruments should be able to extend the range of LEED structure determination to delicate systems such as molecular crystals and physisorption systems, and to systems without long-range order, where the diffracted intensity is much lower than for ordered systems.

There are variations of LEED that use positrons (low energy positron diffraction, or LEPD)/8/ or spin-polarized electrons as a probe /9/ The latter technique is especially useful as a probe of magnetic ordering in surfaces. Spinpolarized LEED, or SPLEED, has been used to study surface magnetism and phase transitions on nickel.

At higher energies the surface sensitivity and the importance of multiple scattering is reduced. Diffraction techniques in this energy range have primarily been applied to the study of defects and deviations from long range order, as in the use of reflection high-energy electron diffraction (RHEED) to monitor epitaxial growth on surfaces. The higher-energy diffraction techniques have only infrequently been used for surface structure determination/10/ due to theoretical complications, but new approaches are promising./11/

#### 2.1.2. Diffuse low energy electron diffraction

Conventional LEED experiments are done on systems with long range order. This is not a fundamental restriction. The energy-dependent variation in diffracted intensity at a given point in the Brillouin zone is primarily determined by the local scattering geometry at the surface. Long range order gives rise to sharp diffraction beams which reflect this intensity dependence. If angle resolved intensity data are collected from a system with definite local geometry but without long range order, the local geometry can still be determined by LEED calculations./12/ This "diffuse" LEED experiment will be difficult to interpret unless there is one predominant local scattering geometry. Unlike the conventional LEED experiment, the diffraction process does not filter out the contributions of defects and impurities from the contribution of the equilibrium structure in the diffuse LEED experiment. If the scattering from different kinds of sites is superimposed in the experimental data it will be difficult to construct a reasonable model of the surface.

There are a number of "lattice-gas" chemisorption systems, where atoms or molecules are adsorbed in well-defined sites on the surface, as determined by vibrational spectroscopy, but where there is no long range order. The adsorption sites and bond lengths for such systems can be determined by diffuse LEED calculations, as has been done for oxygen on the tungsten (100) surface./13/

#### 2.1.3. Photoelectron diffraction

The interference and diffraction of photoemitted electrons can provide structural information, as in angle-resolved photo-electron fine structure (ARPEFS) spectroscopy, angle-resolved x-ray photoelectron spectroscopy (ARXPS), and angle-resolved x-ray photoelectron diffraction (ARXPD). The main advantage of photoemission over LEED is that the initial state of the photoemitted electron is a simple spherical wave, and can be controlled to emphasize particular structural features, especially in chemisorption systems. Because the initial state is simple, in some high-energy cases the data analysis can be more straight forward than a full LEED multiple-scattering calculation.

In photoelectron diffraction experiments monoenergetic photons excite electrons from a particular atomic core level. Angular momentum is conserved, so the emitted electron wave-function is a spherical wave centered on the source atom, with angular momentum components  $l \pm 1$ , where l is the angular momentum of the core level. If the incident photon beam is polarized, the orientation of the emitted electron wave-function can be controlled. These electrons then propagate through the surface and are detected and analyzed as in LEED experiments. A synchrotron x-ray source normally produces the intense beams of variable energy polarized photons needed for photoelectron diffraction.

In angle-resolved photoemission fine-structure (ARPEFS) experiments electrons are detected at a given angle as a function of energy. Structural information is obtained from the variation in intensity due to interference between different scattering paths for electrons over an energy range of  $\sim 100$ -500 eV. In this energy range the interference effects are dominated by single scattering, so the scattering amplitude can be readily calculated for a model system. A Fourier transform of the interference pattern will show the distribution of different scattering path-lengths that contribute to the detected intensity. This can be a guide to the proper surface structure, but this result must be confirmed by a calculation of the interference for a model geometry./14/ ARPEFS has been used to solve several surface structures, including sulfur on nickel./15/ Long-range order is not required for ARPEFS experiments. In spite of the name, ARPEFS is not a normal "fine-structure" technique (see below). The variations in the detected intensity as a function of energy are orders of magnitude larger than the fine-structure modulation in core-level excitation cross-sections.

Photoelectron diffraction is most useful for systems where the photoexcited atoms all have the same local geometry, as in a chemisorption problem. If there are source atoms in different local geometries, there will be interference between multiple sets of scattering paths, and the resulting interference spectrum will be harder to interpret. For these cases LEED experiments are probably better, with diffuse LEED used for disordered systems.

#### 2.2. Fine Structure Techniques

There are a large number of "fine structure" techniques, all based on the same physical principle. In all of these techniques an electron is ejected from an atomic core-level by incident photons or other particles. The different names refer to different experimental arrangements for the excitation and detection of core-holes.

As the excitation energy is varied the energy of the emitted electron varies. The emitted electron wave can be scattered back to the source atom from neighboring atoms, where it interferes with the source wave-function with a phase that depends on the electron energy, interatomic distance and the identity of the neighboring atom. This energy dependent interference changes the coupling of the incident excitation to the final state, producing a modulation or "fine-structure" in the excitation cross section. Fine structure experiments are often carried out with synchrotron sources, since the initial electron state is better defined for photoemission than for electron excitation. When core-hole decay is detected by Auger or secondary electron emission, the technique is surface sensitive. Core-hole decay can also be detected by fluorescence, or by adsorption of the incident photon beam. These methods are not intrinsically surface sensitive, but they are useful when the source atoms are exclusively located at the surface.

If there are different local geometries for source atoms, the different fine structures will be superimposed in the experimental spectrum, which will then be more difficult to interpret. Fine structure techniques are particularly useful when a chemisorbed atom is used as the source atom.

#### 2.2.1. Near-edge fine structure techniques

In the "near-edge fine structure" region emitted electrons have energies up to  $\sim 50$  eV and multiple scattering effects are predominant. An emitted electron wave can scatter several times and still return with a significant amplitude to the source atom. Therefore the variation in the observed cross-section depend not only on interatomic bond distances, but also on bond angles, so the full threedimensional geometry around the source atom can be determined. The theoretical analysis of near-edge fine structure data is very similar to LEED data analysis.

A few structures have been solved by x-ray adsorption near-edge fine structure (XANES), including oxygen on Ni(100)./16/ This technique is also known as near-edge x-ray adsorption fine structure (NEXAFS).

A variation of XANES or NEXAFS has been used to determine the structure of molecules chemisorbed on surfaces. In this approach photoemitted electrons excite molecular orbitals in the chemisorbed molecules. By varying the polarization of the incident photons, molecular orientation can be determined from selection rules for excitation. The bond lengths can be determined from a quasi-empirical correlation between bond-length and the shift in the molecular orbital excitation energy. This technique has been used to study the chemisorption of several hydrocarbon molecules on different metal surfaces./17/

#### 2.2.2. Extended fine-structure techniques

For emitted electrons above  $\sim 50$  eV, the "extended fine structure" region, the modulation of the excitation cross section is dominated by single backscattering between near-neighbor atoms and the source atom. A Fourier transform of the extended fine structure as a function of momentum transfer gives the distribution of radial distances between the source atom and neighboring atoms. With empirical or theoretical correction for scattering phase shifts, which have been calibrated using results from bulk structures known from x-ray diffraction, this gives chemical bond lengths with an accuracy of better than 0.05 Å.

There are a large number of extended fine-structure results available. These techniques, after LEED, have provided the largest amount of quantitative information on surface structure and chemical bonding. The extended fine structure techniques give quantitative information on surface structure without the need for complex model calculations. In simple systems and when combined with qualitative data from other experiments, knowledge of bond lengths may be sufficient to completely describe the surface geometrical structure. These techniques are most useful in multi-component or chemisorption systems, where atoms of a particular chemical species have only one local geometry. By selectively exciting an appropriate core level, near-neighbor bond lengths are determined. In systems with non-equivalent atomic sites, such as reconstructed surfaces, the extended fine structure will be complicated by a superposition of radial distribution functions for the different sites. Additional data will be needed to solve these structures. Data interpretation is generally simpler with photon excitation, since the polarization and orientation of final-state electrons can be controlled by using single crystal samples and polarized photons from a synchrotron source. One important advantage of extended fine structure techniques is that they do not require long range order or single crystal substrates, so they can be directly applied to many systems of technological importance.

A number of different experimental methods are available to observe fine structure. In extended x-ray adsorption fine structure (EXAFS) experiments x-ray photons excite core levels and the cross section is determined by x-ray absorption

31

or fluorescence from excited atoms. When Auger or secondary electrons emitted from the excited atoms are detected, the process, now called surface EXAFS (SEXAFS), is surface sensitive. SEXAFS experiments have also been done by detecting ions emitted from surfaces in photon stimulated desorption SEXAFS (PSD-SEXAFS).

There are analogous processes using electrons instead of photons to excite atomic core levels. Diffraction effects may perturb the cross section fine structure when electrons are used to excite core levels or monitor cross section. This is not a problem for systems without long range order. For cases involving long range order it is desirable to integrate over detector angles, and also electron beam incidence angles where this is practical, to average out multiple-scattering effects in the initial and final electron states. In electron appearance potential fine structure spectroscopy (EAPFS) incident electrons at  $\sim 1$  KeV excite shallow core holes, and the cross section is monitored by soft x-ray fluorescence in soft x-ray appearance potential spectroscopy (SXAPS-EAPFS), Auger electron appearance potential spectroscopy, (AEAPS-EAPFS), or by the variation in elastic backscattering in disappearance potential spectroscopy (DAPS-EAPFS), which is also referred to as surface electron energy loss fine structure (SEELFS). With excitation by high energy electrons (60-300 KeV) and detection by fluorescence the process is called extended x-ray energy loss fine structure (EXELFS), or electron energy loss near-edge spectroscopy (ELNES) in the near edge region. This last process, like EXAFS, is not inherently surface sensitive.

#### 2.3. Surface Topography Techniques

Field ion microscopy (FIM), atom diffraction (AD) and scanning tunneling microscopy (STM) provide atomic scale information on surface topography. These techniques produce good qualitative images of surfaces. It is difficult to get atomic coordinates directly, but knowledge of the surface topography can lead directly to structural models of a surface.

# 2.3.1. Field ion microscopy

Field ion microscopy (FIM) is the oldest of these techniques, developed in the 50's /18/ A sharp, single crystal metal tip with a radius of ~1000 Å is maintained at ~ 10 kV in a low pressure (~  $< 10^{-4}$  torr) gas, usually helium. Gas molecules are polarized and attracted to the tip by the strong, inhomogeneous electrostatic fields. The field strength near the tip is several V/Å. Valence electrons in a gas atom can tunnel into the metal surface as the neutral atom approaches the tip, creating an ion which is repelled by the high field around the tip. The ions project an image of the high field regions of the tip onto a phosphor screen. If the tip is cooled, individual surface atoms can be imaged. Pairs of atoms separated by as little as 1.5 Å have been resolved.

A field-ion microscopy image is a two-dimensional projection of the outermost surface layer. This image provides a qualitative image of the surface, but very little information on distances normal to the surface. Although the direct information on the surface chemical bond is limited, FIM has added greatly to the qualitative understanding of surface structure. Because of the high field strengths required, application of the FIM has been limited to refractory metals, although some chemisorption systems on these metals have been studied./19/

2.3.2. Atomic beam diffraction

A thermal energy atomic beam (20-200 meV) has a wavelength on the order of inter-atomic distances. The atomic beam diffracts from a contour of the surface potential corresponding to the beam energy. This contour is located 3-4 Å above the ion cores in the outermost layer of the surface. Atomic beam diffraction patterns are normally interpreted using model surface scattering calculations, where the scattering is described as a Van der Waals interaction.

The low energy probe of atomic diffraction does not damage even delicate physisorbed overlayers; and it is sensitive to hydrogen, which is an important component of many surface systems of current interest. Electron scattering techniques are relatively insensitive to hydrogen because of its small scattering cross section. The position of hydrogen chemisorbed on Pt(111) was determined using helium diffraction./20/ Finally, atom diffraction is extremely sensitive to surface order and defects, and it has been very useful in the study of disorder and kinetic processes on surfaces. Because neutral atoms scatter well outside the ion cores of the surface atoms, structural details can be lost and no information on subsurface structure can be obtained.

2.3.3. Scanning tunneling microscopy

The scanning tunneling microscope (STM) is one of the most recently developed surface sensitive techniques./21/ In STM a metal probe is brought close enough to the surface under study for the electron wave functions to overlap. A fixed potential difference between probe and surface is maintained and the probe approaches the surface until a given tunneling current is observed. The probe is mechanically scanned over the surface, and a feedback loop adjusts the vertical spacing to maintain a constant tunneling current. STM has achieved a horizontal resolution of  $\sim 2$  Å and a vertical resolution of  $\sim 0.1$  Å under optimum conditions. By changing the probe-surface potential difference it is possible to map out different surface profiles of wave function overlap. The STM is very flexible and can be applied to all kinds of surfaces. Unlike electron techniques it is not limited to the solid-vacuum interface, although the best resolution has been obtained in vacuum.

The STM can give a direct qualitative image of surface topography. An early STM experiment confirmed the LEED result that the "missing row" model correctly describes the 2x1 reconstruction of the gold (111) surface./22/ Because the tunneling current is a complicated function of the electronic and geometric structure of the tip and surface, so it is difficult to relate a constant tunneling current contour to the geometrical structure of the surface, especially if more than on type of atom is involved. Information on the surface electronic structure is available, however. The lateral resolution of STM images is not good enough to provide accurate information on chemical bond lengths and angles. As the experimental and theoretical tools develop, scanning tunneling microscopy should provide increasingly useful information on surface structure.

## 2.4. Ion Scattering

At high energies (~ 1 MeV) the interaction of ions with surfaces can be described by classical Rutherford scattering. This simple interaction has been used to study surface structure by directing ion beams along bulk crystal axes at solid surfaces. The "channeling" and "blocking" of these beams is very sensitive to deviations from bulk structure. Ion scattering has been used in particular to study relaxation and reconstruction at crystal surfaces. Measurements of surface relaxation have provided accurate structure determinations, as in the case of reconstructed Au(110)./23/ However, if a surface structure involves a large departure from the bulk crystal structure, it can be difficult to solve from ion scattering results.

In any case, because ion scattering is strongly affected by the thermal vibrations of surface atoms, experimental data must be compared to Monte-Carlo simulations for model surfaces to achieve quantitative results. The available data base for structure-fitting is rather small compared to electron spectroscopies, so the sensitivity to structural parameters is sometimes limited. But when the surface structure is close to the bulk structure, ion channeling data can be strongly sensitive to small variations in structural parameters.

# 2.5. Complementary Techniques

There are a number of other surface probes that are sensitive to the local geometry of the surface or give important information on surface composition, but which do not give direct information on atomic coordinates in the surface region. These techniques provide vital information needed to construct reasonable models of surface structure, which are needed to interpret data from quantitative techniques such as LEED and SEXAFS.

### 2.5.1. Chemical composition

Chemical composition is the most basic information needed to describe a surface, and a pre-requisite for structure determination. Auger electron spectroscopy is the most generally used techniques for measuring surface composition, and it is sensitive to all elements except hydrogen and helium. Thermal desorption spectroscopy (TDS) is a simple and particularly useful technique for chemisorption studies -- it gives a general idea of the chemical identity of adsorbates, and some information on the type of binding to the surface. Secondary-ion mass spectrometry (SIMS) is another way to get information on surface chemical composition -- its interpretation is generally more complicated, but SIMS is sensitive to hydrogen, and also gives some information on the molecules present on the surface.

### 2.5.2. Electronic spectroscopy

One group of techniques is sensitive to electronic structure at the surface, and can probe the electronic band structure and density of states near the Fermi level. This electronic information is useful for understanding the bonding mechanisms responsible for chemical process operating at the surface. Structural information can also be obtained by comparing experimentally observed electronic structure with theoretical calculations of electronic structure for model systems (see part 4).

Ultra-violet photoemission spectroscopy (UPS) probes the density of states, and ion neutralization spectroscopy (INS) and surface Penning ionization (SPI) provide similar information with probes of ions and metastable atoms, respectively. Angle-resolved UPS can determine the valence band structure. Xray Photoelectron Spectroscopy (XPS) provides information on chemical shifts of the atomic core levels, and this can also help in understanding chemical bonding at the surface.

#### 2.5.3. Vibrational spectroscopy

Another class of techniques monitors surface vibration frequencies. Highresolution electron energy loss spectroscopy (HREELS) measures the inelastic scattering of low energy ( $\sim 5 \text{eV}$ ) electrons from surfaces. It is sensitive to the vibrational excitation of adsorbed atoms and molecules as well as surface phonons. This is particularly useful for chemisorption systems, allowing the identification of surface species. Application of normal mode analysis and selection rules can determine the point symmetry of the adsorption sites./24/ Infra-red reflectance-adsorption spectroscopy (IRRAS) is also used to study surface systems, although it is not intrinsically surface sensitive. IRRAS is less sensitive than HREELS but has much higher resolution.

# 2.5.4. Optical techniques

Non-linear optical techniques, such as second harmonic generation (SHG), have recently been used as surface probes. Bulk materials with inversion symmetry do not generate second harmonic signals, while surfaces and interfaces cannot have inversion symmetry, so the total SHG signal will come from the surface region for many systems. The components of the non-linear polarizability tensor have been used to determine the orientation of chemisorbed molecules. /25/ Optical techniques are not limited to solid-vacuum interfaces like charged particle techniques, so their further development can expand the range of surface structural studies to solid-solid, solid-liquid, solid-gas and liquid-gas interfaces.

# 2.5.5. Electron-stimulated desorption

Observation of the ion angular distribution after electron stimulated desorption of chemisorbed species (ESDIAD) can provide direct quantitative information on the orientation of adsorbed molecules on surfaces. Electrons incident on the surface can excite chemical bonds into non-bonding states, causing molecular decomposition. The excess energy can be converted into kinetic energy, which accelerates an ionic fragment of the molecule along the axis of the broken bond. The angular distribution of desorbed ions can be related to the orientation of the bonds in the unperturbed adsorbed molecules. This technique gives direct information on the number and symmetry of sites for chemisorption, and approximate information on bond angles.

3.

# THE THEORY OF MODERN TECHNIQUES FOR SURFACE STRUCTURE ANALYSIS

Although the wide range of experimental techniques described in part 2 have made significant contributions to understanding surface structure and bonding, many of these techniques do not yield explicit information on atomic coordinates in the near surface region, the information required to characterize the surface chemical bond. Other techniques can provide some of this information in certain cases, but can only be applied to a limited range of surface systems, for example ion channeling studies have provided important information on the reconstructions of solid surfaces, but are much more difficult to apply to most chemisorption systems. Optical techniques are being developed which have the potential to contribute direct, quantitative information on surface structure, including surface x-ray diffraction and non-linear optical probes, but these have not yet reached the stage of routine use.

Almost all of the existing quantitative data on surface structure was obtained through experimental techniques that involve the propagation and scattering of electrons in solids. This class of surface probes includes the whole range of "fine-structure" techniques, in addition to LEED and angle-resolved photoemission experiments. This chapter will provide a theoretical description of these techniques and the methods of analyzing the experimental data to determine surface structure.

# 3.1. General Four-Step Description of Electron-Diffraction Techniques

The most promising techniques for obtaining detailed surface structural information about molecular adsorbates rely on electron diffraction in one way or another. These include LEED,/27,28,29/ IV-HREELS,/30/ EAPFS,/31/ SEELFS,/32,33/ EXELFS,/34,35/ ARUPS, ARXPS, ARPEFS,/36,37,38/ PE-SEXAFS, SEXAFS, EXAFS, and NEXAFS (XANES). These and other techniques have been discussed above in part 2, and were summarized in Table I. Among these techniques, LEED has been the most productive.

We shall in the following discuss the surface sensitive techniques involving electron diffraction from a common viewpoint. These techniques can all be fit within a four-step description, which will be very useful for comparison. Various techniques are illustrated in terms of this description in Figure 1, and the four steps are defined below.

#### 3.1.1. Step 1: incoming particle

Either a photon or an electron impinges on the surface. This photon or electron may be polarized to yield additional surface information. The electron, part of a well-collimated and monoenergetic electron beam, may be multiply scattered by surface atoms before reaching step 2. Multiple scattering is most marked at kinetic energies below about 200 eV and can make the process particularly sensitive to the surface structure at these lower energies.

3.1.2. Step 2: primary event

A variety of processes may take place at this stage, distinguishing the different techniques -- photoelectron emission, Auger electron emission, ion emission, energy loss due to core-hole, plasmon or phonon excitation, as well as elastic electron scattering. Thus, in the primary event, the incoming particle generates an outgoing particle. More than one type of particle may be emitted simultaneously, e.g. an electron and a photon in SEXAFS.

From the point of view of obtaining surface structure information, the nature of this primary process is important in two ways. First, the process may be atom-specific, giving chemical selectivity, as in photoelectron emission and Auger electron emission. Second, the process can affect the characteristics of the outgoing particles, especially in terms of angular distribution, and in terms of the exact location within the surface where this primary process takes place. The angular distribution can give direct evidence of the molecular orientation with respect to the surface; this happens, for instance, when an electron is emitted from a valence orbital.

In terms of location, the primary process may be concentrated at one atom, as in an electron-atom scattering in LEED or in electron emission from core levels. It may also be delocalized over many atoms, as in photoelectron emission from a delocalized valence band level. The latter case is again of value to obtain molecular orientations directly. The polarization of the incident electron may also be used to determine molecular orientations, through its effect on the primary process.

3.1.3. Step 3: secondary event

Part of the outgoing electron wave resulting from step 2 will back-scatter from neighboring atoms to the site of emission or initial scattering. If the kinetic energy of the outgoing electrons does not exceed a few hundred eV this results in detectable interference between the outgoing and back-scattered electron waves, which modulates the probability of the primary emission or scattering process. Such modulation is usually called "fine structure" and is the basis of techniques like SEXAFS (EXAFS) and EAPFS (EXELFS, SEELFS), as well as in NEXAFS (XANES). Note that the electrons responsible for this fine structure are rarely collected themselves -- other outgoing electrons or photons (or even ions) are normally detected experimentally. Two energy regimes are of importance here. At electron kinetic energies above about 50 eV, single back-scattering from neighboring atoms is usually predominant. By contrast, at lower energies electrons can also be multiply scattered by several nearby atoms before returning to the location of the primary process. The single scattering regime modulates the outgoing particle current in a simple oscillatory manner. The near-neighbor interatomic distances can be extracted relatively easily by Fourier transformation given appropriate scattering phase shifts (cf. SEXAFS). When multiple scattering is significant, a multiplescattering computer simulation is required. This makes the analysis more complex, but gives access to bond angles as well as bond lengths (cf. NEXAFS).

3.1.4. Step 4: outgoing particle

Photons, ions or electrons are detected outside of the crystal. On their way out, electrons may be multiply scattered by surface atoms, especially at the lower energies, which again gives added sensitivities to the surface structure.

#### 3.2. Structural Information

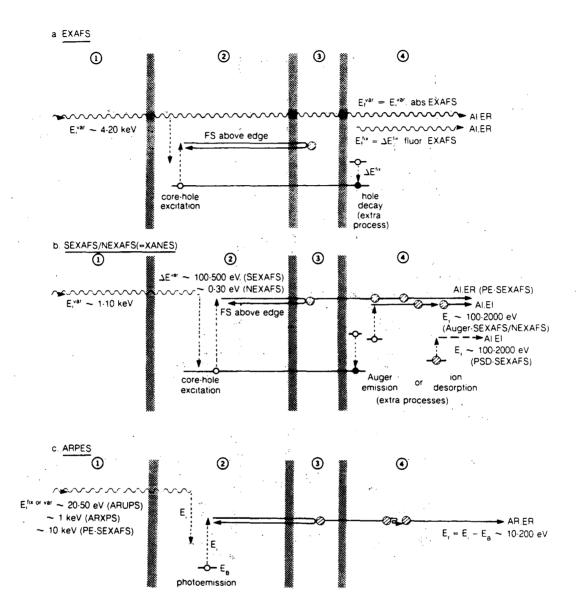
Two modes of electron detection are commonly used, which affect the kind of structural information that can be extracted.

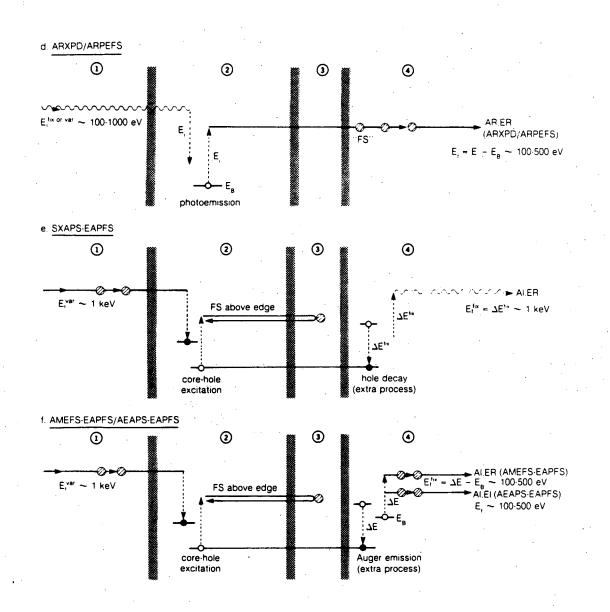
In the angle resolved mode, which selects electrons traveling in well-defined directions, emphasis is laid on the properties of plane-wave diffraction within the surface -- this provides access to all interplanar distances (not only between atomic planes parallel to the surface) and thus, to the complete three-dimensional crystallographic structure (as for example in LEED and in ARPES). Significant structural information can come from steps 1 and 4.

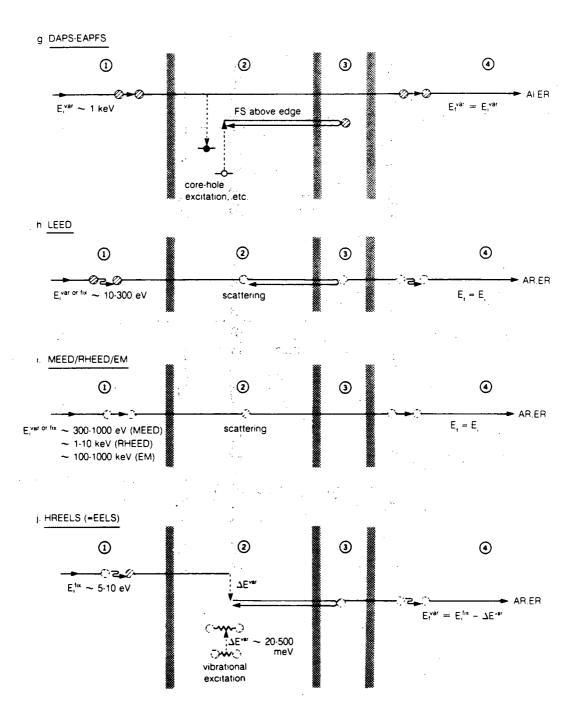
In the angle integrated mode, electrons emitted in many different directions are accumulated simultaneously. To an appreciable extent this averages out the structure-dependent effects of step 4, and therefore emphasizes the information arising from the primary and secondary events of steps 2 and 3, such as the radial distances determined in fine-structure techniques like SEXAFS.

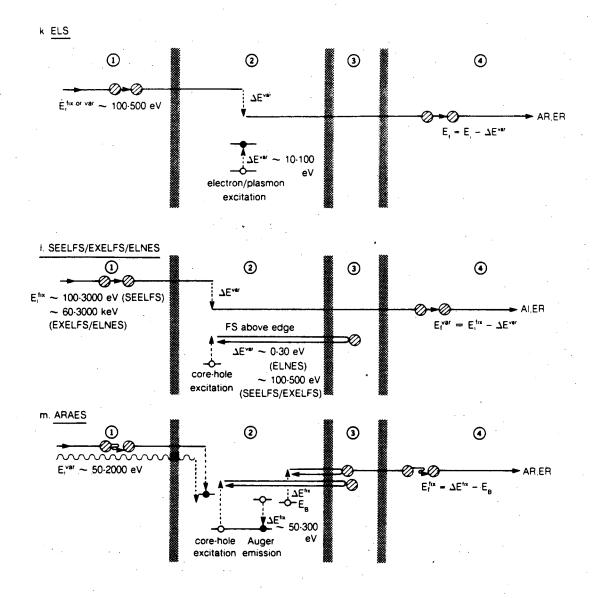
Energ	y vs. t	ime diagram	s							
for the	ne ever	t sequences	١Ň	surface	crystallography	techniques	that	use	electron 'scattering/diffraction	
Leger	nd:									

>	electron propagation
·····> ,	photon propagation
<b>&gt;</b>	ion propagation
-@->	multiple electron forward-scattering by atoms is important
-030-	multiple electron backscattering by atoms is important
	electron backscattering by nearby atoms is important
<b>•</b>	bound electron
0	electron hole
<b>▲</b> : : ▼	energy gain, loss
E,	incident particle energy
Ε,	final particle energy
superscript "fix":	energy is kept fixed in experiment
superscript "var":	energy is varied in experiment
E <sub>B</sub>	electronic binding energy
E,	atomic binding energy in surface lattice
AR	angle-resolved detection
AI	angle-integrated detection
ER .	energy-resolved detection
EI	energy-integrated detection
FS	fine structure is important









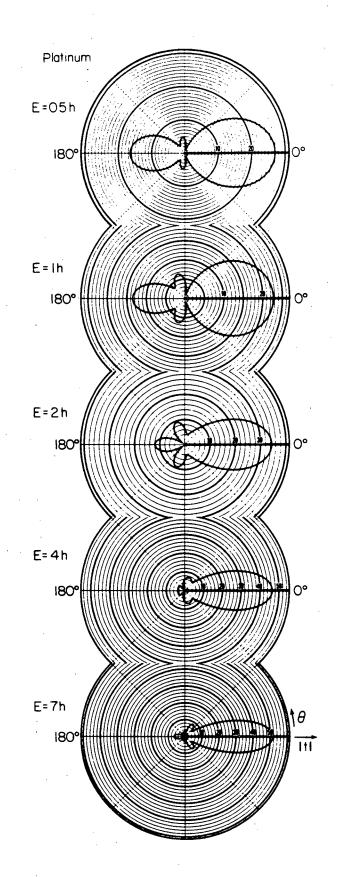
In several techniques an additional process associated with one of the four steps generates the detected particles, e.g. Auger emission in Auger-SEXAFS or ion emission in PSD-SEXAFS. This additional process does not normally provide structure sensitivity, but produces particles that are more conveniently detected. We shall include such processes in the discussion of step 4.

In any of the steps 1, 3 and 4, multiple scattering of electrons can play an important role in the techniques of interest here. On the one hand, multiple scattering provides a greater sensitivity to various aspects of structure; on the other hand, it complicates the theoretical treatment, i.e. it complicates the extraction of the structural information. For the following discussion it will be useful to first describe in more detail a couple of important features of electron scattering by individual atoms in a surface.

At low kinetic energies (10 eV), electrons are scattered strongly but somewhat isotropically by each atom (Figure 2), generating multiple scattering in all directions. As the kinetic energy rises, back-scattering weakens considerably, while forward-scattering remains strong, and multiple scattering remains important only for small scattering angles. This effect is already noticeable around 100 eV and becomes more and more pronounced towards KeV and MeV energies as scattering concentrates in an ever narrower forward cone. This gives the appearance of a more kinematic behavior, i.e. multiple scattering effects becomes less obvious. The reason is that only small momentum transfers occur, which also provides little structure sensitivity. Thus, with rising energy, little back-scattering and therefore, little back-and-forth scattering between any pair of atoms can occur, although multiple forward-scattering along a chain of atoms can be significant. As we shall describe more explicitly in section 3.5.1 one often disregards multiple forward-scattering and talks of a kinematic or singlescattering situation.

3.3. Theoretical Aspects of Individual Techniques

We shall now individually discuss the various techniques in terms of the above four-step description. In all these techniques the flux of outgoing particles is measured as a function of the energy (or sometimes direction) of either the



incident or outgoing particles. The flux (intensity) exhibits variations as a function of energy (or angle), from which the surface structure is extracted. In some cases, the outgoing particles are not energy-analyzed but measured collectively. This is done to enhance weak signal-to-noise ratios, as in SEXAFS.

### 3.3.1. EXAFS

Extended X-ray absorption fine structure (EXAFS) was the first technique in which "fine structure" was used to obtain structural information./39,35,40/ An incoming photon, penetrating the surface in step 1, undergoes an absorption process creating a core-hole excitation at an atomic site as the primary event (step 2), cf. Figure 1a. This is accompanied by the photo-emission of electrons which back-scatter from near-neighbor atoms as the secondary event (step 3). Interference by the back-scattered electrons modulates (i.e. produces fine structure in) the overall absorption cross-section as their kinetic energy varies in step with the incident photon energy. The fine structure can be observed in the loss of intensity from the incident photon beam ("absorption EXAFS") or instead in the intensity of fluorescence as the core-holes decay ("fluorescence EXAFS"). EXAFS is not intrinsically surface sensitive, and provides surface information only for high-surface-area materials, such as exfoliated graphite or highly dispersed particles, or when the signal comes from atoms which are only present at the surface,/39/ or when total reflection provides surface selectivity.

# 3.3.2. SEXAFS

To obtain surface sensitivity with EXAFS, thereby creating surface extended x-ray absorption fine structure (SEXAFS), one may monitor instead the outgoing Auger electrons (Auger-SEXAFS), outgoing ions ejected during core-hole decay (PSD-SEXAFS), or outgoing photoelectrons (PE-SEXAFS) instead of a photon signal. Surface sensitivity comes from the short escape depths of electrons and ions./31,41,42,43/ The electron kinetic energies involved in step 3 are sufficiently high (> 50 eV) that single back-scattering prevails over multiple back-scattering. Coupled with angle-integrated detection, this allows a simple Fourier transform

approach to obtain near-neighbor distances (although theoretical or empirical atomic scattering phase-shifts need to be included). Polarization of the incoming photons can be used to obtain additional information about bond directions if valence levels are involved, since the excitation cross-sections include simple selection rules that depend on bond orientations. Chemical selectivity is provided by monitoring only Auger electrons or photoelectrons due to a particular chemical element. One may selectively investigate the structure in the immediate neighborhood of atoms of a particular element. The outgoing particles are normally energy-integrated to provide a measurable signal.

SEXAFS-type fine-structure can be obtained with photo-electrons in the low-energy region ( $\sim 100-300$  eV). To that end, one must reduce the effect of multiple scattering in step 4 until the effects of step 3 dominate. This can be accomplished with polycrystalline surfaces and with angle-integrated detection, as has been done recently in PE-SEXAFS./44/

#### 3.3.3. NEXAFS and XANES

If in step 3 of EXAFS or SEXAFS, the electron kinetic energy is held within about 50 eV of the excitation edge, one reaches the "near-edge" regime where multiple back-scattering becomes important in the secondary process cf. Figure 1b. This technique is referred to as near-edge x-ray absorption fine structure (NEXAFS) or x-ray absorption near-edge structure (XANES)./45,46,47,48/ Compared to EXAFS and SEXAFS, this multiple scattering gives more complete sensitivity to bond lengths and bond angles in the neighborhood of the atom where the primary process takes place. But model calculations are generally needed to extract this information. As with (S)EXAFS, polarization of the incoming photon can also give direct access to bond directions. Furthermore, combining an empirical correlation between carbon-carbon bond lengths and resonance energies, it appears to be possible to obtain these bond lengths./48/

# 3.3.4. ARPES, ARUPS and ARXPS

In angle-resolved photoelectron emission spectroscopy (ARPES), incoming photons give rise to the primary event of photoemission (step 2), cf. Figure 1c. This can involve excitation from delocalized electron orbitals (as in angle-resolved ultraviolet photoemission spectroscopy (ARUPS)/49,50/ from valence levels) or from deeper-lying localized orbitals (as in angle-resolved x-ray photoemission (ARXPS) from atomic core-levels). /51/ If the photoemitted electrons have kinetic energies in the range 10-200 eV, they undergo multiple scattering (similar to that encountered in LEED) in the third and fourth steps, of the four-step process. This yields sensitivity to the surface within a photo-electron mean free path length of the photoexcited atom, which can be chosen with chemical selectivity. Compared to ARUPS, ARXPS is a more convenient approach for the extraction of structural information, since core-level excitations are more easily described than valence-level excitations. Angle-resolved detection is normally used to obtain the most complete structural information, which is interpreted in a procedure very similar to that of LEED with full simulation of the electron emission intensity as a function of energy or angle.

# 3.3.5. ARXPS and ARXPEFS

If, starting with angle-resolved x-ray photoelectron spectroscopy (ARXPS),/51/ the emitted electron kinetic energy is increased to a few hundred electron volts, the back-scattering of photoemitted electrons to the source atom is considerably reduced, cf. Figure 1b and d. Then the secondary event of step 3 becomes negligible compared to the events of step 4. At the same time, step 4 simplifies to include predominantly single scattering by neighboring atoms, (for convenience, we neglect the multiple forward-scattering in this description, since it yields little structure sensitivity). In this case, electrons reach the detector either directly from the photoemitting atom or after single scattering by atoms that are near the photoemitting atom (again, x-rays, as opposed to ultraviolet radiation, provide the most convenient core-level emission). The interference

between these different outgoing electron paths modulates the detected intensity as a function of the angle of detection: this measurement mode is used in ARXPD.

Similarly, "fine-structure" arises as a function of the emitted-electron kinetic energy in the measurement of angle resolved photoemission extended fine structure (ARPEFS)./37,36,38/ This "fine-structure" is different from that of SEXAFS, EXAFS, etc., since it does not originate from back-reflection to and interference at the electron source atom. It yields the surface structure information relatively easily through Fourier-transformation if angle-resolved detection is used (suitable scattering phase-shifts must be available, however). The full three-dimensional structural information can be so obtained. Sensitivity to a particular structural feature may be emphasized through appropriate selection of the detection angle and and the polarization of the incident photons.

#### 3.3.6. Extended Appearance Potential Fine Structure (EAPFS)

In EAPFS,/31/ incident electrons excite core-level electrons into states above the Fermi level  $E_F$  in the primary process cf. Figure 1e-g. This requires a minimum incident energy for any given core-level, namely  $E_F - E_1$ , where  $E_1$  is the core-level energy (hence the designation "Appearance Potential"). The choice of core-level provides chemical selectivity. The excited electron can then undergo back-reflection from neighboring atoms as the secondary step. This yields fine structure as a function of the incident energy that can be used to obtain structural information by Fourier transformation. Since the incident electrons can undergo multiple scattering prior to the core-level excitation, amorphous materials are preferred to minimize any disturbing LEED-like modulations due to such scattering.

There are three main detection modes for EAPFS within the appearance potential spectroscopy (APS) technique./31/ First, one may monitor soft-x-ray emission due to the decay of the core hole left by the primary process. This is called SXAPS-EAPFS (Figure 1e). Second, it is also possible to monitor Auger electrons due to the same core-hole decay, as in AEAPS-EAPFS and AMEFS-EAPFS, cf. Figure 1f. Third, one may measure the remaining total intensity of

the elastically scattered electrons in DAPS-EAPFS (DA = Dis-Appearance) cf. Figure 1g. Angle-integrated detection removes most of the structural sensitivity of step 4 (especially with amorphous materials). Normally one collects all emitted electrons in these experiments, i.e. energy-integration is used. However, in the Auger-Monitored Extended Fine Structure version (AMEFS-EAPES)/52/ energy resolution is used, which achieves chemical sensitivity at the cost of a lower signal/noise ratio, cf. Figure 1f.

3.3.7. LEED, MEED, RHEED and Electron Microscopy (EM)

In low-energy electron diffraction (LEED) only elastic scattering events are considered, i.e., no energy loss is allowed /27,28,29/ This situation is sometimes referred to as ELEED (Elastic LEED). In LEED, the different steps of the general four-step process are equivalent to each other, in the sense that each step describes possible elastic electron-scattering events in a multiple-scattering chain (which of these scattering events is termed the primary event becomes arbitrary). Figure 1h schematically shows possible scatterings in LEED. The four-step description makes vividly clear that multiple scattering plays a large role in LEED, especially when compared to other techniques described here. This multiple scattering, together with angle-resolved detection, gives LEED a high sensitivity to all details of the surface structure: layer spacings, bond lengths and bond angles throughout the surface to a depth determined by the energydependent electron mean free path. To obtain structural information from LEED, the multiple scattering must be simulated on a computer for each plausible geometry until the correct geometry is found by trial-and-error.

At increasingly higher energies, LEED becomes in turn medium-energy electron diffraction (MEED),/53,54,55/ reflection high-energy electron diffraction (RHEED)./56/ and electron microscopy (EM)./57,58/ cf. Figure 1i. Multiple scattering remains important, although the mean distance between successive scatterings increases gradually towards hundreds of Angstroms. On the other hand, to an increasing degree the only significant scattering events at these energies occur near the forward direction. A perfectly ordered surface yields sharp diffracted electron beams, unlike the other techniques which we describe in

this chapter. Any kind of disorder of defects generate diffuse intensities between the sharp diffraction beams. The diffuse intensity contains information not only about deviations from long-range order, but also about the short-range order or local geometry, including chemical bond lengths and bond angles.

### 3.3.8. ILEED, HREELS and ELS

If at least one of the scattering events in a LEED multiple-scattering chain involves an energy loss, one speaks of inelastic low-energy electron diffraction (ILEED), /59,60/ (multiple losses are possible but infrequent). The lost energy can be transferred to surface vibrations (e.g. molecular vibrations or phonons), as is the case in high-resolution electron loss spectroscopy (HREELS)/61, 62, 63/ or to electronic excitations (e.g. single-electron excitations or plasmons), as is the case in electron loss spectroscopy (ELS)./64,65/ In ILEED, the primary event of the four-step process is the inelastic electron scattering. It is not necessarily localized at an atomic site (as illustrated for convenience in Figure 1j,k) instead, it is quite often delocalized over many atoms, as with dipole scattering in HREELS or plasmon excitation ELS. In HREELS cf. Figure 1j, multiple scattering is at last as important as it is in LEED, and angle-resolved detection is also used. HREELS can therefore yield potentially the same structural information as LEED, e.g. when intensities are measured as a function of incident energy, at the cost of having to describe an additional inelastic process in the theory. /63/ This approach may be called IV-HREELS, since LEED-like IV curves are used. HREELS is however mostly used in a mode where the multiple scattering effects are virtually constant, namely by scanning the energy loss over a small range at fixed incident energy. (61, 62) Then all that matters is the occurrence of sharp energy losses at values corresponding to frequencies of surface vibration. This gives a loss spectrum similar to that familiar in infra-red adsorption spectroscopy (IRAS) in the gas phase and at surfaces. This is also the approach with ELS, cf. Figure 1k, although here the wide scan of energy loss allows multiple scattering to significantly modulate the heights of the peaks corresponding to individual excitations. Under these circumstances the structural information is obtained indirectly through the measured vibrational and excitational properties of the surface, rather than through the diffraction effects.

# 3.3.9. Surface Extended Energy Loss Fine Structure (SEELFS)

Another electron-based energy-loss technique is SEELFS./32, 33/ Compared to HREELS and ELS, higher electron energies are used, so that a core-hole excitation-edge and the associated fine structure become available, cf. Figure 11. There is a great similarity between SEELFS and EAPFS. However, in SEELFS the energy-loss is kept small compared to the incident energy, thus, one has a single-electron final-state problem in SEELFS rather than a two-electron finalstate problem as in EAPFS. By keeping the incident energy fixed in SEELFS and by angle-integrating the detection, variable diffraction effects in steps 1 and 4 are minimized. This yields fine structure that can be Fourier-analyzed to yield bond lengths around chemically-selected atoms. Complication can arise however, when several spherical waves with different angular momenta are needed to describe the electrons of step 3. This produces in effect several overlapping fine structures, which may not be easy to isolate. Nevertheless, experimental evidence suggests that normally one of the angular momentum components is sufficiently dominant to avoid these complications.

# 3.3.10. Extended X-Ray Energy Loss Fine Structure (EXELFS)

By substantially increasing the electron kinetic energy in ILEED and SEELFS to 60-300 KeV, one reaches a situation that can resemble EXAFS, with electrons replacing the EXAFS photons, cf. Figure 11. Chemical selectivity. is obtained by choosing an appropriate core excitation edge. And surface sensitivity on the atomic scale exists mainly for high-surface-area materials, as with EXAFS.

3.3.11. Electron Energy Loss Near-Edge Structure (ELNES)

ELNES/66/ is the near-edge equivalent of EXELFS, with the same highenergy (60-300 KeV) electrons as incident particles. If focuses on final energies within about 30 eV of an absorption edge, so that the fine structure arising in step 3 behaves very much as in NEXAFS, cf. Figure 11. Here multiple scattering is important, giving full structural information in the immediate vicinity of a selected chemical element. However, there is no simplifying dipole selection rule in the primary process, since electrons replace the photons.

## 3.3.12. Angle-Resolved Auger Electron Spectroscopy (ARAES)

One may directly monitor Auger electrons emitted following core-hole excitation induced by an incident electron or photon beam, using angle resolved detection, cf. Figure 1m / 67, 68 / Thus the core-hole excitation together with the Auger process constitutes our step 2. At the lower energies used in ARAES ( $\sim$ 20-200 eV), multiple scattering is often important as in LEED, especially in step 4. Thus step 3, as in LEED, is not distinguished by convenient fine-structure, but is much more complex due to multiple scattering. In addition, to obtain structural information, the complicated atomic Auger process must be modeled accurately. This has only been done in a few special cases involving atomic orbitals (as opposed to solid state orbitals)./69,70/ As a result, the Auger transition probabilities into the various outgoing spherical waves in step 2 are generally unknown. So far these probabilities have been fit to experiment, with limited success in terms of structural determination. The orientation of adsorbed molecules appears to be accessible with the photon-excited version of this technique, by using photon polarization and symmetry selection rules /71/Otherwise the angle-resolved detection of ARAES can yield the same relatively complete three-dimensional structural information as does LEED.

#### 3.4. Formalism for Individual Processes

In section 2.3 we have decomposed various surface-sensitive techniques into a small set of more elementary processes. In this section we shall present appropriate formalisms that describe these individual processes. Namely, we shall discuss the theoretical treatment of the propagation of electrons in the surface region, as well as the treatment of elastic and inelastic electron-atom scattering, photoelectron emission and of Auger electron emission. These parts can then be easily recombined to provide a complete theoretical description of each surface-sensitive technique. Some general features of particular interest will be highlighted in section 3.5.

#### 3.4.1. Overview of process formalisms

We shall deal mainly with the propagation and scattering of electrons through solid surfaces. The most appropriate formalism to describe these processes will depend very much on the situation, as computational efficiency is at a premium. Spherical-wave and plane-wave expansions are frequently used, often side by side within the same theory. Spherical waves are convenient to describe the scattering or emission of electrons by an individual atom. An important quantity will then be the complex amplitude of each spherical wave leaving that atom.

Plane waves are often used when two conditions are satisfied: 1) many (but not necessarily all) atomic layers of the surface have a two-dimensional periodicity, and 2) either a plane-wave incident electron beam is present or angle-resolved electron detection is applied. Computation based on the planewave expansion are often much more efficient than those based on the sphericalwave expansion. This explains their frequent use even in problems that do not involve strict two-dimensional periodicity, as with disordered overlayers on an otherwise periodic substrate.

The fate of scattered or emitted electron waves depends on the occurrence of multiple scattering from atom to atom. With strong atomic scattering, a large number of scattering paths must be considered: this applies especially at low energies and with angle-resolved detection, e.g. in LEED and ARPES. At higher energies fewer scattering paths are important, because the atomic scattering is relatively weaker (except for forward-scattering). Paths involving mostly forward-scattering dominate in angle-resolved techniques such as ARPEFS, MEED, RHEED, and EM. By contrast, single back-scattering to the emitting atom dominates in angle-integrated fine structure techniques such as (S)EXAFS, EAPFS and SEELFS. The individual formalisms strongly reflect these different circumstances.

#### 3.4.2. Electron propagation

The interference effects resulting from electron propagation are responsible for providing the desired structural information in all the techniques discussed here. The extraction of structural information, therefore, requires a knowledge of the electron wavelengths and of any phase shifts that may occur in electron emission and electron-atom scattering. Failure to understand these processes can result in quite erroneous results.

The well-known muffin-tin model of the electron atom interaction potential has in most cases proved to be an adequate compromise between accuracy and computational efficiency, at least for electron kinetic energies exceeding  $\sim 20$ eV./27,28,29/ The muffin-tin potential is spherical inside the muffin-tin spheres. This "ion core" usually provides the dominant contribution to electron scattering and emission, to be discussed shortly.

The interstitial region between these spheres is represented by a constant potential valve (the muffin-tin constant or muffin-tin zero). This is the region of unscattered electron propagation, in which simple plane-wave or spherical-wave behavior describes the electron wave-field. The plane-wave description is computationally advantageous when dealing with multiple scattering by periodic lattices, since such lattices diffract any plane wave into other well-defined plane waves. This approach is often useful even with non-periodic overlayers adsorbed on an otherwise periodic substrate.

The spherical-wave description has its own great advantages. It is best adapted to the scattering and emission by the spherical ion cores and it does not require the presence of any structural periodicity. In particular, it is well suited to the treatment of multiple scattering between different atoms within any cluster of atoms, in particular within a periodic unit cell as in LEED. It is also convenient for the treatment of fine structure arising from back-scattering by nearby atoms, as in (S)EXAFS, NEXAFS, EAPFS, etc. (i.e. in step 3 in our four-step description).

For energies lower than  $\sim 20$  eV, the muffin-tin model is often inadequate outside the muffin-tin spheres. In the case of surfaces, this applies especially to low-energy studies of adsorbed molecules. For instance, HREELS is normally performed at kinetic energies around 5-10 eV (to benefit from a strong reflection coefficient from the substrate). HREELS is therefore highly sensitive to the potential in the molecular bonding regions and couples strongly with weakly bound and relatively delocalized electron states. Also, NEXAFS is often measured down to energies of about 10 eV above an emission edge, giving similar sensitivity to bonding details. No satisfactory alternative treatment to the muffin-tin model has yet been applied in the surface context, mainly because excessive computational efforts would be involved (however this problem has been dealt with in the case of low-energy electron scattering by gas-phase molecules/72/).

#### 3.4.3. Single electron-atom scattering

Electron-atom scattering is central to all techniques under discussion here. As we have mentioned, electron-atom scattering at surfaces has been treated almost exclusively by means of the muffin-tin model.

The formalism of electron-atom scattering has been extensively dealt with elsewhere./27,28,29/ We shall only recall its main features here. Because of the assumed spherical symmetry, the partial-wave scattering approach is convenient. Namely, an incoming spherical wave  $h_l^{(2)}(kr) Y_l^m(\mathbf{r})$ ,  $(-l \le m \le l)$  can scatter only into the outgoing spherical wave  $h_l^{(1)}(kr) Y_l^m(\mathbf{r})$  (here  $h_l^{(1)}$  and  $h_l^{(2)}$  are Hankel functions of the first and second kinds,  $k = 2\pi/h(2mE)^{\frac{1}{2}}$ , E is the kinetic energy and  $r = |\mathbf{r}|$ ). This occurs with amplitude  $t_l$  ( $t_l$  is an element of the diagonal atomic *t*-matrix), which is related to the phase shifts  $\delta_l$  through

$$t_l = -\frac{h^2}{8\pi m} \frac{1}{k} \sin \delta_l \ e^{i\delta_l} \tag{1}$$

The phase shifts  $\delta_i$  are calculated by standard partial-wave scattering theory. It involves the electron-atom interaction potential of the muffin-tin model. There are a variety of ways to obtain this potential, which consists of electrostatic and exchange parts (spin dependence may be included, especially when the spin polarization of the outgoing electrons is of interest). One usually starts from known atomic wave functions within one muffin-tin sphere and spherically averages contributions to the total charge density or potential from nearby atoms. The exchange term may be treated as non-local (e.g. Hartree-Fock) or local (e.g.  $X_{\alpha}$ ). The muffin-tin constant with respect to the vacuum zero level is a by product of this approach, however in practice this constant is normally adjusted *a posteriori* to take into account surface-related work function changes.

The t-matrix of Eq. (1) will be useful in describing the scattering of a *plane* wave by an atom. Expansion of the plane wave  $e^{i\mathbf{k}\cdot\mathbf{r}}$ , with  $|\mathbf{k}| = k$ , into spherical waves yields the total scattered wave

$$e^{i\mathbf{k}\cdot\mathbf{r}} + f(\theta)\frac{e^{i\mathbf{k}\cdot\mathbf{r}}}{r}$$
(2)

at large values of kr. The atomic scattering amplitude  $f(\theta)$  depends on the scattering angle  $\theta$  through the well-known relation

$$f(\theta) = -4\pi \sum_{l} (2l+1)t_l P_l(\cos\theta)$$
(3)

where the functions  $P_l(\cos\theta)$  are Legendre polynominals. The scattering amplitude  $f(\theta)$  can be used to illustrate the nature of electron scattering in solids. A large scattering amplitude implies strong multiple scattering. To discuss this issue, we need to first include the effect of atomic thermal vibrations. It has been found adequate for this purpose to replace the scattering amplitude  $f(\theta)$  by a statistical average over certain atoms, even in the presence of multiple scattering. In the case of diffraction by a periodic lattice, the average is preformed over atoms that are equivalent by two-dimensional periodicity, and in the case of back-scattering by shells of vibrating neighbors, around equivalent source atoms. In either case, one ends up multiplying  $f(\theta)$  by a Debye-Waller attenuation factor  $e^{-M}$ , with

 $M = \frac{1}{2} |\mathbf{s}|^2 < (\Delta \mathbf{r})^2 > \tag{4}$ 

where s is the linear momentum transfer and  $\langle (\Delta \mathbf{r})^2 \rangle$  is the mean-square atomic displacement.

Note that the product  $e^{-M} f(\theta)$  can be expressed in terms of effective phase shifts in direct analogy with Eqs. (1) and (3), then  $\delta_l$  is replaced by an effective

 $\delta_l(T)$  in those relations. These so-called "temperature-dependent" phase shifts  $\delta_l(T)$  are commonly used in multiple scattering theory, because the effect of thermal vibrations is felt again and again at each scattering in a chain of scatterings.

The product  $e^{-M} f(\theta)$ , shown as  $|f(\theta)|$  in Figure 2, has a marked lobe structure in its angular dependence. There is always a pronounced lobe of strong scattering amplitude in the forward-scattering direction ( $\theta = 0$ ). This lobe becomes narrower (more forward-focused) with increasing kinetic energy, becoming quite narrow (a few degrees) at energies above 1000 eV. High temperatures also favor a narrow forward scattering lobe since the Debye-Waller factor attenuates forward-scattering less than large angle scattering. In addition, there is usually a lobe centered on the back-scattering direction ( $\theta = \pi$ ). At low energies ( $\sim 10 \text{ eV}$ ) this lobe is wide and comparable in strength to the forward lobe, yielding nearly isotropic scattering. But at higher energies the backscattering lobe rapidly loses strength, while also becoming narrower. Finally there are one or more side-scattering conical lobes which are usually of a strength comparable to or smaller than the back-scattering lobe. These become more numerous and narrower with increasing energy. Between lobes there may be directions with vanishing scattering amplitude, when accidental cancellation of partial scattered waves occurs.

# 3.4.4. Multiple electron scattering

We have just described electron scattering by a single atom. The main feature to remember is the pronounced forward scattering within a more or less narrow forward cone, which occurs especially at the higher energies. The implications for multiple scattering are as follows.

At low energies ( $\sim 10 \text{ eV}$ ) the scattering is relatively isotropic and relatively strong, so that scattering in any direction is likely to be followed by scattering from another atom that finds itself in the electron path. In fact, several successive scatterings are quite possible, especially with heavy (high-Z) atoms, which scatter most strongly. This includes the possibility of repeated back-andforth scattering between two or more atoms, which is, when the interference is constructive, similar to a negative-ion resonance in a molecule. With such strong multiple scattering, a perturbation expansion in terms of the number of scatterings will often fail to converge and a self-consistent solution is then necessary.

At higher energies, back-scattering and side-scattering become increasingly less probable, leaving mainly forward-scattering, which itself remain quite strong. Even for very high energies, e.g. in HEED or EM at  $E \sim 10-1000$  KeV, multiple scattering is still important. But now all scattering paths remain bundled within a few degrees of the incidence direction.

These facts explain many differences between surface-sensitive techniques. Those techniques which use low kinetic energies, such as LEED, ELS, HREELS, ARAES, ARPES and NEXAFS, require a rather complete multiple scattering treatment. Some perturbation theories do apply to them but close attention to multiple forward-scattering as well as to several back-scattering events remain essential. Techniques using higher energies split up in two groups. The finestructure techniques, such as (S)EXAFS, EAPFS, SEELFS and EXELFS, rely almost exclusively on the (weak) back-scattering from neighboring atoms to the emitting atom. Forward-scattering, though strong, is largely irrelevant in this situation (this is enhanced by angle-integrated detection, which averages over many exit directions). Other high-energy techniques are much more sensitive to multiple forward scattering events, e.g. MEED, HEED, EM and ARPEFS (partly because of their angle-resolved detection mode in the forward direction).

We shall next describe several formalisms used to calculate the effects of multiple scattering. We start with the most accurate formalism in common usage and then introduce simplifications and specializations.

Within the muffin-tin model of spherical scatterers, all multiple scattering can be properly included with the Green function formalism. We already have given the *t*-matrix for scattering by a single atom. It is now necessary to describe the propagation of the scattered spherical waves in the "near-field" region (without asymptotic forms). Consider the propagation of a wave of angular momentum quantum number  $L \equiv (l,m)$  from an atom at location  $\mathbf{r}_i$  to an atom at location  $\mathbf{r}_j$ . This wave can be expressed in terms of spherical waves  $L' \equiv (l',m')$  incident on atom j with amplitudes given by the Green function

$$G_{LL}^{ij} = -4\pi i \; \frac{8m}{h^2} k \sum_{L_1} i^{l'_1} a(L,L',L_1) h_{l_1}^{(1)}(k | \mathbf{r}_i - \mathbf{r}_j |) Y_{L_1}(\mathbf{r}_i - \mathbf{r}_j) \quad (5)$$

Here  $k = |\mathbf{k}|$  and  $L_1 = (l_1, m_1)$  extends over all values of  $l_1$  and  $m_1$  compatible with L and L', namely such that  $|l - l'| \leq l_1 \leq l + l'$  and  $m + m' = M_1$ . This compatibility is manifest as non-zero values of the Clebsch-Gordon (or Gaunt) coefficients

$$a(L,L',L_1) = \int_{\Omega} Y_L^*(\Omega) Y_L(\Omega) Y_{L_1}^*(\Omega) d\Omega$$
(6)

With the *t*-matrix and the Green function we can represent any multiplescattering path explicitly. For instance, scattering by atom 1 to atom 2, then back to atom 1 and on to final scattering by atom 3 yields a scattering amplitude of

 $t^3 G^{31} t^1 G^{12} t^2 G^{21} t^1$ 

(7)

where one should read from right to left (in the fashion of matrix multiplication) and where the superscripts on the *t*-matrices allow the different atoms to have different scattering properties. When strong multiple scattering occurs, the contributions from all such scattering paths should be included. This can be done self-consistently by replacing the infinite series due to longer and longer scattering paths by a matrix inversion./73/ The result is the following expression, for diffraction by a set of N atoms labeled i = 1, 2, ..., N:

$$\begin{pmatrix} T^{1} \\ T^{2} \\ \vdots \\ T^{N} \end{pmatrix} = \begin{pmatrix} I & -t^{1}G^{12} & \cdots & -t^{1}G^{1N} \\ -t^{2}G^{21} & I & \cdots & -t^{2}G^{2N} \\ \vdots & \vdots & \ddots & \vdots \\ -t^{N}G^{N1} & -t^{N}G^{N2} & \cdots & I \end{pmatrix}^{-1} \begin{pmatrix} t^{1} \\ t^{2} \\ \vdots \\ t^{N} \end{pmatrix}$$
(8)

Here  $t^i$ ,  $T^i$ ,  $G^{ij}$  and I are matrices indexed by L = (l,m) and L' = (l',m'); I is the unit matrix. A multicenter expansion is used, i.e. the spherical waves are centered on the respective atoms. The quantity  $T^i_{LL'}$  is the total amplitude of the

spherical wave  $Y_L$  that leaves atom *i* after spherical waves  $Y_{L'}$  have initially impinged on every atom of the cluster and multiple scattering within the cluster has been taken into account. The scattered wave accumulated over all terminal atoms *i* is obtained by simple addition of the  $T^i$  values with proper consideration of the relative amplitudes and phases of the initial wave incident of the cluster.

The dimension of the large matrix to be inverted in Eq. (8) is  $N(l_{max}+1)^2$ , where  $l_{max}$  is the largest value of l included. This dimension critically affects the required computing effort. The number of spherical waves used,  $(l_{max}+1)^2$  is typically 16 to 64 at LEED energies ( $l_{max}$  is ~ inversely proportional to the electron wavelength). The value of N is in general the number of atoms in the cluster needed to adequately account for all multiple paths involving any given surface atom. At 20 eV this might be several hundred atoms, as defined by a sphere around the given atom and whose radius is a few times the electron mean free path. Thus, matrix dimensions in Eq. (8) of the order of  $10^4$  would be required within this formalism. This is the situation for NEXAFS, ELNES and diffuse LEED. A similar single-center expansion approach has also been formulated for this problem./74,75/ It involves a new "wallpapering" scheme that bypasses the larger matrix inversion of Eq. (8); instead it builds up the cluster scattering properties as seen from a central atom in a shell-by-shell iteration, each step of which involves the inversion of a smaller matrix. However, the single-center expansion gives rise to much larger values of  $l_{max}$  (proportional now to the radius of the cluster instead of the muffin-tin radius) which still results in large computation times.

Simplifications can be brought about whenever the surface structure has symmetries. Point-group symmetries help moderately to reduce the matrix dimensions. On the other hand, two-dimensional periodicity can help drastically by reducing the number N to the number of atoms within a single twodimensional unit cell with a depth perpendicular to the surface of a few times the electron mean free path. For surface crystallography this is, however, not yet sufficient, because surface structural determination requires repeating such calculations for hundreds of different geometrical models of the surface structure.

Great computational advantage can ensue from using the plane-wave expansion between atomic layers. This occurs when such a representation converges, which requires sufficiently large spacings between the layers. Various calculational methods based on plane waves have been developed over the years. such as the Bloch-wave, Layer Doubling and Renormalized Forward Scattering methods. These have been extensively described previously in the context of LEED, /27, 28, 29/ but their use in other techniques merits further discussion here. In conventional LEED, the two-dimensional surface periodicity clearly defines a finite set of outgoing plane waves (corresponding to the discrete diffracted beams defined by the two-dimensional reciprocal lattice). Most other techniques do not share this feature -- no sharp electron beams emerge from the surface in photoemission, SEXAFS, diffuse LEED, etc. However, the use of angle-resolved detection is equivalent to defining a finite set of plane waves. This situation has been described as inverse LEED or time-reversed LEED./76/ The detector essentially singles out an emerging plane wave, which, when time is reversed, acts like a plane wave incident on the surface. This plane wave scatters through the periodic layers as does normal LEED, via the set of plane waves familiar in LEED, until they reach the original source of electrons. The source can be a photoemitting atom, for instance. The calculation need not proceed in this timereversed manner, however, given the source of emission in the form of amplitudes of outgoing partial waves (which can be corrected for intra-layer multiple scattering), one can deduce the resulting amplitudes of the above-mentioned set of plane waves as they leave the source. From then on multiple scattering through the lattice proceeds as in conventional LEED using the finite set of outgoing plane waves defined by the direction of detection.

Some techniques also involve a well-defined *incident* electron beam, even though the primary process at some point imparts an arbitrary parallel momentum to the electrons. This happens, for example, with energy loss in HREELS and ILEED, with diffuse scattering in LEED and with Auger emission in ARAES. In these cases the direction of the electrons leaving the surface has an arbitrary relationship to the incident beam direction. Up to the primary process, however, conventional LEED can be applied in the plane-wave representation, at least in the ordered part of the surface, using the finite set of plane waves defined by the direction of incidence.

#### 3.4.5. Approximations in multiple scattering

We shall now describe a series of approximations of increasing simplicity which have been developed to reduce computational effort required to describe multiple scattering. These approximations are usually tailored to specific circumstances and are used only in those particular circumstances in order to maintain the highest possible accuracy.

We have mentioned the preponderance of forward scattering of electrons by atoms. Perhaps the earliest method used to exploit this feature was Renormalized Forward Scattering in LEED./27/ This plane-wave method is a perturbation expansion in terms of the number of back-scatterings between atomic layers. It expressly does not count forward scatterings in the expansion. Instead, all forward scattering events that may occur between successive backscattering events are explicitly included. This approach is very economical and converges well except at the lowest energies (  $\sim 10 \text{ eV}$ ) where multiple scattering is too strong (as with all plane-wave methods, a sufficiently large interlayer spacing is also required). More recently this ideas has been applied to conventional LEED within the spherical-wave representation under the name Reverse Scattering Perturbation./77/ Most recently, this idea has been adapted to a shell-by-shell treatment (as opposed to a layer-by-layer treatment),  $\frac{78}{78}$ similar to the "wallpapering" scheme mentioned above. One then considers spherical waves leaving an atom or cluster and reflecting back from shells of neighboring atoms, including multiple scattering. This approach is particularly useful when long-range order is absent or unimportant, as in NEXAFS/78/ and in one part of a diffuse LEED theory./79/

This diffuse LEED theory consists of three parts:

1) multiple scattering of the incident electrons through the ordered region of the surface, yielding to a conventional LEED treatment;

2) scattering by a defect site, e.g. an isolated disordered adsorbate, including multiple scattering from shells of neighboring atoms back to the defect site;

3) multiple scattering on the way out from the defect site to the detector through the ordered region of the surface, which corresponds to the inverse LEED problem. Another method based on the number of back-scatterings by atomic layers is Beam Set Neglect in LEED,/80/ which is particularly appropriate for adsorbates on simple substrates. This method takes advantage of the fact that some sets of diffraction beams only affect the intensities of other beams through multiple scattering of third- or higher-order, therefore such sets of beams may be neglected. The method is very efficient both large superlattice unit cells (which create large number of of beams, most of which may be neglected) and also yields an efficient solution to the diffuse LEED problem./79/

As the electron energy increases, back-scattering rapidly becomes weaker and multiple scattering occurs primarily within a narrow cone in the forward direction. This is exploited in the chain method developed for MEED and RHEED./53,54/ In these techniques, grazing incidence is normally used to obtain surface sensitivity and sufficient reflection. These factors favor scattering along chains of atoms oriented parallel to the surface in the direction defined by the incident beam. The chain method uses this as a basis to calculate MEED and RHEED intensities exactly (allowing application to LEED as well). But when back-scattering and side-scattering are very weak, they-can be selectively and efficiently neglected in favor of the multiple forward-scattering that occurs within the chains of atoms.

We next turn to the high-energy fine-structure techniques: EXAFS/SEXAFS, EAPFS, SEELFS, EXELFS and ARPEFS. All but one of these involve single scattering back to a source atom, resulting in interference modulation of the primary process (Auger emission, etc.). The exception is ARPEFS, where the source atom emits photoelectrons which are scattered only once by neighboring atoms directly towards the detector (not counting multiple scattering which is insensitive to the structure). The structural information stems from the interference at the detector between the waves directly traveling from the source atom to the detector by different neighboring atoms. Furthermore, angle-resolved detection is used in ARPEFS unlike the other finestructure techniques. The common feature of all these techniques is high electron energies and a diffraction geometry which de-emphasizes forward scattering (although forward scattering effects have been observed)./47/ Under these circumstances substantial simplifications can be considered. First, single

scattering by neighboring atoms may be assumed. Second, one may ignore the finite radius of curvature of the spherical waves reaching the neighboring atoms, yielding the "plane-wave" or "small-atom" approximation. Third, the radial spherical functions may be given their asymptotic form  $\frac{e^{i\mathbf{k}\cdot\mathbf{r}}}{r}$ .

These simplifications lead to the following relative intensity modulations for ARPEFS:

$$\frac{(I - I_o)}{I_o} \equiv \chi(k)$$
$$= \sum_j \frac{\cos\beta_j}{\cos\gamma} \frac{+ f(\pi) + f(\pi)f(0) + \cos[kr_j(1 - \cos\alpha_j) + \phi_j]}{r_j}$$
(9)

Here k is the electron momentum,  $\alpha_i$  is the scattering angle at the neighboring atom situated at position  $\mathbf{r}_{j}$ ,  $| f(\alpha_{i}) |$  is the corresponding scattering amplitude and  $\phi_i$  the corresponding phase shift (i.e. the phase of  $f(\alpha_i)$ ), while  $\gamma$  is the angle between the polarization direction and the direct emission path to the detector, and  $\beta_{j}$  is the angle between the polarization direction and the initial path of an electron scattered from site j. (A Debye-Waller factor and an inelastic damping factor may be added to Eq. (9)). This expression may involve many terms j, one for each neighboring atom which contributes. Neverless the expression remains simple to analyze in many circumstances. Namely, by suitable choice of the energy, which affects  $f(\alpha_i)$ , and polarization direction, most terms can be made negligible. Then it becomes relatively easy to extract the structural information in the form of the path length differences  $r_j$   $(1-\cos\alpha_j)$ . With the energy scans of ARPEFS, Fourier transformation of the k-dependent data is sufficient, although some care with data manipulation is required. In particular, the phase shifts  $\phi_i$ have to be known from theory. There is also controversy about whether the plane-wave approximation is adequate in ARPEFS.

With the other fine-structure techniques (EXAFS, SEXAFS, EAPFS, etc.), the above mentioned approximations lead to the following general relationship for the intensity modulation at the detector: /41, 42, 43/

$$\chi(k) = \sum_{j} \frac{N_{j}}{kr_{j}^{2}} \sin(2kr_{j} + 2\delta_{l} + \phi_{j}) + f_{j}(\pi) + (10)$$

Here  $\delta_l$  is the phase shift of the central atom for a partial wave of angular momentum l, while  $N_j$  is the number of identical atoms at a distance  $r_j$ . (Here again a Debye-Waller and an inelastic damping factor may be added; also a polarization dependence may be included for EXAFS and SEXAFS.) Fourier transformation can yield the distances  $r_j$  with proper care. In this case the phase shifts are usually obtained from EXAFS results for bulk materials where the phase shifts are determined from the interatomic distances known from x-ray diffraction. Alternately, the phase shifts may be computed as is done in LEED. Note that multiple forward scattering in not included in Eq. (10).

#### 3.4.6. Photoelectron emission

The first step in photoemission (and some other techniques) involves photon propagation through the surface region to the location of the electron excitation.

#### 3.4.7. Photon propagation

The propagation of electromagnetic waves in bulk solid materials and in molecules is well understood. This understanding is appropriate for bulk EXAFS, for instance, but not necessarily for surface studies. The situation of a solid surface has only been studied recently in terms of atomic-scale phenomena, as is required by techniques such as photoemission. Although photons typically penetrate to a depth of about 1  $\mu$ m into the metal surfaces of interest, the only important photon-induced excitations occur within the electron escape depth of about 5 to 10 Å. Therefore, the shape of the electromagnetic fields should be known in this near-surface region of a few atomic layers.

It has been found that for photon energies near and below plasmon energies ( ~ 20 eV) and near other excitations, the electromagnetic fields are quite structured, both as a function of depth from the surface and as a function of energy./81/ For any quantitative structural studies, this situation is to be avoided. However, at all other photon energies, the fields are quite uniform and well described by the macroscopic bulk dielectric theory /82,83/ There remains, neverless, the unanswered question of where exactly to locate the boundary between solid and vacuum, especially in the case of adsorbed layers: at the substrate-overlayer interface, or at the overlayer-vacuum interface or elsewhere. It has been estimated that this uncertainty leads to errors which do not exceed approximately 20% in absolute emission cross-sections and which do not vary when the polar incidence angle with respect to the surface normal is kept constant./82/

To summarize, for photon energies above the plasmon energies (and away from other excitation energies), the electromagnetic fields can be described adequately with macroscopic dielectric theory.

#### 3.4.8. Photoemission matrix elements

The cross-section for photoexcitation from an initial state  $\psi_i$  to a final state  $\psi_f$  is: /81/

$$\frac{d\sigma}{d\Omega d\omega} = \frac{2\pi e^2}{hc} \frac{2\pi^3 k}{|\mathbf{A}_o|^2 m h\omega} + \int \mathbf{j}_f(\mathbf{r}) \cdot \mathbf{A}(\mathbf{r}) d^3 r |^2$$
(11)

where 
$$\mathbf{j}_{f_i} = \psi_f^*(\mathbf{r}) \nabla \psi_i(\mathbf{r}) - \psi_i(\mathbf{r}) \nabla \psi_f^*(\mathbf{r})$$

is the transition current density and  $\mathbf{A}(\mathbf{r})$  is the vector potential of the photon field. Assuming that  $\mathbf{A}(\mathbf{r})$  is spatially constant within the surface, one obtains the following dipole matrix element, written in the single particle model using the electron potential  $V(\mathbf{r})$ :

$$\frac{d\sigma}{d\Omega d\omega} = \frac{2\pi e^2}{hc} \frac{2\pi h^2 k}{mh\omega (E_f - E_i)^2} | <\psi_f | \mathbf{e}_A \cdot \nabla V(\mathbf{r}) | \psi_i > |^2$$
(12)

 $E_f$  being the kinetic energy of the emitted electron.

In the case of photoexcitation from a bound state  $\psi_i$  of a single atom  $\alpha$  with a muffin-tin potential, one obtains/82/ the following amplitudes for out going spherical waves L = (l,m):

$$M_{L}^{\alpha} = -(-i)^{l} \int d^{3}r \left[ e^{i\delta_{l}^{\alpha}} R_{l}^{f} \left( |\mathbf{r} - \mathbf{R}_{\alpha}| \right) - j_{l} (|\mathbf{r} - \mathbf{R}_{\alpha}|) \right]$$

$$\times Y_{L}^{*}(\mathbf{r} - \mathbf{R}_{\alpha}) - \frac{i\hbar}{2\pi} \frac{e}{mc} \frac{1}{(E_{f} - E_{i})} \mathbf{A} \cdot \nabla V(\mathbf{r}) \psi_{i}(\mathbf{r})$$
(13)

where the  $\delta_l^{\alpha}$  are the phase shifts of atom  $\alpha$ , the  $j_l$  are Bessel functions and the  $R_l^{f}$  are the normalized radial parts of the solutions to Schrödinger's equation inside atom  $\alpha$  at energy  $E_f$ . If  $\psi_i$  is an atomic core state with quantum number l', then the photoemission dipole selection rule (implicit in Eq. (13)) implies that  $l = l' \pm 1$ . Usually, one of the two outgoing values of l is by far dominant, as is the case in the gas phase.

Once  $M_L^{\alpha}$  has been computed, one knows the electron waves leaving the source atom and one can proceed to calculate the electron propagation through the surrounding medium, as described in preceding sections (this is the inverse LEED problem). It should be recalled that in this subsequent propagation, scattering by the source atom itself may occur. This is usually treated as if the source atom had already completely relaxed to its initial condition, i.e. as if the hole left by the emitted electron had already been filled. This assumption does not appear to impair the ability to perform structural determination with photoelectrons.

#### 3.4.9. Auger electron emission

The transition matrix element needed to describe Auger electron emission corresponds to the process in which an electron is ejected as a result of the filling of a deeper lying empty level by another electron. This process can be localized on one atom or involve neighboring atoms, especially if valence and conduction levels are involved. The Auger matrix element is/84/

$$M=<\!\psi_c\psi_e\,|\,{e^2\over r}\,|\,\psi_1\psi_2>$$

where  $\psi_{c}$ ,  $\psi_{e}$ ,  $\psi_{1}$  and  $\psi_{2}$  are respectively the wave functions of the core hole being filled, the emitted Auger electron and the initial state wave-functions of the two participating electrons. It is rather difficult to evaluate this matrix element, especially in the solid state. In the gas-phase atomic state, some results have been tabulated./69/ However, the difficulty of obtaining reliable values for the solid state is such that few attempts have been made./67,68/ In addition, there are no selection rules that limit the number of excited partial waves. Therefore, in ARAES the amplitudes of the outgoing partial waves have usually been left as adjustable parameters; and their relative phases have been neglected by assuming incoherent emission into the different partial waves. This inconvenient situation is a major cause for the infrequent use of ARAES in surface structural determination. While some success has been achieved in understanding the angular dependence of AES (and to a limited extent some structural determination has resulted),/67,68,71/ rather more accuracy is needed to achieve structural results that can compete with other techniques.

Note that in AEAPS-EAPFS, the Auger process is not the primary process which is modulated by fine structure since the energies involved in the Auger process are constant. Given the angle-integrated defection mode in EAPFS, the Auger step, therefore, need not be described in any detail.

3.4.10. Inelastic electron-electron scattering

The matrix element for inelastic electron-electron scattering is given by the following golden-rule expression (spin-averaged): /85/

$$<\rho_{I}> = \frac{4\pi^{2}N_{c}}{h} \sum_{\mathbf{k}_{1},\mathbf{k}_{2}>\mathbf{k}_{F}} \delta(E_{i}+E_{c}-E_{1}-E_{2})$$

$$\times \{\frac{3}{4}\mid -<\mathbf{k}_{1}\mathbf{k}_{2}\mid V_{c}\mid \mathbf{k}_{i}\cdot\boldsymbol{\gamma}_{l}>_{-}\mid^{2}$$

$$+\frac{1}{4}\mid +<\mathbf{k}_{1}\mathbf{k}_{2}\mid V_{c}\mid \mathbf{K}_{i}\cdot\boldsymbol{\gamma}_{c}>_{-}\mid^{2}\}$$

(14)

• (15)

72

Here  $< \cdots >$  indicates an average over the possible magnetic quantum numbers of the core-hole;  $E_c$  is the core-hole binding energy;  $\gamma_c$  represents the quantum numbers of the core electron, and  $\mathbf{k}_1$ ,  $\mathbf{k}_2$  and  $E_1$ ,  $E_2$  correspond to the momentum and energies of the electrons in the final state. The + and subscripts indicate the symmetry of the wave-functions under exchange of the spatial coordinates of the two electrons;  $N_c$  is the number of scattering sites, and  $k_F$  is the Fermi momentum. The above expression is applicable in particular to the primary process of EAPFS. No strict selection rules emerge in this situation, but a "pseudo-selection rule" does exist:/85/ for nodeless core wave-functions, both final state electrons in the dominant channel have angular momentum increased by one over that of the core state, at least for incident energies which do not exceed the ionization threshold by 500 eV. In addition, it is found that the dipole component in a partial-wave expansion of the Coulomb interaction dominates the matrix elements.

Phase shifts calculated following the above formalism are incorporated into the Fourier-transformation of the experimental EAPFS oscillations, together with phase shifts for back-scattering from nearby atoms./31/ This allows the bond length to be determined with an accuracy on the order of 0.02 Å.

At the high energies E of SEELFS/32,33/ and ELNES,/66/ the final state has only a single "active" electron (the incident electron). One obtains then, for momentum transfer q, a differential cross-section/33/

$$\frac{d^2 N(E,q)}{dE dq} \approx -\frac{1}{q^3} \operatorname{Im} \frac{1}{\tilde{\epsilon}_L(E,q)}$$
(16)

where  $\tilde{\epsilon}_L = \epsilon_1 + i\epsilon_2$  is the longitudinal dielectric function. Moreover, a dipole approximation is valid when the momentum transfer q is sufficiently small. As a result, one obtains a situation very similar to that of (S)EXAFS. By utilizing phase shifts calculated for (S)EXAFS, one may then determine/32/ near-neighbor bond distances with a quoted accuracy of 0.05 Å.

# 3.4.11. Electron-phonon scattering

We are concerned here with HREELS, /61, 62/ where the probe electrons lose a small amount of energy ( $\leq 0.5$  eV) to atomic vibrations in the surface. Two regimes are commonly discussed. In the case of "small-angle inelastic scattering", also called "dipole scattering", the energy is lost to a longwavelength phonon with small momentum transfer. The scattered electrons are made to reappear outside the surface by a LEED-type scattering, which supplies the large momentum transfer required for reflection, thus, these electrons emerge within a few degrees of LEED beam directions.

The second case is that of "impact scattering", where the lost energy is transferred to a vibrational mode by a localized impact (distances in the Angstrom range). Impact scattering can occur with small as well as with large scattering angles, but is often overshadowed by dipole scattering at the smaller angles. LEED-type elastic scatterings can occur in addition to impact scattering, but are not essential to obtain a measurable effect. However, they are unavoidable and must therefore be understood./30/

Dipole scattering does not require an atomistic theory. A phenomenological theory suffices, which includes a response function dependent on dielectric constants. The cross-section for dipole scattering based on these assumptions is given in Eqs. 3.7 and 3.9 of Ibach and Mills./61/ These formulae include plane-wave reflection coefficients from the surface, which are solutions of the standard LEED problem. Since dipole scattering involves essentially only forward scattering, it is not necessary in practice to adopt the spherical-wave picture of our step 2 (cf. section 3.4.3), the plane-wave approach is adequate in this situation.

In the case of impact scattering, an atomistic description is essential, since a short-range interaction is operative. The cross-section is then (Eqs. 3.77-79 of Ibach and Mills/61/)

$$\frac{dS}{d\Omega} = \frac{2mE_I}{h} \frac{\cos^2\theta_{out}}{\cos\theta_{in}} A \mid M \mid^2$$
(17)

74

where

$$M = (n_s + 1)^{\frac{\mu}{2}} \left(\frac{h}{2N\omega_s}\right)^{\frac{\mu}{2}} \frac{\partial f}{\partial Q_s}$$
(18)

Here *m* and *h* are the electron mass and Planck's constant,  $\theta_{in}$  and  $\theta_{out}$  the polar angles of incidence and emergence, *A* the surface area and  $n_s$  the number of vibrational quanta present (following the Bose-Einstein statistics); *N* is the number of unit cells of the surface,  $\omega_s$  the frequency of the vibrational mode and  $\frac{\partial f}{\partial \theta_s}$  the partial derivative of the atomic scattering amplitude with respect to all the nuclear displacements occurring in the vibrational mode. The latter quantity can be related to the corresponding partial derivative of the atomic scattering potential  $V(\mathbf{r})$ . If  $R_{i\alpha}$  is the nuclear displacement of atom *i* in vibration mode  $\alpha$ , one obtains in the Green function language (Eqs. 3.80-81 of Ibach and Mills/61/)

$$\frac{\partial f}{\partial R_{i_o}} = \langle \mathbf{k}_{out} | (G + GT_o G) \frac{\partial V(\{\mathbf{R}\})}{\partial R_{i_o}} (1 + GT_o) | \mathbf{k}_{i_o} \rangle$$
$$= \langle \mathbf{k}_{out} | g_{PE} \frac{\partial V(\{\mathbf{R}\})}{\partial R_{i_o}} | \psi_{LEED}^{(in)} \rangle$$
(19)

Here  $V({\mathbf{R}})$  is the scattering potential for the ensemble of scatters at locations  $\mathbf{R}_{i}$ , G is the free-space electron propagator and  $T_o$  the t-matrix for multiple scattering of the electron by the surface.

Eq. (17) clearly exhibits the different steps of the HREELS process:  $\psi_{LEED}^{(in)}$  is the LEED wave-function of the electron before the inelastic event;  $g_{PE}$  is the photo-electron propagator of the electron following the inelastic event (this includes all multiple scattering paths ending at the detector). Both  $\psi_{LEED}^{(in)}$  and  $g_{PE}$ provide the sensitivity to surface structure, while  $\frac{\partial V}{\partial R_{i\alpha}}$  contains the vibrational properties of the surface. Given the low energies in most HREELS experiments (~ 5-10 eV), the multiple scattering is extremely important and complex. Only a full multiple scattering calculation can properly simulate the diffraction effects. Nevertheless, as a function of loss energy, the widely used loss peak structure appears /61, 62/ This often leads to a relatively simple vibrational mode assignment in the case of adsorbates.

3.5. Unifying and Distinguishing Features

In this section, we shall emphasize some aspects of electron diffraction that are common to or differ among the various experimental techniques mentioned so far.

#### 3.5.1. Single vs. multiple scattering

A clarification of terminology is necessary here. In essence, we shall describe why multiple-forward scattering can often be neglected, leaving only single (back-) scattering. We recall from section 3.2 the relative predominance of forward scattering of electrons by atoms over scattering into other directions. especially at higher energies (this is reinforced by the Debye-Waller factor). It is important to realize that, as a result, multiple forward scattering is always present. For instance, in SEXAFS, where one traditionally speaks of single scattering from shells surrounding the emitting atom, there is in reality also multiple forward scattering from one atom to the next in a radial direction, whether outbound or inbound relative to the source atom. This forward scattering often takes the form of focusing of electrons beyond the scattering atom. In this case, the main effect of forward scattering, as far as structure information is concerned, is to change the effective wavelength of the electron, which can be modeled as a changed inner potential. Otherwise, forward scattering does not produce a position-dependent phase change (since  $e^{i\mathbf{s}\cdot\mathbf{r}} = 1$  for forward-scattering where the momentum transfer s vanishes, whatever the atomic position **r**).

This shows how SEXAFS can be described kinematically with a suitable inner potential. Since in SEXAFS the phase shifts are usually empirically determined from other experiments, this corrected inner potential is already implicitly built into the phase shifts. Consequently, the multiple forward scattering need not be explicitly accounted for and one can use a single-scattering theory in an effective sense.

For the same reason, LEED I-V curves for clean unreconstructed surfaces often have recognizable Bragg peaks, despite strong multiple scattering. These Bragg peaks occur at energies that may be explained kinematically with a suitably adjusted inner potential, which can differ considerably from the muffintin constant of a multiple-scattering theory: the difference is due again to the effects of forward scattering./28/

#### 3.5.2. Range of multiple scattering

Multiple scattering samples the environment of any surface atom and gives sensitivity to bond angles in addition to bond lengths within that environment. An important question is therefore how large that environment is. The determining factors are, primarily, the mean free path and, to a lesser degree, the atomic scattering amplitude. At kinetic energies of a few eV the mean free path can be large (> 10 Å) which results in a large sampled environment. The sampling radius may then be on the order of 20 Å in metals, for instance, including many tens of neighboring atoms.

As the energy is raised, the mean free path goes through a minimum near 50-100 eV and slowly increases again, while the scattering amplitude steadily but slowly decreases, especially in non-forward directions and when the Debye-Waller factor is counted in. Then the sampled environment becomes generally smaller.

We must now distinguish between different techniques. In fine-structure techniques (such as SEXAFS, EAPFS, etc.), weak back-scattering combined with the usual  $\frac{1}{r^2}$  radial decay of spherical waves limits the range of scattering to a few shells of nearby atoms. In techniques like LEED and ARPES, including ARPEFS and ARXPD, multiple forward scattering can occur along electron paths that leave any atom toward the detector or, in the case of LEED, that arrive toward any atom from the source. Such nearly straight paths extend the

sampling range relative to the fine-structure techniques. Therefore, the range of multiple scattering which matters in these techniques is mainly determined by the mean free path.

It is clear that the larger the range of multiple scattering, the more complex the corresponding calculations become. But it has been found, in the context of LEED calculations, that one may markedly cut the effective range of multiple scattering in the *less dense* materials, especially in molecular overlayers./86/ This approximation is valid because relatively few neighboring atoms are available to interfere with the primary kinematic process near a given atom. For example, in a typical organic molecule, each atom has at most four nearneighbors, compared with a maximum of 12 within a metal lattice. One may approximate the calculation by including only nearest neighbors in the multiple scattering process. This approach has been used successfully in LEED structural determination of adsorbed molecules in the method called "near-neighbor multiple scattering"./86/

#### 3.5.3. Long- vs. short-range order

We address here the question whether LEED samples only long-range order, as is often stated, rather than short range order, as do most other techniques described here. This is an important question, because many surfaces will not take on long-rang order, and this might prevent the application of LEED. We shall argue that LEED remains applicable. In the case of LEED we should make the following distinction: on the one hand, there is sensitivity to the long-range order, determined by the periodic lattice which produces the diffraction beams, and on the other hand, there is short-range sensitivity to local geometry, determined by the range of multiple scattering as discussed above. This distinction becomes clearest in the case of diffuse LEED from disordered surfaces. Then, the diffracted intensity can be expressed approximately/79/ as the product of a kinematic structure factor representing the long-range arrangement of the surface and an effective form factor representing the short-range structure, including the sampling by multiple scattering in the neighborhood of any atom.

This factorization into structure and form factors is exact in the limit of dilute identical defects in an otherwise periodic lattice, and only approximate for dense defects since multiple scattering between defects is neglected. Such a "defect" may be a vacancy or a step in an otherwise periodic surface, or a molecule in an adsorbed layer that has no long range periodicity despite longrange periodicity in the substrate (a "lattice gas"). The error made in the approximation mentioned above can be shown to be small in most cases of interest, since it involves higher-order multiple scattering events, which are relatively weak, as well as long range multiple-scattering paths, which are also relatively weak. Therefore, the main contributions to LEED intensities are due to short-range structure, through the effective form-factor, and to long-range structure, through the kinematic structure-factor, and these terms can be separated out.

This factorization into structure- and form-factors can be applied to ordered surfaces as well (the traditional application of LEED), it then decouples longrange order from short-range order. It is particularly valuable for large unit cells, because one may then simply ignore the long-range order, and also the large number of beams that give rise to very large computational efforts in the more exact traditional formalisms (where all beams are considered coupled). This approach has been implemented and tested in the Beam-Set Neglect method mentioned previously,/80/ in which most beams are ignored and only selected sub-sets of beams are included in the calculation. This BSN method has enabled the study of large adsorbed molecules, e.g. benzene, including cases of several molecules per unit cell, with a much reduced computational effort compared to previous methods. In fact, the computational effort in this approach may even be chosen to be independent of the unit cell size, instead of being proportional to its second or third power. The same BSN method has also been programmed and tested for the case of disordered overlayers./79/

# 3.5.4. Various forms of disorder

Many kinds of disorder are known at surfaces. "Clean, well-ordered" surfaces present, among others, point defects (impurities, dislocations, etc.) and line defects (steps, crystallite boundaries, etc.). Surfaces with adsorbates or reconstruction-induced superlattices can have a variety of additional defects, e.g.

79

out-of-phase, rotated or mirrored domains, disordered regions, isolated ad-atoms, etc. Also, different adsorption geometries can occur at substrate defects and atdomain boundaries. With adsorbed molecules (including adsorbed clusters), internal degrees of freedom of the molecules can lead to further disorder, e.g. rotational disorder, while chemical reactions can produce a variety of coadsorbed species.

Different surface-sensitive techniques respond differently to the various kinds of disorder. The measurement of LEED beams is unique in largely filtering out all defects that are unrelated to the superlattice periodicity that defines the beams. Other techniques (including diffuse LEED) generally include contributions from all defects, for instance from adsorbates located at undesired steps and crystallite boundaries. Then only a reduction of the defect concentration can remove defect contributions from the experimental data. Rotational disorder of adsorbed molecules does not matter for techniques which measure only bond lengths, and not bond orientations. Thus, NEXAFS is more sensitive to such disorder than SEXAFS.

In the presence of a variety of chemical species, one may distinguish between the species by various means, e.g. by selection of Auger lines in SEXAFS, or core-levels in ARPEFS, or vibrational frequencies in HREELS.

3.5.5. Layer spacings vs. bond lengths

As mentioned earlier, the electron diffraction techniques under discussion in this paper divide into two categories, depending on whether they are primarily sensitive to layer spacings and bond orientations or to bond lengths. The cause of this difference is the source of the structural information. In SEXAFS and EAPFS, for example, the structural information comes primarily from step 3 of the 4-step description, as electrons emitted from the source atom back-scatter from neighboring atoms. Angle-integrated detection is used, which tends to remove all directional information from propagation effects (step 4) and, therefore, leaves only radial information, mainly bond lengths. By contrast, angle-resolved techniques, such as LEED and ARPES, emphasize the behavior of plane waves. In these techniques a lot of the information comes from propagation effects (steps 1 and 4 of the 4-step description). These plane waves carry structural information through the phase of the interference function  $e^{i\mathbf{s}\cdot\mathbf{r}}$ where **s** is the momentum transfer between two plane waves. Therefore, only the projection of the atomic position vector **r** onto the direction of **s** is relevant, and this projection can be viewed as a layer spacing. When many beams are involved and multiple scattering occurs, many values and directions of **s** are used simultaneously, such that layer spacings in many orientations are accessible. This gives sufficient information to completely determine a surface structure.

#### 3.5.6. Bond angles vs. bond directions

We have pointed out two methods to obtain bond angles or bond directions. One uses the sensitivity of electron multiple scattering, as in LEED and NEXAFS, and the other uses variable polarization of of incident photons, together with selection rules, as in SEXAFS. The first method gives access to bond angles, i.e. the angle between two inter-atomic bonds. The second method gives access to bond directions, i.e. the absolute orientation of a bond with respect to a laboratory coordinate system. The bond angle is the chemically more relevant quantity, which can only be obtained from the bond direction with additional information of assumptions. For example, the direction of the bond between atoms A and B only provides the bond angle between atoms A, B and C if the bond direction BC is also measured or is known from previous work.

# 4. THE THEORY OF SURFACE CHEMISTRY AND BONDING

The goal of theoretical surface chemistry is to understand the surface chemical bond, and from this to be able to describe and predict the properties of atoms and molecules adsorbed on surfaces. The primary properties of interest include adsorption sites and geometries, bond lengths and angles, the electronic structure of adsorbed species, adsorption energies, diffusion energies, and the frequencies of vibrational excitations. Other properties that may be derived relate to reaction pathways, kinetics, rates and selectivities as a function of the nature of surface on which the reaction proceeds. Significant progress has been made toward this goal in the last decade using both semiempirical and *ab initio* calculational methods.

The basic approach of chemical theory to surface science is to model a surface with a cluster of a finite number of atoms, with one or more "adsorbate" atoms or molecules bonded to various sites on the cluster. In parallel with the chemical theory there is also the solid state physics approach. This starts from an "extended" surface surface model, where an array of atoms perfectly periodic in two dimensions represents both the substrate and any adsorbates. Many theoretical techniques have been developed for the extended-surface model. We can only refer the interested reader to the literature/87,88,89,90,91,92,93,94/ and remark that the relative merits of the cluster and extended-surface approaches are still very much under active debate. It is clear that certain properties, such as bonding, are very localized in character and are well represented in a cluster. On the other hand, there are properties that have a delocalized nature, such as adsorbate-adsorbate interactions and electrostatic effects, for which an extended surface model is more appropriate.

The cluster approach is, like the extended-surface approach, characterized by many different calculational schemes. A recent review stresses electronic aspects of bonding. In this review we have chosen to concentrate on geometric aspects. We shall discuss a number of major techniques in order of increasing computational complexity: the extended Hückel theory, self-consistent  $X\alpha$ scattered wave calculations, and self-consistent *ab initio* Hartree-Fock and valence bond methods. In that order these techniques allow increasing accuracy. However, the cluster size must decrease simultaneously due to calculational complexity, ultimately reducing the degree of analogy with surfaces.

82

# 4.1. The Extended Hückel Theory and Applications

The most widely used semiempirical quantum chemistry technique for theoretical chemisorption studies is the Extended Hückel Theory (EHT). The method was first proposed by Hoffmann/95/ in its nonrelativistic form, and by Lohr and Pyykkö/96/ and also Messmer/97/ in its relativistic form, based on the molecular orbital theory for calculating molecular electronic and geometric properties. For a cluster the molecular orbitals are expanded as linear combinations of atomic orbitals

$$\psi_i = \sum_{j=1}^n C_{ij} \phi_j.$$

On minimizing the total energy, one obtains a set of secular equations

$$\sum_{i=1}^{n} [H_{ij} - \epsilon S_{ij}] C_{ij} \phi_j = 0 \quad \text{for} \quad j = 1, 2, \dots, n.$$
(21)

(20)

(23)

Here *i* and *j* span the *n* atomic orbitals in the basis set of valence orbitals (core electrons are neglected) and the coefficients  $C_{ij}$  are chosen to diagonalize the Hamiltonian matrix. The quantity  $S_{ij}$  is the overlap integral between orbital *i* and orbital *j*. EHT approximates the off-diagonal matrix elements  $H_{ij}$  by the Wolfsberg-Helmholz formula/98/

$$H_{ij} = \frac{1}{2}K (H_{ii} + H_{jj})S_{ij}, \tag{22}$$

where the diagonal matrix elements  $H_{ii}$  and  $H_{jj}$  are approximated as valence state ionization potentials (IP) for atomic orbitals on atom *i* and atom *j*. The constant K is commonly taken as 1.75. The total energy is computed as a sum of one-electron orbital energies

$$E_{EHT} = 2\sum_{i} \epsilon_{i}.$$

The EHT total energy differs from the Hartree-Fock total energy  $E_{HF}$  by the neglect of the nuclear-nuclear repulsion energy  $E_{NN}$  and by the overcounting of electron-electron repulsion and exchange. The energy difference is

$$E_{HF} - E_{EHT} = E_{NN} - \sum_{i=1}^{n/2} \sum_{j=1}^{n/2} (2J_{ij} - K_{ij}).$$
(24)

Here  $J_{ij}$  and  $K_{ij}$  are the Coulomb and exchange integrals of the *i* and *j* orbital pairs. The sum in Eq. (24) is usually positive.

EHT has the advantage of being computationally an extremely simple method and can be applied to large clusters, up to a few hundred atoms. However, due to the neglect of repulsion terms in Eq. (24), the EHT binding energies for molecules are over-estimated and bond distances are too short./95/ Unrealistic electron charge transfers have also been found for diatomic molecules when the difference between the atomic electro-negativities is large./95/ Improvements can be made by calculating the ionization potential selfconsistently/99,100/ or by evaluating the matrix elements more accurately, as is done in the CNDO method./101/

Here we shall discuss a simple method of incorporating the repulsive energy terms as suggested by Anderson and Hoffmann./102/ The method is called Atom-Superposition Electron-Delocalization Molecular Orbital (ASED-MO) theory. It uses the fact that the cluster binding energy can be expressed exactly as the sum of pairwise repulsive energies  $E_R$ ; due to rigid atom superposition, and attractive electron delocalization energies  $E_D./103/$ 

$$E_{ASED-MO} = E_R + E_D \tag{25}$$

It has been shown/103/ that  $E_D$  can be approximated by a one-electron molecular orbital energy  $E_{MO}$ :

$$E_{ASED-MO} = E_R + E_{MO}$$

84

(26)

 $E_{MO}$  is obtained using Eq. (21) with matrix elements

$$H_{ii} = -IP_i$$

$$H_{ij} = 1.125 (H_{ii} + H_{jj}) e^{-0.13R_{ij}} S_{ij}$$
(27)
(28)

Here K = 2.5 has been used in obtaining  $H_{ij}$ . An exponential damping factor depending on the inter-atomic distance  $R_{ij}$  is introduced which often improves the results.  $E_R$  is given as the Coulomb interaction between the nucleus of one atom (usually the more electronegative atom) and the nuclear and electronic charges of the other. It has been shown that the simulation of two-body interactions in this way appreciably improves the calculated molecular binding energies and bond lengths /103/

There is a vast literature on the application of EHT to surface chemistry using model clusters. There are also recent reviews on this subject./104,105/ We shall discuss next specific examples relevant to chemisorption of molecules on metal surfaces for illustrative purposes.

Our first example is the widely discussed problem of CO chemisorption on transition metal surfaces. Ray and Anderson/106/ investigated CO chemisorption on a Pt (111) surface using the ASED-MO theory. In their work,  $Pt_4$  and  $Pt_{10}$  clusters were used to model the Pt (111) surface. The bulk Pt-Pt bond distance was used and other theoretical parameters are reproduced in Table II. The calculated Pt-Pt and C-O bond distances and harmonic force constants are within 8% of experimental values for isolated Pt\_2 and CO. The results for dissociation energies are less satisfactory: 94.08 and 116 kcal/mole in comparison with experimental values of 84.5 and 256 kcal/mole, respectively.

The calculated binding energy for CO adsorbed on  $Pt_4$  and  $Pt_{10}$  is largest for the 1-fold coordinated site ("top-site"), indicating a definite preference for the 1fold site. With the 3-fold coordinated site ("hollow-site"), there is a small preference for the 3-fold site which has a vacancy in the second metal layer, corresponding to the fcc hollow site of the (111) surface. The binding energies for 2-fold (bridging) and 3-fold sites are similar and the former is favored on the larger cluster. These results are supported by experiment. High-resolution electron energy loss spectroscopy (HREELS) obtained by Froitzheim et al./107/ for CO adsorbed on the Pt (111) surface indicates sequential occupation of two binding sites with increasing coverage of CO: the 1-fold site is occupied first at lower coverages, and at higher coverages the two-fold sites are also occupied by CO./108/ Infrared reflectance-absorption spectroscopy (IRAS),/109/ XPS and work function measurements/110/ also support these results. In addition the experimental adsorption energy derived from molecular beam experiments (1.52 eV)/111/ is in good agreement with the theoretical value of 1.66 eV. Both the calculated and measured force constants/111/ indicate a weakening of the C-O bond relative to gas-phase CO when adsorbed in the 1-fold site. This can be explained by charge transfer from the *sd* band of Pt to the two antibonding  $\pi^*$ 

orbital	atom	n	IP(ev)	S	С
s .	Pt	6	9.0	2.55	-
	0	2	28.48	2.246	-
	С	2	20.00	1.658	-
p	Pt	6	4.96	2.25	-
	0	2	13.62	2.227	-
	C	2	11.26	1.618	
d	$\mathbf{Pt}$	5	9.6	2.39	6.013
					0.5715
		·		:	0.6567

Table II	Extended	Hilchel F	Parameters :	for CO.Pt
Table II.	Extended	HUCKELL	arameters	

Here n = principal quantum number, IP = ionization potential,  $\varsigma = \text{orbital exponent and } C = d$ -orbital coefficient. To mimic selfconsistency in adsorption studies Pt ionization potentials are increased by 1.5 eV, O and C ionization potentials are decreased by 1.5 eV, and O exponents are decreased by 0.1 eV. CO orbitals. The calculated bond stretch is 0.07 Å. On going to the 2-fold and 3-fold adsorption sites, the C-O force constant is progressively weakened and the C-O bond lengthened.

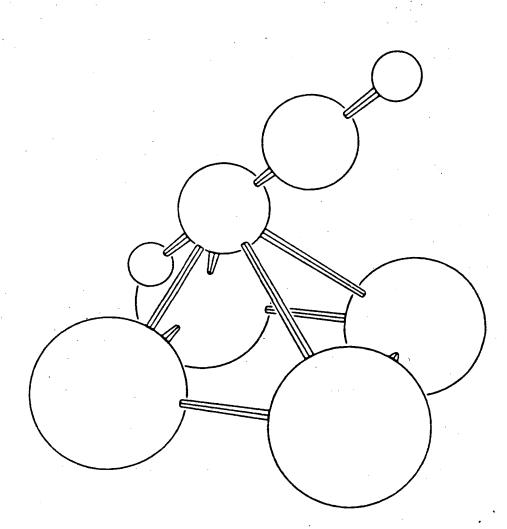
The interaction of adsorbed CO and adsorbed oxygen has also been studied to estimate the energy of activation for the oxidation of CO on Pt (111) surface. Two mechanisms have been proposed: the Langmuir-Hinshelwood mechanism and the Eley-Rideal mechanism. In the Langmuir-Hinshelwood mechanism, the associatively adsorbed CO interacts with adsorbed oxygen. The activation energy for oxidation is calculated as 1.6 eV for the transition state geometry. This is in reasonable agreement with experimental results of 1 eV./111/ In the Eley-Rideal mechanism, the CO molecule dissociates on the surface and only then interacts with the adsorbed oxygen atoms. The calculated barrier to  $CO_2$ formation is 1 eV greater than that in the Langmuir-Hinshelwood case. Both the experimental evidence and the theoretical results favor the Langmuir-Hinshelwood mechanism.

The chemisorption of hydrocarbon molecules on surfaces presents another class of important and interesting systems for study. We shall discuss the case of acetylene chemisorption on the Ni (111), Rh (111) and Pt (111) surfaces, as they incorporate many features relevant to all hydrocarbon chemisorption systems.

Gavezzotti et al./112,113/ have applied EHT to predict the chemisorption binding energies of acetylene and a number of organic fragments such as CH,  $CCH_2$ ,  $CCH_3$  and HCCH on the Ni (111), Rh (111), and Pt (111) surfaces. The metal surface was modeled by a four-atom cluster, and the acetylene bond lengths were held constant, although the C-C-H bond angle was allowed to vary. The bond length was 1.2 Å for C-C and 1.06 Å for C-H. They found the behavior of acetylene chemisorbed on these different metals to be similar. Ni, Rh and Pt catalyze the rearrangement of adsorbed acetylene to vinylidene ( $>C=C<_{\rm H}^{\rm H}$ ), and Ni was also found to catalyze the reverse reaction. However, Ni was found to be the best catalyst for carbon-carbon bond breaking in acetylene. Moreover, adsorbate-adsorbate interactions force the acetylene molecule to tilt out of the plane parallel to the surface on Ni (100), as shown in Figure 3.

Anderson and Hubbard/114/ also performed an ASED-MO calculation for acetylene chemisorbed on the Pt (111) surface. Various adsorption sites were considered in this calculation. The hollow site with the C-C axis parallel to the

87



# Ni (100) + $c(2 \times 2) C_2 H_2$

Fig. 3. Perspective view of acetylene over a hollow site of Ni(100), represented by four Ni atoms. The C-Ni bonds are drawn to indicate geometrical relationships only, not the bonding character.

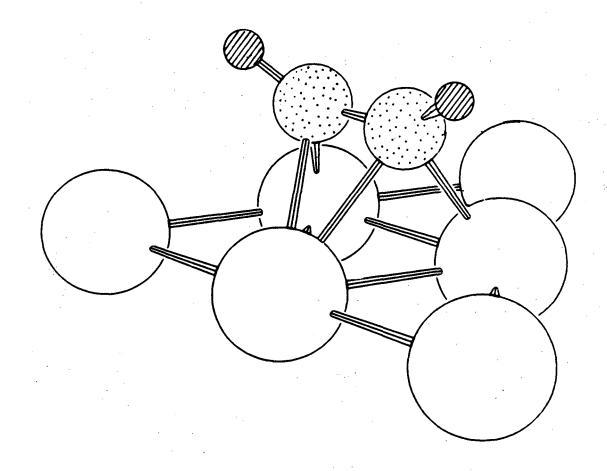
sides of the Pt<sub>3</sub> triangle was definitely preferred, in agreement with the HREELS analysis of Ibach and Lehwald,/115/ (see Figure 4). In most sites the C-H bond axes rotated away from the surface by about 55° and the C-C bond lengthened by about 0.3 Å relative to the gas-phase. This is in agreement with the bending results of Gavezzotti et al./112/ as well as the HREELS estimates of 60° and 0.24 Å for these quantities.

A very stable species found on several metal surfaces, including Pt(111), is ethylidyne, CCH<sub>3</sub>. ASED-MO calculations agree that the CCH<sub>3</sub> species does take on the structure deduced from LEED analysis, namely the C-C axis is perpendicular to the surface, with one carbon bonded equally to three metal atoms. The LEED estimates of a 2.0 Å Pt-C distance and a 1.50 Å C-C distance agree well with the calculated values of 2.0 Å and 1.55 Å (see Figure 5). Ethylidyne is produced either with acetylene co-adsorbed with H<sub>2</sub> or with ethylene adsorption, both of which are unstable relative to ethylidyne. Structures of CCH<sub>2</sub> and CHCH<sub>2</sub> have also been calculated and were found to be less stable than acetylene and CCH<sub>3</sub> when chemisorbed on Pt (111).

We conclude this section with the observation that the extended Hückel method can produce results in good agreement with experiments when used with caution and appropriate parameter searching procedures.

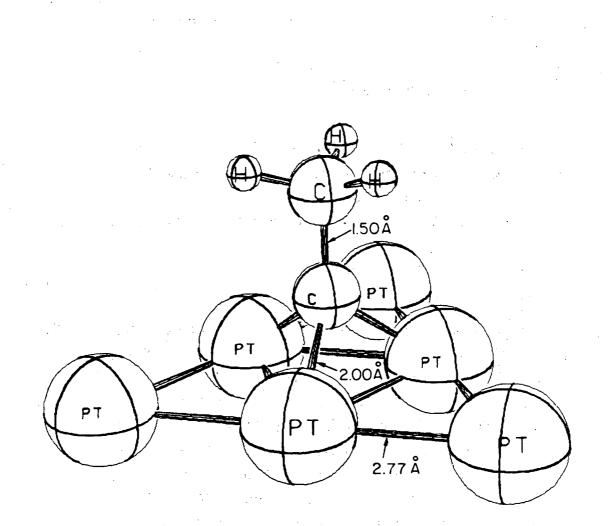
# 4.2. The SCF $X\alpha$ Scattered Wave Method

The self-consistent-field- $X\alpha$ -Scattered Wave (SCF- $X\alpha$ -SW) method was developed by Johnson/116/ to calculate electronic energy levels and eigenfunctions for polyatomic molecules and solids. In this scheme, the electronic wave functions are solved by a multiple-scattering method, equivalent to the Korringa-Kohn-Rostoker/117,118/ (KKR) method used for energy band calculations. The method has also been adapted to the calculation of magnetic problems, by use of a spin-polarized formalism,/119/ and to the case of clusters containing heavy elements, by the use of a relativistic formalism./120/ This method has been used quite successfully in correlating the electronic structure of chemisorption systems with the observed experimental photoemission spectrum



# Metastable acetylene on Pt(III)

Fig. 4. The structure of acetylene on Pt(111) as determined from HREELS data. The lines between atoms are drawn to indicate geometrical relationships only, not the bonding character.



# Pt (III) + ethylidyne

Fig. 5. The adsorption geometry of ethylidyne on Pt(111) as determined by LEED intensity analysis.

assuming known adsorbate binding geometries. It has been less successful in obtaining the adsorption binding energies via total energy calculations.

# 4.3. SCF- $X\alpha$ -SW Calculations

The SCF-X $\alpha$ -SW method makes the following major assumptions. First one replaces the nonlocal Hartree-Fock exchange potential with the X $\alpha$  local exchange potential that corresponds to the average exchange potential of a free electron gas. The exchange potential is related to the local electronic density by

$$V_{X\alpha}(\mathbf{r}) = -6\,\alpha \frac{3}{8\pi} \rho^{1/3}(\mathbf{r}) \tag{29}$$

The value of  $\alpha$  varies between 2/3 ( the Kohn-Sham potential)/121/ and 1 (the Slater potential)./122/ Different methods for determining the value of  $\alpha$  have been proposed. Usually the value of  $\alpha$  for an isolated atom is determined by requiring that the total energy, using the statistical approximation, should equal the precise Hartree-Fock energy/123/ or the experimental value. The latter takes into account the atomic correlation energy in a phenomenological way. In a molecule or cluster  $\alpha$  values are usually chosen in one of two ways. The values of  $\alpha$  characteristic of the various atoms may be used within each atomic core, and an average may be used in the region between atoms; alternatively, one may set the parameter  $\alpha$  to a universal value in all regions. /124/ Using the statistical approximation, no Slater determinant is required for the electronic wave functions. Instead, we have a one electron equation

$$\left[-\nabla^2 + V(\mathbf{r})\right]\psi(\mathbf{r}) = E \ \psi(\mathbf{r}) \tag{30}$$

where  $V(\mathbf{r}) = V_c(\mathbf{r}) + V_{X\alpha}(\mathbf{r})$  and  $V_c$  is the Coulomb potential. Once the eigenvalues and eigenfunctions for this problem are determined, one assumes that the orbitals of the lowest energy are occupied up to a Fermi level. From the resulting charge densities, one may compute the total energy of the cluster, using the statistical approximation for the exchange-correlation energy.

The second assumption of the SCF-X $\alpha$ -SW method is the introduction of "muffin-tin" approximation to the potential. Each atom j in the cluster is represented by a sphere of radius  $b_j$  where the inside of these spheres constitutes the so-called region I. The potential  $V^j(\mathbf{r})$  in each sphere is spherically symmetric and nonoverlapping in the original SCF-X $\alpha$ -SW method. Later, overlapping spheres were introduced to improve the results of total energy calculations./124/ The entire cluster is then surrounded by a sphere of radius  $b_o$ , which is the smallest sphere containing all the atomic spheres of region I. The outside of this large sphere defines the region III, in which the potential  $V(\mathbf{r})$  is also taken to be spherically symmetric. The space between the small spheres of region II. Within region II, the potential is taken as a constant  $\overline{V}$ ; which is the volume average of  $V^j(\mathbf{r})$  in region II. Assuming that the position of the nucleus of the *j*th atom is at  $\mathbf{R}_j$ ,  $(j = 1, 2, \dots, N)$  and the center of the outer sphere is at  $\mathbf{R}_o$ , then:

$$V(\mathbf{r}) = \begin{cases} V^{j}(r_{j}) & \text{region I}; \quad r_{j} = |\mathbf{r} - \mathbf{R}_{j}| \leq b_{j} \\ \overline{V} & \text{region II}; \\ V^{o}(r_{o}) & \text{region III}; \quad r_{o} = |\mathbf{r} - \mathbf{R}_{o}| > b_{o} \end{cases}$$
(31)

The self-consistent field calculation requires that as a first approximation  $V_j$  be calculated for each atom j with its associated atomic electron density. The total potential V is then obtained as a superposition of the atomic potentials:

$$V(\mathbf{r}) = \sum_{j=1}^{N} V^{j}(r_{j})$$
(32)

Next the total potential is made spherically symmetric within each atomic sphere and in region III. The constant potential  $\overline{V}$  in region II is obtained by

$$\overline{V} = (\Omega_{II})^{-1} \int_{\Omega_{II}} V(\mathbf{r}) \, d\mathbf{r}$$
(33)

where  $\Omega_{II}$  is the volume of the interatomic region. It should be noticed that the

potential in each atomic region includes not only the contribution of the atom located at its center but also the spherically averaged contribution from all other atoms.

After constructing the  $X\alpha$  potentials in each region, the one-electron Schrödinger equation can be solved by matching together separate solutions in regions I, II and III, just as in the KKR method for crystals. The wave matching conditions lead to a determanental equation, which can be solved only for certain values of E, the eigenvalues. The corresponding wave-functions yield a new electron density, from which the procedure can be iterated.

We will now discuss the advantages and disadvantages of the SCF-X $\alpha$ -Scattered Wave method. The *ab initio* approach is the major advantage of this method, while it has the flexibility of semi-empirical methods through the incorporation of adjustable parameters such as  $\alpha$  and the muffin tin radii. It also need not treat the core and valence electrons separately: both are handled as parts of the same calculation. On the other hand, the unrealistic "muffin-tin" approximation is disadvantageous in that the bonding between atoms in the constant potential region is overestimated./125,126/ This results in unreliable total energy values. Although overlapping atomic spheres/127/ and non muffintin corrections/128/ have been introduced to compensate for this problem, such corrections increase the computational work considerably.

This shortcoming is avoided in the Hartree-Fock-Slater method by removing the muffin-tin approximation./128/ This will be discussed in section 4.5. The SCF-X $\alpha$ -SW method has nevertheless been able to score successes in the determination of surface structures. This success comes from the sensitivity of the calculated surface density of states (DOS) to the surface geometry. It is true that the orbital energies obtained by the SCF-X $\alpha$ -SW method contain unwanted self-interaction energies and are different from the HF orbital energies./129/ However, by using Slater's transition-state theory,/128/ which assumes that  $\frac{1}{2}$ electron is in the initial-state orbital energies, since the self-interaction terms partially cancel, and most of the relaxation energy is included. In this way good agreement between the calculated DOS with a given adsorbate geometry and the experimental photoemission spectra is often obtained, so that the most favorable adsorbate geometry may be determined. However, the interpretation of experimental photoemission spectra presents its own complications, which can induce uncertainties in structural determinations. We shall discuss recent applications of this method in the next section.

# 4.4. Results of the $X\alpha$ -Method

Determination of the adsorbate bonding geometries for CO chemisorbed on the Cu (100) surface provides an interesting example of the  $X\alpha$ -SW method. This example illustrates the problems of interpreting photoemission spectra, since the location of CO on Cu(100) is found to be on a top-site by LEED, while  $X\alpha$ -SW calculations either favor a 4-fold hollow site or are inconclusive. Yu/130/ has carried out calculations for CuCO and Cu<sub>5</sub>CO clusters with CO bonded to the Cu surface through the carbon atom. In CuCO the CO molecule was put directly on top of a Cu atom and in Cu<sub>5</sub>CO it was located in the four-fold coordinated hollow site, simulating CO adsorbed perpendicular to the (100) surface. The calculated valence density of states for the four-fold adsorption site gives a satisfactory interpretation of the two main peaks observed below the copper d-band in the UV photoemission spectrum (UPS)./131/ An observed weak third peak can be correlated with a minority of CO molecules adsorbed directly on top of a copper atom.

Messmer and Lamson later calculated core and valence photoemission spectra using the  $X\alpha$ -SW method and offered another explanation for the CO-Cu (100) UV photoemission spectra./132/ They pointed out that, in addition to the main photoionization transitions, the outgoing electron can also excite valence electrons. Assuming that a Cu<sub>5</sub> cluster with CO bonded in a four-fold coordinated hollow-site models the Cu (100) surface, they obtained theoretical DOS to compare with the experimental UPS of Norton et al.133

The experimental spectrum was resolved into four peaks. Two of these are assigned to three shake-up transitions labeled  $1\pi_+$ ,  $4\sigma_+$  and  $5\sigma_+$  arising from a hole in each of the  $1\pi$ ,  $5\sigma$ , and  $4\sigma$  orbitals. A third peak is assigned to the  $1\pi$  and

95

 $5\sigma$  ionizations and the fourth peak to the  $4\sigma$  transition. Messmer and Lamson conclude that CO adsorption in the four-fold symmetric hollow site is sufficient to explain the observed UPS data.

A theoretical interpretation of the core-level satellite structure in the x-ray photoemission spectrum was also offered by Messmer et al./134/ using a larger  $Cu_gCO$  cluster and assuming the chemisorption of CO in the one-fold and four-fold sites of the Cu (100) surface. The qualitative differences in the intensity distributions suggest that the  $Cu_gCO$  cluster is a better model than the smaller  $Cu_sCO$  cluster for the Cu (100) surface.

A three-peak structure of the carbon 1s x-ray photoemission spectrum for CO chemisorbed on Cu (100) is obtained experimentally. The structure is from the photoionization of a carbon 1s electron, where three final ion states with roughly the same energies but different degrees of hole screening are excited. These differences in hole-screening lead to the observed differences in the carbon 1s binding energies.

A molecular orbital study using the  $X\alpha$ -SW method suggests that the first peak in the experimental XPS data arises from a transition between the ground state of the neutral chemisorption system and a final state in which a core hole in the CO molecule is created, together with the transfer of an electron from Cu to the  $2\tilde{\pi}_b$ -orbital of the chemisorption system. The other two peaks are caused by shake-up excitations from this core-hole-ion ground state. One of these two peaks can be viewed as a transition from this ground state ion to an excited-state ion via an excitation of electron from the  $2\tilde{\pi}_b$ -orbital to the higher energy  $2\tilde{\pi}_a$ orbital. The other peak is described as a one-electron excitation from the  $1\tilde{\pi}'$ level to the  $2\tilde{\pi}'$  level. Unfortunately the core level shake-up spectra calculated for the 1-fold and 4-fold sites are qualitatively very similar, and this rules out a definite conclusion regarding the CO binding site on the Cu (100) surfaces.

Another way of making geometric structural determinations with  $X\alpha$ -SW calculations is to compare the adsorbate photoemission energy level shifts with theoretical level shifts obtained with the assumed binding geometries. An example is the adsorption of ethylene (C<sub>2</sub>H<sub>4</sub>) on Ni (111).

In the so-called  $\pi$ -bonded model, the C<sub>2</sub>H<sub>4</sub> molecule lies flat on the surface and a  $\sigma$ -bond is formed by the overlap of the Ni  $d_{z^2}$  orbital and the C<sub>2</sub>H<sub>4</sub>  $b_{3u}(\pi)$ - orbital, which donates charge to the nickel atoms. The " $\pi$ -back-bonding" refers to charge transfer from the Ni  $d_{xz,yz}$ -orbitals into the unoccupied  $C_2H_4 \ b_{2g}(\pi)^*$ orbital. UPS spectra show an ethylene derived  $\pi$ -level with a bonding shift of 0.9 eV for adsorption on Ni (111), in addition to a relatively uniform relaxation shift for both the  $\pi$ - and  $\sigma$ -type orbitals./135/ The X $\alpha$ -SW calculation of Rösch and Rhodin/136/ for the Ni<sub>2</sub>(C<sub>2</sub>H<sub>4</sub>) cluster gave a 0.72 eV bonding shift for the C<sub>2</sub>H<sub>4</sub>  $b_{3u}(\pi)$  orbital of the  $\pi$ -bonded complex and a 0.30 eV shift in the di- $\sigma$ bonded complex.

Howard and Dresselhaus later did calculations for the  $\pi$ -bonded model using a Ni<sub>10</sub> cluster and found that the level structure as a whole exhibits slow oscillations in energy from iteration to iteration./137/ An accurate level shift cannot be determined without artificially shifting and aligning the calculated Fermi energy with the experimental one for the chemisorption system. The resulting level structure can explain the reported activation energy difference for ethylene hydrogenation on paramagnetic and ferromagnetic nickel. It is due to shifts in the Ni *spd* levels relative to the ethylene  $b_{3u}(\pi)$  bonding orbital level, via an exchange splitting of ~ 0.1 eV.

Finally we discuss the case of CO bonding to a platinum (100) surface using the relativistic version of the X $\alpha$ -SW method./138/ Adsorption in the top, bridge and four-fold hollow sites with the carbon atom bonded to the metal were examined for PtCO,  $Pt_2CO$  and  $Pt_5CO$  clusters, respectively. In general, the sband in the transition metals hybridizes with the *d*-band and at the same time participates in bonding with an adsorbate. However, its hybridization with the d-band is sufficiently weak so the general appearance of the latter remains intact. When relativistic spin-orbit coupling is included the *d*-band splits into  $d_{3/2}$  and  $d_{5/2}$  components. Strong  $d_{3/2}$ - $d_{5/2}$  hybridization is observed only for the sp or spd orbitals, which are largely responsible for bonding among the Pt atoms. Upon addition of the CO molecule, the metal bands undergo different changes in each model cluster. In all cases, the s-band which overlaps the dband, and which participates in bonding as well as back-bonding with CO, is partially depleted in the *d*-band region. The orbitals responsible for bonding between CO and Pt clusters are the 5 $\sigma$  and  $2\pi^*$  in the generally accepted bonding picture of 5 $\sigma$  donation and  $2\pi^*$  back-donation. The energy position of the 5 $\sigma$ orbital with respect to the centroid of the d-band remains fixed for all three

97

clusters. In all cases the C-Pt bond involves at least one antibonding orbital. In the  $Pt_5CO$  cluster, but not the other two, one of these antibonding orbitals is occupied. Thus, qualitatively, we expect the four-fold site to have the lowest binding energy among the three sites considered for CO-Pt (100). This prediction is confirmed by HREELS observations.

In the two previous sections, we have discussed the use of the basic SCF- $X\alpha$ -SW method. The advantage of this method is its computational efficiency relative to other *ab initio* methods which allows larger clusters to be handled. The disadvantage is the inadequacy of the "muffin-tin" approximation for systems with low symmetry or open structure, which renders the determination of orbital energies and total binding energies unreliable. In the following section we shall describe an improved method which relaxes the "muffin-tin" approximation and is potentially valuable in adsorbate structure determination.

4.5. The Hartree-Fock-Slater Method and its Applications

In the Hartree-Fock-Slater (HFS) method, one solves the  $X\alpha$  one-electron equation (Eq. (21)) directly without using the muffin-tin approximation. Various approaches can be taken. The scheme called discrete variational linear combinations of atomic orbitals (DV-LCAO) uses Slater type orbitals (STO) as variational basis functions./139/ The charge density required to calculate  $V_c$  and  $V_{X\alpha}$  is cast into a STO-based multipolar form by applying a fitting procedure to each product of orbital pairs. Highly accurate results can be obtained, but the large basis sets are only treated with difficulty. Alternatively, the discrete variation self-consistent charge (DV-SCC) scheme uses numerical atomic-like wave functions as variational basis functions./140/ Since these numerical basis functions can be chosen to form a computationally highly efficient contracted basis set, larger clusters may be treated. To facilitate the calculations, a shape approximation to the charge density is obtained through a Mulliken population analysis/141,142/ of the cluster eigenvectors which leads to spherically overlapping charge densities and Coulomb potentials. Generally DV-SCC results are found to be of intermediate quality, between  $X\alpha$ -SW and full potential DV-LCAO results.

An example of such an application is the calculation of molecular ionization energies for oxygen chemisorbed on Ni (100) surfaces using the DV-SCC method. A Ni<sub>5</sub>O cluster was used to model chemisorbed oxygen in the c(2x2) configuration in four-fold symmetric hollow sites on the Ni (100) surface. The vertical distance of the oxygen atom to surface plane is taken as 1.7 a.u., a height near that inferred from LEED data. All 148 electrons of  $Ni_5O$  were explicitly treated with  $\alpha = 0.7$  and basis sets including the 4s and 4p nickel states. At this height the oxygen valence levels ( $\sigma$  and  $\pi$  type) are strongly perturbed by mixing with the metal 3d, 4s, and 4p orbitals of  $a_1$  and e symmetry. The 12e orbital of the Ni<sub>5</sub>O cluster, which has a dominant oxygen 2p character, was found to have a binding energy of 10.8 eV. The UPS spectra of Eastman and Cashion/143/ and the ion neutralization spectra of Hagstrum and Becker/144/ for oxygen on Ni (100) show a broad peak (  $\sim 2 \text{ eV}$  wide) centered 5.5 - 6.0 eV below the Fermi energy. This corresponds well to the calculated oxygen 2p level. In addition, some high lying (4.7 eV above the Fermi energy) antibonding levels can be correlated directly with the HREEL spectrum obtained by Andersson /145,146/

Rosén et al./147/ and Ellis et al./148/ have carried out calculations using the DV-LCAO method for CO chemisorbed on the Ni (100) surface at various binding sites. They used NiCO and Ni<sub>5</sub>CO clusters for the top site configuration, a Ni<sub>2</sub>CO cluster for the bridge bonding configuration and a second Ni<sub>5</sub>CO cluster for the four-fold hollow site configuration. The experimental HREELS measurements of Andersson for c(2x2) CO on Ni (100) show two vibrational losses, which are assigned to the Ni-C and C-O stretch vibrations of CO linearly bonded to nickel atoms (top-sites)./145,146/ At low coverage, Andersson also found vibrational excitations assigned to CO bridge bonded to two surface nickel atoms.

Total energy calculations of sufficient precision would be able to determine the energetically favorable adsorption site. Such calculations are still much more difficult than the calculation of orbital energy levels and vibrational frequencies. Values of the Ni-Ni bond distance were chosen to correspond to the bulk crystal structure. In the DV-LCAO calculations the C-O and C-Ni bond distances were taken from known nickel-carbonyl bond distances./149/ The results showed that one-electron binding energies in these clusters are relatively insensitive to the site geometry. The comparison between the theoretical and experimental stretching frequencies for chemisorbed CO did not provide firm evidence for one specific chemisorption site. However, the theoretical results are sensitive to geometrical factors such as the Ni-C and C-O bond distances, and the possible variation of the CO molecular axis from the surface normal. Several LEED results confirm the HREELS observation of top sites without tilting, and support the bond lengths assumed in the DV-LCAO calculations. In addition, a comparison of experimental angle-resolved UPS measurements /150/ with theoretical calculations/151/ showed that CO is chemisorbed with its molecular axis normal to the surface within 5°. A tilted molecule would give a split  $\pi$  level. However, this splitting is estimated to be quite small./151/

The chemisorption of chalcogen atoms on Ni surfaces has been investigated by many techniques (see Table VI). As a result of LEED and other studies the geometrical structure of chalcogens chemisorbed on nickel surfaces is well established. Chalcogen atoms generally adsorb in the site with maximum coordination on close packed nickel surfaces; 4-fold coordinated on the (100) and (110) surfaces, and 3-fold coordinated on the (111) surface. Recently Cao et al./152/ carried out DV-LCAO calculations investigating the spectroscopic and bonding properties of S, Se and Te atoms chemisorbed on Ni (100), (110) and (111) surfaces. The model clusters they used were Ni<sub>5</sub>S and Ni<sub>9</sub>S<sub>2</sub> for Ni (100), Ni<sub>5</sub>S for Ni (110) and Ni<sub>7</sub>S for Ni (111) corresponding to the binding sites found by LEED. Their calculations of the variation of adsorbate energy levels with adatom spacing above the metal surface are in good agreement with the results of the LEED structural analyses.

Finally, we conclude this section by drawing attention to the recent development of total energy calculations within the  $X\alpha$  approximation. A total energy algorithm specially implemented for calculating small energy differences in large systems has been developed by Ziegler for chemisorption studies./153/ Ellis et al. also developed a method within the HFS approximation to handle this problem and the results for a series of clean copper clusters, namely Cu<sub>2</sub>, Cu<sub>4</sub>,  $Cu_{13}$  and  $Cu_{79}$  are very encouraging. Direct binding site determination via accurate total energy calculations for clusters of sufficient sizes is likely to play a more important role in the near future.

4.6. The *ab initio* Quantum Chemical Calculation

In the previous two sections we have discussed the semiempirical extended Hückel theory and the SCF- $X\alpha$ -SW method. We have detailed the advantages and disadvantages of these methods for surface structure determination. However, there exists a vast literature of *ab initio* quantum chemical methods which are described in terms of either the molecular orbital (MO) or valence bond (VB) schemes for determining the electronic and geometric structure of molecules. The application of these methods to surface problems has advanced rapidly in recent years, as we shall discuss in this section.

The most commonly used *ab initio* method is the self-consistent field Hartree-Fock (SCF-HF) scheme with or without configuration interaction (CI). In the Hartree-Fock method, the wave function for a closed shell singlet state has the antisymmetrized form

$$\psi_i = A \left( \phi_1 \alpha \phi_1 \beta \phi_2 \alpha \phi_2 \beta \cdots \phi_n \alpha \phi_n \beta \right) \tag{34}$$

with each orbital appearing twice for the two spin states  $\alpha$  and  $\beta$ . The equation satisfied by the one-electron orbital  $\phi_i$  is written as

$$[h_{eff} + \sum_{j} (2J_i - K_i)] \phi_i = \epsilon_i \phi_i$$
(35)

Here  $h_{eff}$  contains the kinetic energy operator and the electron-nucleus attraction interaction.  $J_j$  and  $K_j$  are the usual Coulomb and exchange operators. Eq. (35) can be solved by a self-consistent iteration procedure within the LCAO approximation. Filling these molecular orbitals up to the Fermi energy gives the ground state electronic configuration for the system. For open-shell systems when a few determinants of the form of Eq. (34) are combined, the resulting oneelectron equations can be solved using the multiconfiguration SCF (MCSCF) method. The SCF-HF results neglect electron-electron correlation effects. The configuration interaction includes these effects by formulating a multiconfiguration electron state as

$$\Psi = \sum_{i} c_{i} \psi_{i}$$

(36)

where the  $c_i$ 's are coefficients to be determined variationally.

Numerous studies have applied SCF-HF, MCSCF and SCF-HF-CI methods to surface problems./154,155,156,157,158,159,160,161,162,163/ One particularly interesting example is an explanation of the origin of the coveragedependent vibrational frequency shift for oxygen on Ni (100). Bauschlicher and Bagus have carried out SCF studies for the Ni<sub>25</sub>O and Ni<sub>25</sub>O<sub>5</sub> clusters to model the p(2x2) and c(2x2) structures of O on Ni (100), respectively./164/ The cluster contains a four-atom by four-atom square top layer and a three-atom by threeatom second layer. Four oxygen atoms are located in hollow sites for the (2x2) arrangement and a fifth centered atom is added for the c(2x2) arrangement. The spacing between the oxygen atoms and the first Ni layer is varied. For the Ni<sub>25</sub>O<sub>5</sub> cluster, the four atoms placed at the outer four-fold sites are given an equilibrium spacing determined from Ni<sub>25</sub>O calculations where only one oxygen is present, centered on the square top layer. The spacing of the central atom is then allowed to vary.

The Ni atoms are treated as one-electron systems in which the effects of the Ar-like core and the nine 3d electrons are replaced by a modified effective. potential (MEP) as suggested by Melius et al./165/ A contracted gaussian basis set is used for Ni, which includes two functions to describe the 4s and one to describe the 4p atomic orbitals. Since a previous study/159/ found the O-Ni spacing and the vibrational frequency  $\omega_e$  insensitive to correlations in this openshell system, the authors have adopted the SCF calculation scheme. To check the approximation of treating the Ni atoms as a one-electron system, they performed both the MEP and an all electron SCF calculation for the Ni<sub>5</sub>O cluster. They found that the MEP spacing is 0.37 Å or 35% smaller than the all-electron value; the MEP  $\omega_e$  value is 90 cm<sup>-1</sup> or 24% smaller. Since the 3d orbital extends into the valence region where the 4s electron density is substantial, a correction needs to be added to the MEP calculation to take the 3dpenetration into account. This was done phenomenologically by replacing the core charge of +1 by a distance-dependent  $Z_{eff}(R)$ . When this correction is included, the resulting spacing and  $\omega_e$  values are in good agreement with the all-electron values. They found that for Ni<sub>25</sub>O, the spacing is 0.83 Å and for  $m Ni_{25}O_5$  it is 0.72 Å. The  $\omega_e$  values are 400 and 315 cm<sup>-1</sup>, respectively./166/ The  $\omega_e$  values measured in HREELS experiments are 430 and 310 cm<sup>-1</sup> for p(2x2)-Ni(100)-O and c(2x2)-Ni (100)-O. The spacings obtained from EXAFS experiments are  $0.86\pm0.07$  Å for both p(2x2)-Ni (100)-O and c(2x2)-Ni (100)- $O_{167}$  LEED analyses have yielded a spacing of  $0.9\pm0.1$  Å for both coverages./168,169/ These calculations do not support the possibility of having two states, i.e., an O radical state for p(2x2) and an oxide state for c(2x2)coverages. The two states were previously suggested by Upton and Goddard/170, 171/as an explanation for the two different Ni-O vibration frequencies.

Another interesting example of MCSCF calculation is the determination of the oxygen binding site on Si (100). Batra et al performed this work for a few model clusters for oxygen chemisorbed at one, two and four-fold coordinated sites on  $Si_3H_6$ ,  $Si_6H_{12}$ , and  $Si_7H_8$  clusters /172/

They attempted to resolve the controversy regarding the dissociative chemisorption of oxygen on semiconductor surfaces. The energy-minimized geometries and absolute binding energies are listed in Table III. Since the binding energy of  $O_2$  is 2.6 eV per oxygen, dissociative chemisorption is found to be energetically favorable and is exothermic by 3 eV. Moreover, the two-fold bridge site is calculated to be more stable than the one-fold top and four-fold hollow sites. The calculated interatomic distance for the on-top site, 1.64 Å, is in good agreement with the value obtained by Goddard et al., of 1.69 Å./173,174/ Since the treatment of correlation effects in MCSCF is limited, the dissociation energies are expected to increase when a more accurate configuration interaction calculation is performed.

Comparing the calculated vibrational frequencies with the HREELS data/175/ also yields a reasonable interpretation. For Si (100) at low  $O_2$  exposures at 700 K, two major EELS peaks were reported, one at 1060 cm<sup>-1</sup> and

coordination	1-fold	2-fold	4-fold	
model cluster	Si <sub>3</sub> H <sub>6</sub> O	$Si_6H_{12}O$	Si <sub>7</sub> H <sub>3</sub> O	
spacing (Å)	1.64	0.06	0.96	
bond length (Å)	1.64	1.92	2.88	
energy (eV)	3.81	4.28	0.27	
$\omega_e \ ({ m cm}^{-1})$	866	288	106	

All silicon atoms which are not involved in Si-O bonding are 4fold coordinated, with all dangling (non Si-Si) bonds taken up by Si-H bonds.

the second at 866 cm<sup>-1</sup>. A third low intensity peak is at 370 cm<sup>-1</sup>. The authors assigned the high-frequency peak to the top-site and the lower frequency 866 cm<sup>-1</sup> peak to the bridge site. The third low intensity peak can be associated with adsorbed  $O_2$  or O atoms in an initial or intermediate stage of oxidation of Si to form SiO<sub>2</sub>.

While the above mentioned *ab initio* calculations produced good results for surface structure determinations, their computational cost is often high. In most formulations, the cost arises from the large number of two-electron integrals to be evaluated. The number of integrals increases as  $n^4$  for *n* basis functions, so that computations become lengthy when large basis sets are required to achieve accuracy. This places practical restrictions on the applicability of *ab initio* techniques. One possible simplifying approach is to consider exact evaluations of certain important integrals in the  $n^4$  list and to approximate the remainder. This idea was first applied to molecular problems by Whitten./176/ He introduced the notation

$$\langle g_i(1)g_j(1) | \frac{1}{r_{12}} | g_k(2)g_l(2) \rangle = [\phi_{ij} | \phi_{kl}]$$
 (37)

for electron repulsion integrals where g denotes an arbitrary basis function. He then showed that

$$|[\phi_{ij} \mid \phi_{kl}] - [\phi_{ij'} \mid \phi_{kl'}]| \le \delta$$

where

$$\delta = \epsilon_a^{\frac{1}{2}} \epsilon_b^{\frac{1}{2}} + \epsilon_a^{\frac{1}{2}} K_b^{\frac{1}{2}} + \epsilon_b^{\frac{1}{2}} K_a^{\frac{1}{2}}$$
(39)

$$\epsilon_m = [\phi_m - \phi_m' | \phi_m - \phi_m'] \text{ and } K_m = [\phi_m | \phi_m'], \quad m = a, b$$
 (40)

Here  $\phi_{ij} = g_i g_j$  and  $\phi_{kl} = g_k g_l$  are used to approximate the electron densities  $\phi_{ij}'$  and  $\phi_{kl}'$ . The attractiveness of this approach is due to the simple structure of the error bound  $\delta$  which can be calculated separately for the pair of densities  $\phi_{ij}$  and  $\phi_{kl}$ , yielding a number of integrals proportional to  $n^2$ . One can then obtain the approximated density by minimizing  $\delta$  with respect to all parameters in  $\phi_{ij}$  and  $\phi_{ij}'$ . This method is called the error bound method. Its results have been shown to be quite successful in many cases.

In addition to the error bound method to approximate two-electron integrals, Whitten and Pakkanen also proposed a new embedding theory to increase the cluster size that could be used for chemisorption studies /177 Let us assume that molecular adsorption is taking place at a chosen site of well-defined geometry. Let the adsorbate be characterized by a set of orbitals  $\{\phi_k^A\}$  with energies  $\{\epsilon_k^A\}$  and let the metal substrate be characterized by another set of orbitals  $\{\phi_l\}$  with eigenvalues  $\{\epsilon_l\}$ . For large metal clusters, the number of orbitals in  $\{\phi_l\}$  is very large and the energy levels  $\{\epsilon_l\}$  are densely spaced. Whitten and Pakkanen proposed a so-called "localization" scheme in which the interaction of the adsorbate levels with the large number of metal levels can be described by those orbitals for which the interaction  $| \langle \phi_k^A | H_{eff} | \phi_l \rangle |$  is large. A unitary transformation can be introduced such that  $| < \phi_k^A | H_{eff} | \phi_l > |$  is maximized. This procedure yields one set of functions which physically represent orbitals localized on the designated surface atoms, bonds between these atoms, as well as bonds linking the designated atoms with the remainder of the cluster. A second set of functions consists of so-called interior orbitals. They are treated as an invariant core in each configuration for the step of the configuration

(38)

interaction. Thus, for an n-electron chemisorption system the interior orbitals contribute a fixed Coulomb and exchange field acting on the n electrons included explicitly.

The application of the error bound method and the embedding theory may be illustrated by a SCF-HF-CI calculation for  $H_2$  on Ti (0001)./178/ It was found by this method that dissociative adsorption of  $H_2$  occurs for the Ti<sub>7</sub>H<sub>2</sub>, Ti<sub>10</sub>H<sub>2</sub> and Ti<sub>38</sub>H<sub>2</sub> clusters. The top, bridge and three-fold hollow sites were considered.  $H_2$  was allowed to approach the surface with its axis parallel and perpendicular to the surface plane and the H-H bond was also allowed to stretch. The authors found that dissociative chemisorption occurs and the most stable adsorption geometry is in the 3-fold symmetric site with H spaced 1.3 Å above the surface. Adsorption of two hydrogens in adjacent 3-fold sites (about 1.5 Å apart) is less stable than in next-nearest 3-fold sites or more distant sites. The calculated adsorption energy of 45 kcal/mol for  $Ti_{38}H_2$  compares favorably with experiment (the adsorption geometry is otherwise not known, but by analogy with Ni (111), 3-fold hollow sites are likely). The chemical bond involves mainly the 4s electrons of the metal interacting with the hydrogen and a polarized substrate electron distribution, but d-electron bonding and correlation significantly increase the binding energy. The binding energies calculated for the smaller clusters are in most cases a few tenths of an eV larger than those calculated for the larger clusters. Similar calculations have also been carried out by Madhaven and Whitten for the chemisorption of  $H_2$  on Cu (100) using a  $Cu_{38}H_2$  cluster /179/They found that  $H_2$  dissociative chemisorption is activated in that case. The  $H_2$ binding energies are in the range of 13-22 kcal/mol. The activation barrier is about 35-40 kcal/mol due to the repulsion of molecular  $H_2$  by the surface and the difficulty of stretching  $H_2$  at a significant distance above the surface. It was also concluded from these calculations that the effect of the 3d-electrons, either in terms of direct 3d-4d mixing or in terms of 3d-4s promotion is unlikely to assist the dissociation of  $H_2$  on the Cu surface.

Finally we discuss the Generalized Valence Bond (GVB) method as proposed by Hunt, Hay and Goddard./180,181,182/ This is a method aimed at improving some of the HF procedures, for instance to obtain the correct dissociation limit, and to partially include correlation effects. The basic idea is that the  $\phi_i \alpha \phi_i \beta$  type of orbitals in Eq. (34) be replaced by

$$\phi_{ia} \alpha \phi_{ib} \beta, \tag{41}$$

such that each spin can have a different spatial orbital  $\phi_{ia}$  or  $\phi_{ib}$ , instead of having the same spatial orbital  $\phi_i$  for both spins. This yields the wave function

$$\psi_{i} = A \left( \phi_{1a} \alpha \phi_{1b} \beta \phi_{2a} \alpha \phi_{2b} \beta \cdots \phi_{Na} \alpha \phi_{Nb} \beta \right)$$
$$= \left( \phi_{1a} \phi_{1b} \phi_{2a} \phi_{2b} \cdots \phi_{Na} \phi_{Nb} \chi \right)$$
(42)

where  $\chi$  is a general N-electron spin function and the orbitals  $\phi_{ia}$  and  $\phi_{ib}$  are solved for self-consistently. The dependence of the energy upon the orbital pair *i* has the form

$$E = E_{(i)} + f_{1i} < \phi_{1i} | 2h_{eff} + J_{1i} | \phi_{1i} > + f_{2i} < \phi_{2i} | 2h_{eff} + J_{2i} | \phi_{2i} >$$
  
+  $C_{1i}C_{2i} < \phi_{1i} | K_{2i} | \phi_{1i} >$  (43)

where i = a, b;  $h_{eff}$  is the usual HF Hamiltonian excluding the orbital pair *i*,  $E_{(i)}$  is independent of the orbitals in pair *i* and  $f_k$  is a constant which depends on the orbital occupancy. Separating from  $E_{(i)}$  the terms involving the other pairs, the authors obtained the general expression

$$E = \sum_{k} f_{k}h_{k} + \sum_{k,l} (a_{kl}J_{kl} + b_{kl}K_{kl})$$
(44)

which gives, upon using the variation principle

$$\overline{H}_k \phi_k = [H_k - \sum_{j \neq k} | j > < j | H_j] \phi_k = \epsilon_k \phi_k, \quad k = 1, 2, \dots, n$$
(45)

where

$$H_k = f_k h + \sum_l \left( a_{kl} J_l + b_{kl} K_l \right)$$

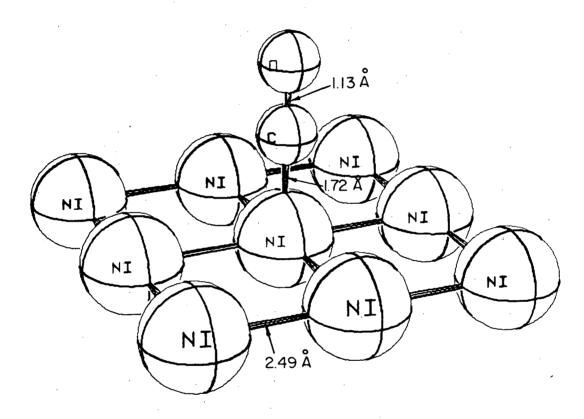
(46)

and n is the number of distinct orbitals. J and K are the usual Coulomb and exchange operators from HF theory. Eq. (46) can be solved self-consistently. Since the GVB method allows paired electrons which have different spins to occupy different spatial orbitals, some correlation is included in solving the GVB equation, which removes many difficulties and inconsistencies of the HF method. Using the GVB wave functions one can include further correlation via the configuration interaction in the so-called GVB-CI method.

To illustrate applications of the GVB-CI method we shall first discuss the recent theoretical studies of CO on Ni (100) of Allison and Goddard /183/ They investigated CO adsorption at a top site having one-fold coordination to one Ni metal atom (see Figure 6). A  $Ni_{14}$  cluster was used to represent Ni (100). The Ar-like core of the Ni atom was replaced by an effective potential  $\frac{184}{\text{while the}}$ nine 3d electrons were kept frozen, producing another electrostatic potential as discussed previously. The GVB calculation produced a CO dipole moment of 0.124 Debye in excellent agreement with the experimental value /185/ The best calculated geometry for Ni<sub>14</sub>CO has bond lengths  $R_{Ni-C} = 1.94$  Å,  $R_{C-O} = 1.14$  Å and an Ni-C-O bond angle of 180°, in good agreement with LEED results. Calculations for CO tilted away from the normal showed this geometry to be energetically less favorable. The dissociation energy, after correcting for the zero-point energy and temperature dependence of the enthalpy, is 1.29 eV. The binding energy obtained for the Ni<sub>4</sub>OC geometry, i.e. with the O end toward the surface, was much lower, only 0.39 eV. The optimum Ni-O bond length is then 2.03 Å. The GVB results agree well with the experimental heat of adsorption of 1.30 eV found by Tracy at low coverages./186/ Good agreement is also found for vibrational frequencies. The calculated frequencies are 49.7 meV for the Ni-CO stretch, 264.0 meV for the C-O stretch, and 40.5 meV for the Ni-CO bend. The calculated frequencies on the Ni<sub>5</sub>CO cluster are 54.2, 258.9 and 50.9 meV for these modes.

Another application of the GVB-CI method is the determination of the chemisorption geometries of oxygen and aluminum on the GaAs (110) surface by Barton et al./187/ The 28 core electrons of Ga and As are replaced by model effective core potentials./184/

The bulk GaAs zincblende structure involves tetrahedral bonding about each atom. Each Ga atom is bound to four near As atoms and vice versa. The

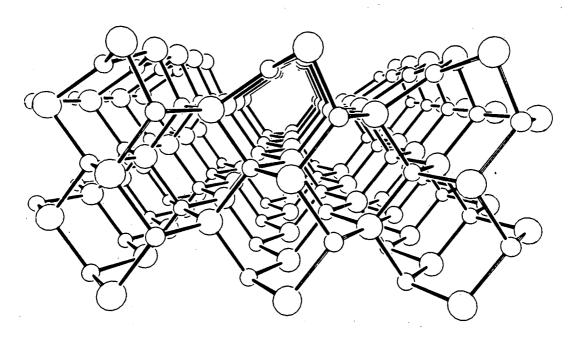


Ni (100) + c (2×2) CO

Fig. 6. The structure of carbon monoxide chemisorbed on Ni(100) in a c(2x2) periodic arrangement. The carbon atoms are bonded to single metal atoms.

unreconstructed GaAs (110) face consists of parallel zigzag chains of atoms. Each Ga is bound to two As atoms in the surface layer and one As atom in the layer below. GVB calculations by Goddard et al./188/ showed that the two dangling bonds broken at the surface, one on a Ga atom and one on an As atom, coalesce into one lone pair of electrons localized on the As center. The surface As has the character of normal trivalent As with a  $(4s)^2$  lone pair. Such an As atom bonds to the p-orbitals leading to optimum bond angles near 90°. In contrast, the surface Ga has three bonds with no electron in the fourth valence orbital. The best configuration for Ga is therefore planar, with bond angles near 120° (see Figure 7). Such bond angles around both Ga and As can be accommodated by a reconstruction involving a simple rotation of the surface zig-zag chains by about 27°. With such a reconstruction, the GVB results indeed gave an average bond angle of 119.4° at the Ga site and 94.9° at the As site, consistent with the above local bond analysis. If we define the surface strain as the projection normal to surface of the total displacement of the surface As relative to the surface Ga, the theoretical value of 0.67 Å is found to be in good agreement with the experimental value of 0.65-0.70 Å obtained by LEED./189, 190, 191, 192/

When oxygen chemisorbs on GaAs (110), the authors predicted that the O atom would be promoted to the singlet state, creating a configuration with an empty p-orbital prepared to accept an electron pair. They also showed that the energy gained by the O-As bond is larger ( $\sim 2.2 \text{eV}$  for H<sub>2</sub>AsO) than the promotion energy of the O atom from the  ${}^{3}P$  to the  ${}^{1}D$  state. Therefore, the only way oxygen can bond to the GaAs (110) surface without disrupting Ga-As bonds is for the O atoms to attach to As atoms. The computed As-O bond length is 1.63 Å (the As-O single bond length is 1.8 Å), in good agreement with the EXAFS value of 1.70±0.05 Å./193/ The calculated dipole moment and vibrational frequency for the As-O bond are 1.00 Debye and 125  $\text{cm}^{-1}$ . Experimentally,  $(H_3C)_3$ AsO has an As-O bond length of 1.63 Å<sub>1</sub>/194/ a vibrational frequency of 110 meV/195/ and a dipole moment of 1.14 Debye./196/ The chemical shifts of the Ga (3d) and As (3d) levels were also calculated for the As=O case. The authors found that Ga (3d) shifts by 0.8 eV and the As (3d) shifts by 2.6 eV, both to higher binding energy. The experimentally reported values for the core-level shifts are 0.8 eV for Ga (3d)/197/ and 2.9 eV for the As (3d)./198,199,200/



Ga As (110)

Fig. 7. Perspective view of the structure of the GaAs(110) surface which exhibits the 27 rotation of the zig-zag chains of surface atoms.

The chemisorption of Al on GaAs (110) proceeds in a different way. The Al atom is an electron donor since it is not very electronegative, with a value of 1.5 on the Pauling electronegativity scale./201/ GVB energy minimization for the Al position finds the Al 2.95 Å above a Ga site, tipped very slightly towards an adjacent As (3.90 Å). At the same time it was found that the Ga site reconstructs (the surface strain decreases from 0.67 to 0.55 Å) leading to a 40% increase in net binding energy. When an Al atom binds to a surface Ga atom, the Ga atom will prefer a more tetrahedral geometry to make more use of the electrons available for bonding to its neighbors. This increases the strength of the Al-surface bond.

### 4.7. Conclusion

The techniques of theoretical surface chemistry have advanced sufficiently to make a significant contribution to the understanding of surface structural chemistry. Even with the simplified "muffin-tin" potential,  $X\alpha$ -scattered wave calculations do a good job of predicting photoemission spectra and their variation with adsorbate geometry. Fully self-consistent *ab-initio* total-energy calculations have been able to successfully determine the structure of adsorbate bonding geometries. These calculations are still very complex, and therefore limited to small clusters. However a number of approaches to increase the efficiency of such calculations are being pursued, and over the next few years such work should make an increasing contribution to the understanding of surface structural chemistry.

### 5. RESULTS OF SURFACE CRYSTALLOGRAPHY

In this section, we present and discuss the accumulated results of surface structure determination. We give a comprehensive tabulation of published results. Only those structures which provide three-dimensional geometrical

information, including bond lengths, bond angles and layer spacings are included. They are brought together in Tables IV to XII, classified by type of surface: clean, unreconstructed metals (Table IV), alloys and reconstructed metals (Table V), chalcogens chemisorbed on metals (Table VI), other atoms adsorbed on metals (Table VII), clean semiconductors (Table VII), atoms adsorbed on semiconductors (Table IX) and insulators (Table X), carbon monoxide chemisorbed on metals (Table XI) and other molecular adsorption on metals (Table XII). It must be stressed that not all these structures can be termed final or even reliable. However, the vast majority are most likely qualitatively correct.

A variety of surface analytical techniques have contributed to these results, as detailed in the tables. Their names, acronyms and characteristics were summarized in Table I and further described in sections 2 and 3.

We first discuss some basic aspects of surface structures, including ordering principles and notations, followed by an overview of the number and types of surface structures that have been investigated. Finally we shall highlight a few major trends emerging from the structural results.

### 5.1. Ordering Principles

The vast majority of solved surface structures have long-range twodimensional ordering parallel to the surface. This means that the structures periodically repeat themselves in the two surface dimensions. There are several reasons for this. First, single crystals have been chosen in most cases as substrates, exposing a simple periodic lattice as a template. Second, a surprising number of surface structures can be easily prepared to remain periodic on the experimental time scale, whether in the clean state or after adsorption of atoms or molecules. Third, ordered structures are desirable for investigation because they provide the greatest simplicity in the interpretation of results. And fourth, structural determination itself is simplest in ordered cases.

The driving force for ordering originates, just as with three-dimensional crystal formation, in the mutual atomic interactions. With adsorbates, an important distinction must be made between adatom-adatom and adatomsubstrate interactions. In chemisorption the adatom-adatom forces are usually

113

small compared to the adatom-substrate binding forces, so the adatom locations or sites are determined by the optimum adatom-substrate bonding. But the adatom-adatom interactions still manage to dominate the long-range ordering of the overlayer. These interactions can be studied by examining the phase transitions of the overlayer as a function of temperature or coverage.

The surface coverage of an adsorbate is another important parameter in ordering. We shall use the common definition of coverage where one monolayer corresponds to one adsorbate atom or molecule for each unit cell of the clean, unreconstructed substrate surface. Thus, if an adsorbed undissociated carbon monoxide molecule bonds to alternating top-layer metal atoms exposed at the Ni(100) surface, we have a coverage of a half monolayer.

At very low coverages some adsorbates bunch together in two-dimensional islands. This results from short-range attractive adsorbate-adsorbate interactions combined with easy diffusion along the surface. Other adsorbates repel each other and form disordered overlayers with atoms or molecules adsorbed in sites of a given type (a "lattice gas"). When the coverage is increased so that the mean interadsorbate distance decreases to about 5-10 Å, the mutual interactions often strongly influence the ordering, favoring certain adsorbate configurations over others. As a result, the structure can develop a unit cell that repeats periodically across the surface. This is very evident in the LEED patterns, which depend directly on this unit cell. For example, atomic oxygen on Ni(100) orders very well at a quarter of a monolayer. The oxygen atoms then occupy one quarter of the available "hollow" sites of Ni(100) in a square array labeled (2x2). When the coverage is doubled to a half monolayer, the extra oxygen atoms occupy the empty hollow sites at the center of each of the (2x2) squares, thereby creating a new pattern labeled c(2x2) (c=centered). The corresponding LEED patterns are fundamentally different in that the (2x2) diffraction pattern has twice as many spots as the c(2x2) pattern, which in turn has twice as many spots as the clean-surface pattern, labeled (1x1).

Most nonmetallic adatoms will not compress into a one-monolayer overlayer on the closest-packed metal substrates. There appears to be a short-range repulsion that keeps adatoms apart by approximately a Van der Waals distance. Attempts to compress the overlayer further by increasing the coverage (which is done by exposing the surface to the corresponding gas) result either in no further adsorption or in diffusion of the adatoms into the substrate, forming compounds.

Some adsorbates do not form strong chemical bonds with substrate atoms. This case is called physisorption. For these adsorbates the adsorbate-adsorbate interactions can dominate the adsorbate-substrate interactions, and the optimum adatom-substrate bonding geometry can be overridden by the lateral adatomadatom interactions, yielding for example incommensurate structures, in which the overlayer and the substrate have independent lattices. When adsorbates are used which physisorb rather than chemisorb (at suitably low temperatures), one also finds that the Van der Waals distance determines the densest overlayer packing. In this case, Furthermore, with physisorption a larger coverage is possible through multilayer formation.

With metallic adsorbates very close-packed overlayers can be formed, because metal adsorbate atoms attract each other relatively strongly and coalesce with covalent interatomic distances. When the atomic sizes of the overlayer and substrate metals are nearly the same, one observes one-monolayer (1x1) structures, where adsorbate atoms occupy every unit cell of the substrate. With less equal atomic radii, other structures are formed, dominated by the covalent closest packing distance of the adsorbate. Beyond one close-packed overlayer, metal adsorbates frequently form multilayers or also three-dimensional crystallites. Alloy formation by interdiffusion is also observed in a number of cases, even in the submonolayer regime.

### 5.2. Notation for surface lattices

In Tables IV to XII the substrate surface is defined by the Miller indices of the corresponding crystallographic plane.

Unless there is reconstruction, this clean surface is labeled (1x1) to denote that the surface lattice is the same as it would be if the bulk lattice were cut along a crystallographic plane (the "terminated bulk surface"). In the case of reconstruction or with overlayers, the surface symmetry and periodicity is often different from the (1x1) lattice. Often this new periodicity is "commensurate" with the (1x1) substrate lattice, i.e. there is a simple rational relationship between the two lattices. Such a "superlattice" may be labeled by the notation

c  $(v \times w)$ R $\alpha$  or p  $(v \times w)$ R $\alpha$ 

· (47)

Here v and w are elongation factors of the (1x1) lattice vectors; they indicate that the non-centered (vxw) lattice has unit cell edges that are v and w times the lengths of the (1x1) unit cell edges. The quantity  $\alpha$  is an angle through which the (1x1) lattice must be rotated to coincide with the superlattice (the R $\alpha$  is omitted when  $\alpha=0$ ). The prefix p denotes a primitive lattice (it is often omitted), while c denotes a centered lattice. As an example, the above-mentioned (2x2) lattice can also be written p(2x2), whereas the c(2x2) lattice can be given equally by  $(\sqrt{2x}\sqrt{2})R45^{\circ}$  or p( $\sqrt{2x}\sqrt{2})R45^{\circ}$ . This so-called Wood notation assumes that the rotation angle  $\alpha$  is the same between the different lattice vectors of the (1x1) lattice and the non-centered (vxw) lattice. For instance, it assumes that the (vxw) lattice is rectangular when the (1x1) lattice is rectangular. (Some authors use the Wood notation even when the rotation angle for the two superlattice vectors is not the same. In this case the notation is not well defined. The matrix notation described below should be used for such cases.)

The more general case can be handled with a "matrix notation", which we will not need here. But there is a frequently occurring case which has its own notation. On a substrate with a six-fold rotationally symmetric (1x1) lattice (such as with fcc(111) surfaces), one often finds rectangular superlattices. These can be labeled

 $c(v\sqrt{3}xw)rect$  or  $p(v\sqrt{3}xw)rect$ 

(48)

indicating that the superlattice unit cell is rectangular and has edges of lengths  $v\sqrt{3}$  and w times the (1x1) cell edges.

#### 5.3. Numbers and types of solved surface structures

If we limit ourselves to observed LEED patterns, we find that over the years about 2000 ordered structures have been reported./202/ Among these, perhaps 180 have been structurally solved by various techniques of surface crystallography. Intensity analyses of low-energy electron diffraction have contributed about 150 of these. The remaining 30 structures were obtained primarily with ion scattering (MEIS, HEIS), SEXAFS or photoelectron diffraction (NPD, ARXPS).

A breakdown of the structural results by type of surface shows results for nearly 50 clean, unreconstructed metal surfaces and about 10 alloys and reconstructed metal surfaces. The structures of about 65 atomic overlayers on metal surfaces have been determined, some 40 of these involving chalcogen atoms. Just over 20 molecular structures have been determined for metal surfaces, half of these being overlayers of undissociated carbon monoxide and the others various hydrocarbons. Turning to semiconductors, some 13 clean, usually reconstructed structures were determined, against nearly 10 atomic overlayer structures. In addition, about 15 insulator surface structures have been investigated.

### 5.4. Major trends among surface structures

### 5.4.1. Bond length contractions and reconstructions

A general observation at surfaces is a tendency for bond lengths to decrease as the bonding coordination number decreases. This trend fits long-established principles (cf. Pauling), if one relates coordination number to bond order (cf. Mitchell). The clearest manifestation is provided bond length relaxations at clean metal surfaces. As one compares close-packed with less close-packed surfaces of metals, one finds that the latter present a smaller interlayer spacing between the topmost and the second atomic layers, compared with bulk values. The corresponding bond length contraction is of the order of 2 to 3%. Moreover, the perturbation caused by this surface relaxation propagates a few layers down into the surface. In fact, there is a compensating expansion between the second and third metal layers of the order of 1%, and a small but detectable change in the next layer. Appropriately, such relaxations are largely removed by the chemisorption of atoms on top of these surfaces.

Another manifestation of bond length contractions at surfaces compared to the bulk metal are certain reconstructions, where the topmost metal layer adopts a different structure and symmetry than the underlying layers. For instance, with Ir, Pt and Au(100), the interatomic distance in the topmost layer shrinks by a few percent parallel to the surface. It then becomes more favorable for this layer to collapse into a hexagonally close-packed layer rather than maintaining the square lattice of the underlying layers. Many adsorbates can reverse this reconstruction by removing the driving force towards smaller bond lengths.

In the case of semiconductor surfaces, a more dominant disturbance is the difficulty of surface atoms to compensate for the loss of nearest neighbors. The "dangling bonds" created at the surface cannot easily be satisfied by bonding to neighboring surface atoms, except through more drastic rearrangements of these atoms. Therefore, most semiconductor surfaces reconstruct. Major rebonding between surface atoms occurs in this process. The associated perturbation propagates several layers into the surface until the bulk lattice is recovered. Here again, adsorbates can reverse the reconstruction and induce a return to the bulk structure.

### 5.4.2. Atomic penetration into substrates

Of major interest for such processes as oxidation and compound formation are results that show several stages of atomic penetration into the substrate lattice. At metal surfaces, this appears to occur mostly with small atoms: oxygen, nitrogen, carbon, as well as hydrogen. In some instances, as the coverage is increased, first an overlayer is formed (e.g. O on Ni(100)). Usually, the adatom occupies high-coordination sites such as "hollow" sites. On less close-packed surfaces, this site puts the adatom nearly coplanar with the surface metal atoms (e.g. O on Fe(100)). This may be viewed as a single layer of the metal-adatom compound. The next stage of penetration is illustrated by N on Ti(0001), where the adatom occupies interstitial sites between the first and second metal layers, thereby forming a three-layer film of the bulk compound TiN. Deeper penetration is often observed in the form of thicker compound films which show no trace of the structural properties of the parent metal.

In the case of semiconductors, there is more interstitial space available for diffusion of adatoms into the surface. The very few cases whose structure is known show, however, that a substitutional arrangement may be the more stable equilibrium configuration. Thus, with Al on GaAs(110), Al atoms tend to occupy the original Ga and As positions.

### 5.4.3. Molecular adsorption

In the case of molecules adsorbed at surfaces, it must be first stated that much important information is obtained from high-resolution electron energy loss spectroscopy (HREELS). This technique measures vibration frequencies of surfaces, in a way similar to infra-red absorption spectroscopy in the gas phase. HREELS allows the identification of the molecular species present on the surface, which no surface crystallography method can do.

Carbon monoxide has proved a popular and convenient molecular adsorbate. It provides a rich variety of behavior at surfaces, while being relatively easy to study by various methods. Toward the left of the periodic table, metal surfaces increasingly tend to dissociate CO, then separate C and O atoms bond directly in individual hollow sites, as in atomic adsorption. On other metal substrates, CO remains intact and bonds through its carbon end to the surface, with the C-O axis perpendicular to the surface. However, the adsorption site varies considerably. CO most commonly adsorbs in one-fold coordinated top sites or two-fold coordinated bridge sites. Occasionally, three-fold coordinated hollow sites are also found. The site depends on several factors: the metal, the crystallographic face and the CO coverage. Another factor has recently been found to influence the CO adsorption site -- coadsorbed atomic or molecular species which donate charge to the CO can shift CO to a higher-coordination site. An example is the coadsorption of benzene, whose  $\pi$ -orbitals give up charge to the metal and to nearby CO species. On Rh(111) this shifts CO adsorption to three-fold sites.

There is a close similarity between the bonding geometry of CO on metal surfaces and in metal-carbonyl complexes. In both cases, for example, the metalcarbon bond length increases markedly with the coordination number of the site where the CO molecule bonds to the metal. The C-O bond length tends to increase slightly at the same time, indicating a C-O bond weakening, which is amplified by nearby electron donors.

If we consider hydrocarbons at surfaces, we must set the saturated ones aside. These do not chemisorb at metal surfaces, but rather physisorb at low temperatures. No detailed structural determination has been performed for saturated hydrocarbons on metals. However, some structures have been obtained using the graphite basal plane as a substrate (cf. Suzanne etc) which give information about Van der Waals packing of such molecules, but no chemical reactions are involved.

With unsaturated hydrocarbons, whether straight-chain or aromatic, two basic types of surface structure can be distinguished. The first consists of the intact molecule bonding to the metal surface by sharing its C-C multiple bonds with the metal. Thus, acetylene and ethylene adsorb with their C-C bonds parallel to the metal surface. The C-C bond is believed to be considerably lengthened, indicating bond-order reduction in favor of the newly formed metalcarbon bonds. The associated rehybridization around the carbon atoms may also result in the hydrogen atoms bending away from the metal. Similarly, benzene bonds with its carbon ring parallel to the surface, and large expansions of the C-C distances have been observed. Such distortions may be a forerunner of molecular dissociation.

The second type of structure for unsaturated hydrocarbons is the result of a hydrogen rearrangement in straight-chain molecules. Alkylidynes are formed, in which a terminal carbon bonds to three metal atoms, while the rest of the chain is saturated and points away from the metal (extra hydrogen atoms may be necessary for these species to form). These alkylidynes, foremost among which is ethylidyne ( $C_2H_3$ ), are quite stable in comparison to other organic species formed at room temperature transition metal substrates. However, at higher

temperatures, a progressive dehydrogenation occurs, leaving CH and CCH fragments, then carbonaceous fragments and ultimately graphite and bulk carbides on the surface.

Both types of hydrocarbon adsorption are also encountered in organometallic complexes. Here again, the geometries found at surfaces often correspond closely to those observed in complexes, including agreement of bond lengths and bond angles. There probably are larger differences between surfaces and complexes in the relative occurrence of the various species.

Substrate Face	Bulk Spacing(Å)	Surface Spacing(Å)	Expansion(%)	Method
Ag (110) fee	1.44	1.34	-7	LEED/1/
Ag (110) fcc		1.33±0.04	-7.6	HEIS/2/
		$1.50 \pm 0.04$	4.2	
Ag (111) fcc	2.35	$2.35 \pm 0.1$	0	HEIS/3/
Al (100) fee	2.02	$2.025 \pm 0.10$	0.0	LEED/4/
Al (100) fcc		2.02	0.0	LEED/5/
<b>A</b> l (100) fcc		2.052	1.0	MEED/6/
Al (110) fee	1.43	1.30	-9.1	LEED/5/
Al (110) fcc		$1.304 \pm 0.012$	-8.8	LEED/7/
•		$1.499 \pm 0.15$	4.8	
• *		$1.404 \pm 0.017$	-1.8	1
		$1.429\pm0.018$	0.0	
Al (110) fcc	•	$1.310\pm0.014$	-8.4	LEED/8/
· . •		$1.510\pm0.016$	5.6	•
		$1.463 \pm 0.019$	2.3	
<b>x</b>		$1.455{\pm}0.022$	1.7	
Al (111) fcc	2.33	$2.350{\pm}0.012$	0.9	LEED/9/
Al (111) fcc		$2.41 \pm 0.05$	3.1	LEED/10/
Al (311) fcc	1.23	1.68 <u>+</u> 0.01	-13.0	LEED/11/
	•	$1.335 \pm 0.02$	8.8	
Al (331) fcc	0.93	$0.82 \pm 0.02$	-11.7	LEED/12/
		$0.89 \pm 0.03$	-4.1	
		$1.05 \pm 0.03$	10.3	
;		$0.88 \pm 0.03$	-4.8	-

TABLE IV. Clean Metal Structures (unreconstructed)

(Where multiple layer spacing changes have been investigated these are listed in the table on successive lines.)

## TABLE IV (continued)

Substrate Face	Bulk Spacing(Å)			Method	
Au (100) fcc (metastable)	2.04	2.04	0.0	LEED/13/	
Cd (100) fcc	2.81	2.81	0	LEED/14/	
Co (100) fcc	1.77	1.70	-4.0	LEED/15/	
Co (111) fcc	2.05	$2.05 \pm 0.05$	0.0	LEED/16/	
Co (0001) hcp	2.05	$2.05 \pm 0.05$	0.0	LEED/16/	
$Co(11\overline{2}0)$ hcp	1.25	$1.14 \pm 0.04$	-8.8	LEED/17/	
Cu (100) fcc	1.81	1.785	-1.1	LEED/18/	
		1.836	1.7		
		1.832	1.5		
Cu (110) fcc	1.28	1.159	-9.2	LEED/18/	
		1.305	2.3		
Cu (110) fcc		$1.21 \pm 0.02$	-5.3	MEIS/19/	
		$1.32 \pm 0.02$	3.3		
Cu (110) fcc		$1.170 \pm 0.008$	-8.5	LEED/20/	
· · · · · · · · · · · · · · · · · · ·		$1.307 \pm 0.010$	2.3		
Cu (111) fcc	2.09	$2.076{\pm}0.02$	-0.7	LEED/21/	
Cu (311) fcc	1.09	$1.035 \pm 0.02$	-5.0	LEED/22/	
Fe (100) bcc	1.43	1.41±0.04	-1.6	LEED/23/	
Fe (110) bcc	2.02	$2.04 \pm 0.04$	0.5	LEED/24/	
Fe (111) bcc	0.83	$0.70 \pm 0.03$	-15.4	LEED/25/	
Fe (111) bcc		$0.69 \pm 0.025$	-16.6	LEED/26/	
		$0.75 \pm 0.025$	-9.3	۰.	
		$0.86 \pm 0.03$	4.0		
		$0.81 \pm 0.025$	-2.1		
$\mathrm{Fe}~(210)^*~\mathrm{bcc}$	0.64	$0.50 \pm 0.03$	-21.9	LEED/27/	
		$0.57 \pm 0.03$	-10.9		

# TABLE IV (continued)

Substrate Face	Bulk Spacing(Å)	Surface Spacing(Å)	Expansion( $\%$ )	Method
		0.61±0.03	-4.7	
		0.64±0.03	0.0	
Fe $(211)^*$ bcc	1.17	$1.05 \pm 0.03$	-10.3	LEED/28/
		$1.23 \pm 0.03$	5.1	•
		$1.15 \pm 0.04$	-1.7	
Fe (310) bcc	0.906	$0.76 \pm 0.03$	-16.1	LEED/29/
		$1.02 \pm 0.03$	12.6	,
		$0.87 \pm 0.04$	-4.0	
r (100) fcc (metastable)	1.92	$1.85 \pm 0.01$	-3.6	LEED/30/
r (110) fcc	1.36	$1.26 \pm 0.10$	-7.4	LEED/31/
r (111) fcc	2.22	$2.16 \pm 0.10$	-2.6	LEED/32/
Na (110) bcc	3.03	3.03	0.0	LEED/33/
Na (110) bcc		<b>3.0±0.01</b>	-1.0	LEED/34/
Na (0001) hcp	2.87	2.87	0.0	LEED/35/
Ni (100) fcc	2.22	$1.78 \pm 0.02$	1.1	LEED/36/
Ni (100) fcc	· ·	$1.604 \pm 0.008$	-8.9	MEIS/37/
Ni (110) fcc	1.25	$1.195 \pm 0.01$	-4.0	MEIS/38/
Ni (110) fcc	· .	$1.18 \pm 0.02$	-4.8	HEIS/39/
		$1.27 \pm 0.02$	2.4	· ·
Ni (110) fcc		$1.14 \pm 0.01$	-8.1	LEED/40/
		$1.28 \pm 0.01$		
Ni (110) fcc		$1.123 \pm 0.02$	-9.8	LEED/41/
		$1.292 \pm 0.02$	3.8	
Ni (110) fcc		$1.138 \pm 0.006$	-8.6	LEED/42/
		$1.284 \pm 0.007$	3.1	
		$1.240 \pm 0.009$	-0.4	

TABLE IV	(continued)	
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Substrate Face	Bulk Spacing(Å)	Surface Spacing(Å)	Expansion(%)	Method
Ni (110) fcc		$1.121 \pm 0.012$	-9.0	MEIS/43/
<b>、</b> ,		$1.290 \pm 0.019$	3.5	· ·
Ni (111) fee	2.03	$2.005 \pm 0.025$	-1.2	LEED/36/
Ni (111) fcc		$2.033 \pm 0.020$	0.0	HEIS/44/
Ni (311) fcc	1.06	0.894±0.010	-15.9	LEED/45/
		$1.106 \pm 0.016$	4.1	
	2 · · · · · ·	1.045±0.017	-1.6	·
Mo (100) bcc	1.25	$1.424 \pm 0.03$	-9.5	LEED/46/
Mo (110) bcc	2.22	$2.19 \pm 0.04$	-1.6	LEED/47/
Pd (100) fcc	1.94	1.95±0.05	0.3	LEED/48/
Pd (110) fcc	1.37	$1.29 \pm 0.03$	-5.8	LEED/49/
		$1.38\pm0.03$	0.7	
Pd (111) fcc	2.246	$2.25\pm0.05$	0.0	HEIS/50/
Pd (111) fcc		2.276	1.3	LEED/51/
	· ·	2.216	-1.3	
		2.296	2.2	
		2.296	2.2	
Pt (100) fcc	1.96	1.96	0.2	SPLEED/52/
(metastable)				
Pt (100) fcc		1.963	0.2	HEIS/53/
(metastable)			· ·	
Pt (100) fcc		1.96	0.0	LEED/13/
(metastable)				
Pt (111) fcc	2.26	$2.29 \pm 0.10$	1.1	LEED/54/
Pt (111) fcc		$2.30\pm0.02$	1.4	HEIS/55/
Pt (111) fcc		$2.276 \pm 0.02$	0.5	SPLEED/56/
Pt (111) fcc		$2.265 \pm 0.05$	0.0	LEED/57/

TABLE IV	(continued)	
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	· · · · · · · · · · · · · · · · · · ·	· — ···		
Substrate	Bulk	Surface	Expansion(%)	) Method
Face	Spacing(Å)	$\operatorname{Spacing}(\operatorname{\AA})$		
Re (1010) hcp		0.67	-16.3	LEED/58/
Rh (100) fcc	1.90	$1.91 \pm 0.02$	0.5	LEED/59/
Rh (110) fee	1.34	$1.33 \pm 0.02$	-0.7	LEED/59/
Rh (111) fee	2.19	$2.16 \pm 0.02$	-1.4	LEED/59/
Rh (111) fcc		$2.192 \pm 0.10$	0.0	LEED/60/
Ru (0001) hcp	2.14	$2.10 \pm 0.02$	-1.9	LEED/61/
Sc (0001) hcp	2.64	$2.59{\pm}0.02$	-1.9	LEED/62/
Ta (100) bcc	1.65	$1.47 \pm 0.03$	-10.9	LEED/63/
		$1.67 \pm 0.03$	1.2	
Te (1010) hcp		$0.34 \pm 0.10$		LEED/64/
Ti (0001) hcp	2.34	$2.29 \pm 0.05$	-2.1	LEED/65/
V (100) bcc	1.51	$1.41 \pm 0.01$	-6.6	LEED/66/
V (110) bcc	2.14	<b>2.13±0.10</b>	-0.5	LEED/67,68
W (100) fcc	1.58	$1.46 \pm 0.03$	-7.6	LEED/69/
W (110) fcc	2.23	$2.23 \pm 0.10$	0.0	LEED/70/
Zn(0001) hcp	2.44	$2.39 \pm 0.05$	-2.0	LEED/71/
Zr (0001) hcp	2.57	$2.54 \pm 0.05$	-1.2	LEED/72/
* <b>7</b> 1	· · · · · ·			(011) $1(010)$

\* There are relaxations in the layer registries for the stepped iron (211) and (210) surfaces in addition to layer spacing relaxations.

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### TABLE V. Alloys and Reconstructed Metals

Substrate and Unit	Cell Structure	Method
Au (110) (fcc)	Missing-row reconstruction confirmed by x	- X-Ray
(2x1)	ray diffraction. Lateral displacement of	Diffraction/1/
	second layer rows toward missing row posi	<b>j</b> -
	tion by $0.12\pm0.02$ Å. Anti-phase domains	
	due to monatiomic steps obeserved. Evi-	
	dence for top-layer expansion or contraction	on
	of $\sim 0.25$ Å.	
Au (110) (fcc)	Missing-row reconstruction. Every other to	op LEED $/2/$
(2x1)	layer $(1\overline{1}0)$ row is missing. The second lay	er
	lateral displacements are $\sim 0.07$ Å, and th	e
	second row is buckled by -0.24 Å. The firs	t
	layer spacing is -20.1%, and the second an	d
	third is -6.3% relative to the 1.44 Å bulk	
	layer spacing.	
Au (110) (fcc)	Missing-row reconstruction studied by cha	n- MEIS/3/
(2x1)	neling and blocking, top layer spacing con-	
	tracted by 18%, second layer spacing ex-	:
	panded by 4% from bulk value of 1.44 Å.	
	Third layer buckled by $\pm 0.10$ Å or $\pm 7\%$ ,	
	with atoms under missing row moving up,	
	alternate rows down.	• •
Au (110) (fcc)	Missing-row reconstruction studied with to	
(2x1)	layer spacing contracted by $0.15\pm0.10$ Å (-	
	11%) from bulk value of 1.44 Å.	

(continued)

131

## TABLE V (continued)

Substrate and Un	it Cell Structure	Method
α-CuAl (111) (fcc)	Al substituted in 1/3 of top layer Cu sites, second layer pure Cu, no buckling in top	LEED/5/
$(\sqrt{3}x\sqrt{3})R30^{\circ}$	layer, layer spacing is $2.05\pm0.05$ Å, the same	
· · ·	as bulk copper. Alloy composition 16% Al atoms in Cu.	
Ir (100) (fcc)	The top layer of the surface reconstructs to	LEED/6/
(5x1)	form a compact hexagonal surface, with $6/5$	
	the density of unreconstructed surface. The	· ·
	layer spacing expands by $14.6{\pm}5.2\%$ from	
	the bulk value of 1.92 Å. Some top-layer	
	atoms are buckled outward by up to an ad-	
	ditional $0.2{\pm}0.02$ Å so the hexagonal layer	
	can fit the square layer below. This is $1/2$ to	
	2/3 of the buckling required to have top	
	layer atoms in hard-sphere contact with all substrate atoms.	
Ir (100) (fcc)	The top layer of the surface reconstructs to	LEED/7/
(5x1)	form a compact hexagonal surface, with $6/5$	
	the density of unreconstructed surface. The	
	layer spacing expands by $7.3{\pm}2.6\%$ from the	
	bulk value of 1.92 Å. Some top-layer atoms	
	are buckled outward by up to an additional	
	$0.48{\pm}0.02$ Å so the hexagonal layer can fit	
	the square layer below. This puts the top	
	layer atoms in hard-sphere contact with all	
	substrate atoms.	

## TABLE V (continued)

Substrate and U	nit Cell Structure	Method
Ir (110) (fcc)	Missing-row reconstruction similar to gold	LEED/8/-
(2x1)	(110). One top layer row is missing, the	
	second layer lateral displacements are $\sim$ .	
	0.04 Å, and the second row is buckled by	
	-0.23 Å. The first layer spacing is -12.4%,	1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 - 1997 -
	and the second and third -5.8% relative to	
	the 1.36 Å bulk layer spacing.	
NiAl (110)	Top layer spacing 1.92 Å, contracted $6\%$	LEED/9/
(CsCl) (1x1)	from bulk value of 2.04 Å. Al atoms buckled out by 0.22 Å.	
Ni <sub>3</sub> Al (Cu <sub>3</sub>	Top layer is 50-50 nickel and aluminum,	LEED/10/
Au) (100)	second layer nickel, etc. Top layer spacing is	
	$1.73\pm0.03$ Å with Al atoms buckled outward	
	by $0.02\pm0.03$ Å, second layer spacing is the	
	bulk value of $1.78$ Å within $\pm 0.03$ Å.	
Pd (110) (fcc)	Missing-row model with third layer assumed	LEED/11/
(2x1)	bulk-like. Second layer found to by bulk-	
	like, fist layer spacing -%.1% relative to 1.37	•
	Å bulk spacing. Saw-tooth model almost as	
t	good.	· . · · ·
Pt (100) (fcc)	Top layer reconstruction, quasi-hexagonal	LEED/6/
	surface given by $\begin{pmatrix} 141\\ -15 \end{pmatrix}$ , also called "1x5" or	
	"4x20" reconstruction. Degree of top-layer	
	buckling and top-laer registry proposed.	

## TABLE V (continued)

Substrate and U	Method	
Pt (110) (fcc)	Missing-row model with the top layer ex-	LEED/12/
(2x1)	panded by $23\%$ to $1.\mathrm{\AA}$ Å from bulk value of	
	1.387 Å. Lateral shift of second layer rows	т.,
	of 0.05 Å.	
Pt (110) (fcc)	Missing-row model is better than buckled-	LEIS/13/
(2x1)	row, paired-row or saw-tooth models.	
·	Terminated-bulk positions assumed for	. *
·:	remaining atoms.	
$\operatorname{Pt}_{x}\operatorname{Ni}_{1-x}(110)$	LEED study of random substitutional alloy	LEED/14/
(fcc)	shows Pt enhancement in $1^{st}$ and $3^{rd}$ layers,	
	along with a Pt depletion in the $2^{ed}$ layer.	
W (100) (bcc)	Below room temperature the "zig-zag"	LEED/15/
(2x1)	reconstruction occurs on the $W(100)$ surface.	
	Alternate atoms move along the (011) and	· ·
• • •	$(0\overline{11})$ directions by $\pm 0.22 \pm 0.07$ Å, while the	
	top layer spacing contracts by $0.05{\pm}0.05$ Å	
	from the bulk value of 1.58 Å. There are	•
	two domains, since atoms may also move	
•.	along the $(0\overline{1}1)$ and $(01\overline{1})$ directions.	
W (100) (bcc)	Below room temperature the "zig-zag"	LEED/16/
$(\sqrt{2}x\sqrt{2})$ R45 °	reconstruction occurs on the W(100) surface.	
	Alternate atoms move along the (011) and	
· · ·	$(0\overline{11})$ directions by ±0.16 Å, while the top	
	layer spacing contracts by 0.09 Å (6%) from	
	the bulk value of 1.58 Å.	

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TABLE VI. Chalcogen Chemisorption on Metals

(Where relaxation of the metal layer spacing has been investigated this is listed in the table after the adsorbate information.)

Face	Overlayer Unit Cell	Adsorption Site	Adsorbate Spacing	Bond Length	Method
<u></u>	· ·				
		ΟΧΎ	GEN		
Ag (110)	(2x1)	long bridge	0.20	2.05	SEXAFS/1/
Al (111)	(1x1)	3-fold fcc	$0.70{\pm}0.12$	1.79±0.05	LEED/2/
Al (111)	(1x1)	3-fold fcc	0.60±0.10	1.75±0.03	NEXAFS/3/
Al (111)	(1x1)	sub-surface	0.60±0.10	$1.75 \pm 0.03$	NEXAFS/3/
·		tetrahedral			
Al (111)	(1x1)	3-fold fcc	0.70	1.79	LEED/4/
Al (111) u	undetermined	3-fold fcc	0.98±0.10	1.92±0.05	EXAFS/5/
Co (100)	c(2x2)	4-fold	0.80	1.94	LEED/6/
Cu (100)	c(2x2)	4-fold	1.40	2.28	LEED/7/
Cu (100)	c(2x2)	4-fold	$0.70 \pm 0.01$	1.94±0.01	SEXAFS/8/
Cu (100)	c(2x2)	4-fold	0.80	1.97	NPD/9/
Cu (110)	(2x1)				ALICISS/10/
	COI	nfirm surface n	nissing-row r	nodel	
Cu (100)	c(2x2)			1.97	ALICISS/11/
Bull	k layer spacing	1.28 Å. First	layer spacing	g expanded	25±1.0%,
seco	nd and third la	ayers contracte	ed by 10±5.		
Cu (110)	disordered	long bridge	0.35		SEXAFS/12/
Cu (110)	(2x1)	long bridge		•	HEIS/13/
top la	yer buckled, [0	01] rows altern	nate $+0.27\pm0$	0.05 Å and •	0.02±0.03 Å
		ayer spacing ex		-	
Cu (410)	(1x1)	quasi 4-fold	$0.4{\pm}0.2$		ARXPD/14/
		at step edge			•

## TABLE VI (continued)

Substrate Face	Overlayer Unit Cell	Adsorption Site	Adsorbate Spacing	Bond Length	Method
Cu (410)	(1x1)	quasi 4-fold	0.4±0.2	1.85±0.04	ARXPD/14/
•		at step edge		N)	
		and 4-fold	4 A.		
Fe (100)	(1x1)	4-fold	0.48±0.10		LEED/15/
		top layer	$1.54 \pm 0.10$	+7.7%	
Ir (110)	c(2x2)	short bridge	$1.37 \pm 0.05$	$1.93 \pm 0.04$	LEED/16/
3		top layer	$1.33 \pm 0.07$	-2.2%	· · ·
Ir (111)	(2x2) or $(2x1)$	3-fold fcc	$1.30\pm0.05$	2.04±0.03	LEED/17/
Ni (100)	(2x2)	4-fold	$0.86 \pm 0.07$	1.96±0.03	EXAFS/18/
Ni (100)	c(2x2)	4-fold	$0.86 \pm 0.07$	$1.96 \pm 0.03$	EXAFS/18/
Ni (100)	(2x2)	4-fold	0.90±0.10	1.98±0.05	LEED/19/
Ni (100)	c(2x2)	4-fold	0.92±0.05	$1.99\pm0.02$	LEED/20/
Ni (100)	c(2x2)	4-fold	$0.85 \pm 0.05$	1.96±0.02	EXAFS/21/
Ni (100)	c(2x2)	4-fold	0.90±0.04	$1.98 \pm 0.02$	NPD/22/
Ni (100)	c(2x2)	4-fold	0.85±0.04	$1.96 \pm 0.02$	NPD/23/
Ni (100)	c(2x2)	4-fold	0.86±0.10	1.96±0.04	HEIS/24/
	•	top layer	$1.85\pm0.10$	+5.1%	
Ni (100)	c(2x2)	4-fold	0.90±0.10	$1.98 \pm 0.05$	XANES/25/
Ni (100)	c(2x2)	4-fold	0.90	1.98	HREELS/26,27/
Ni (100)	c(2x2)	4-fold	0.922	•	HREELS/28/
Ni (110)	(2x1)	missing row,	0.25	•	ALICISS/29/
• 4		long bridge			
Ni (111)	$(\sqrt{3} \times \sqrt{3})$ R30°	3-fold hcp	1.20		
• •	(3x1)				
. ,	. ,	tetrahedral			. ,
		top layer	1.55±0.05	-6.1%	
W (100)	disordered				LEED/32/

TABLE VI (continued)

Substrate Face	Overlayer Unit Cell	Adsorption Site	Adsorbate Spacing	Bond Length	Method
W (110)	(2x1)	3-fold	1.25±0.01	2.09±0.01	LEED/33/
Zr (0001)	(2x2)	sub-surface	1.37	2.31	LEED/34/
		octahedral			
		SUL	FUR		
Co (100)	c(2x2)	4-fold	1.30	2.20	LEED/35/
Cu (100)	(2x2)	4-fold	1.39	2.28	ARXPS/36/
Fe (100)	c(2x2)	4-fold	1.09±0.05	2.30±0.02	LEED/37/
Fe (110)	(2x2)	4-fold	1.43	2.02	LEED/38/
		reconstructed			
Ir (111)	$(\sqrt{3}x\sqrt{3})R30^{\circ}$	3-fold fee	$1.65 \pm 0.07$	2.28±0.05	LEED/39/
Ni (100)	(2x2)	4-fold	1.30±0.10	2.19±0.06	LEED/19/
Ni (100)	c(2x2)	4-fold	$1.28 \pm 0.05$	2.18±0.03	LEED/20/
Ni (100)	c(2x2)	4-fold	$1.30 \pm 0.05$	2.19±0.03	LEED/40/
Ni (100)	_ c(2x2)	4-fold	$1.30 \pm 0.04$	2.19±0.02	NPD/22/
Ni (100)	c(2x2)	4-fold	1.39±0.04	$2.24\pm0.02$	SEXAFS/41/
Ni (100)	c(2x2)	4-fold	$1.37 \pm 0.05$	2.23±0.03	ARPEFS/42/
Ni (100)	c(2x2)	4-fold	1.35±0.10	2.22±0.06	ARXPS/43/
Ni (100)	c(2x2)	4-fold	1.35	2.22	ARXPS/36/
Ni (100)	disordered	4-fold	$1.36 \pm 0.03$	$2.22\pm0.02$	SEXAFS/44/
Ni (110)	c(2x2)	4-fold	0.9	2.34	ARXPS/45/
Ni (110)	c(2x2)	4-fold			LEED/46/
		top layer	1.372±0.02	+9.6%	
• .		next layer	$1.201\pm0.02$	-4.0%	
Ni (110)	c(2x2)	4-fold	0.87±0.03	$2.32\pm0.01$	MEIS/47/
			$1.31 \pm 0.04$		

## TABLE VI (continued)

Substrate	Overlayer	-	Adsorbate		Method
Face	Unit Cell	Site	Spacing	Length	•
Mo (100)	c(2x2)	4-fold	1.04		LEED/48/
		top layer	1.42	-10%	
Pd (100)	c(2x2)	4-fold	$1.30\pm0.05$	$2.33\pm0.03$	LEED/49/
Pd (111) <sup>.</sup> (	√3x√3)R30°	3-fold fcc	$1.53 \pm 0.05$	$2.20\pm0.03$	LEED/50/
Pt (111) (	$\sqrt{3}$ x $\sqrt{3}$ )R30°	3-fold fcc	$1.62\pm0.05$	$2.28\pm0.04$	LEED/51/
Rh (100)	(2x2)	4-fold	1.29	2.30	LEED/52/
Rh (110)	c(2x2)	4-fold	0.77	2.45	LEED/53/
Rh (111) (	√3x√3)R30°	3-fold fcc	1.53	2.18	LEED/54/
	· · · · ·	SELE			
		SELE			
Ag (100)	c(2x2)	4-fold	1.91±0.04	$2.80 \pm 0.03$	LEED/55/
Ni (100)	(2x2)	4-fold			LEED/19/
Ni (100)	c(2x2)	4-fold	1.45±0.10		
Ni (100)	c(2x2)	4-fold	1.55	2.35	
Ni (110)	c(2x2)	4-fold	1.10±0.04	$2.42 \pm 0.02$	NPD/58/
Ni (111)	(2x2)	3-fold fcc	1.80±0.04	$2.30\pm0.03$	NPD/58/
	· .				
		TELL	URIUM		
Cu (100)	(2x2)	4-fold	1.70±0.15	2.48±0.10	LEED/59/
Cu (100)	(2x2)	4-fold	1.90±0.04	$2.62 \pm 0.03$	SEXAFS/60/
Ni (100)	(2x2)	4-fold	1.80±0.10	$2.52 \pm 0.07$	LEED/19/
Ni (100)	c(2x2)	4-fold	1.90±0.10	2.59±0.07	LEED/61/
Ni (100)	c(2x2)	4-fold	1.9		XPD/62/
Ni (100)	c(2x2)	4-fold	1.9	• •	SPLEED/63/

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### TABLE VII. Other Atomic Adsorbates on Metal Surfaces

(Where relaxation of the metal layer spacing has been investigated this is listed in the table after the adsorbate information.)

Adsorption	Overlayer	Adsorption	Adsorbate	Method
system	Unit Cell Site		Spacing	· .
Ag (100)-Cl	c(2x2)	4-fold	1.62	LEED/1/
Ag (111)-Au	(1x1)	3-fold fcc	$2.35 \pm 0.10$	HEIS/2/
Ag (111)-I	(√3x√3)R30 °	3-fold fcc and hcp	$2.29\pm0.06$	LEED/3/
	top layer	0.0%	$2.36\pm0.06$	
Ag (111)-I	(√3x√3)R30 °	3-fold	$2.34\pm0.02$	SEXAFS/4/
Ag (111)-Xe	hexagonal (1x1)	incommensurate	3.55±0.10	LEED/5/
rande	omly oriented hexag	gonal Xe lattice, Xe	-Xe spacing 1.	51 Å
Al (100)-Na	c(2x2)	4-fold	$2.08\pm0.12$	LEED/6/
Al (100)-Na	c(2x2)	4-fold	$2.05 \pm 0.10$	LEED/7/
Au (111)-Ag	(1x1)	3-fold fcc	$2.35\pm0.10$	HEIS/2/
Cu (100)-Cl	c(2x2)	4-fold	$1.60 \pm 0.03$	LEED/8/
	top layer	+3%	$1.85 \pm 0.03$	
Cu (111)-Cs	(2x2)	top	$3.01\pm0.05$	LEED/9/
Cu (100)-I	(2x2)	4-fold	$1.98 \pm 0.02$	SEXAFS/10/
Cu (111)-I	(√3x√3)R30 °	3-fold hcp	$2.21\pm0.02$	SEXAFS/10/
Cu (111)-Ni	(1x1)	3-fold fcc	$2.04 \pm 0.02$	LEED/11/
Cu (100)-Pb	c(2x2).	4-fold	$2.05 \pm 0.05$	LEED/12/
Cu (100)-3Pb	$c(5\sqrt{2}x\sqrt{2})R45^{\circ}$	4-fold	$2.4 \pm 0.05$	LEED/12/
overlaye	er relaxed with anti-	-phase domain wall	s and off-cente	er atoms
Fe (100)-C+O	c(2x2)	4-fold	0.48	LEED/13/
CO decom	poses on Fe(100), C	and O occupy rane	dom sites in (2	2x2) lattice
Fe (110)-H	(2x1)	quasi 3-fold	0.90±0.10	LEED/14/
Fe (110)-2H	(3x1)	quasi 3-fold	1.00±0.10	LEED/14/
Fe (100)-N	c(2x2)	4-fold	$0.25 \pm 0.05$	LEED/15/
	top layer	+8%	1.54±0.05	

Adsorption system	Overlayer Unit Cell	Adsorption Site	Adsorbate Spacing	Method
lr (110)-S	(2x2)			LEED/16/
Sulfur	is adsorbed in 3-	fold sites on the (11)	I) facets left b	y the
clean-sur	face missing-row	reconstruction. Th	e first Ir-Ir sp	acing is
contract	ed by 3.3%, the	second expanded by	1.3%. Ir-S is	2.39 Å
for fir	st-layer Ir atoms	and 2.26 Å for seco	nd-layer Ir ato	oms.
Mo (100)-N	c(2x2)	4-fold	1.02	LEED/17/
Mo (100)-Si	<u>(</u> 1x1)	4-fold	$1.16 \pm 0.10$	LEED/18/
Ni (100)-Br	c(2x2)	4-fold	$1.51\pm0.03$	EXAFS/19/
Ni (100)-C+O	c(2x2)	4-fold	0.93±0.10	LEED/20/
CO decomp	oses on Ni(100),	C and O occupy ran	dom sites in (?	2x2) lattice
Ni (100)-2C	(2x2)	4-fold	0.10±0.10	LEED/21/
	top layer	+22%	$1.96\pm0.05$	
	reconstructed	lateral motions -	$0.25\pm0.35$ Å	
Ni (100)-Cu	(1x1)	4-fold	$1.80{\pm}0.03$	LEED/22/
Ni (100)-Na	c(2x2)	4-fold	$2.2\pm0.10$	LEED/23/
Ni (100)-Na	c(2x2)	4-fold	$2.23\pm0.10$	LEED/24/
Ni (100)-Na	c(2x2)	4-fold	1.9	XPD/25/
Ni (110)-C				SEELFS/26
Graphitic	layer on Ni(110)	, 3 carbon sites: A -	off top, Ni-C	= 1.95 Å
B - 4-fold,	Ni-C = 2.49  Å, 0	C - off bridge, Ni-C =	= 1.95, Ca-Cb	= 1.49 Å
Ni (111)-2C	(1x1)	3-fold hep and fee	$2.80\pm0.08$	SEELFS/27
Ni (111)-2H	(2x2)	3-fold hcp and fcc	1.15±0.10	LEED/28/
Pd (111)-Au	(1x1)	3-fold fcc	$2.25 \pm 0.19$	HEIS/29/
Ti (0001)-Cd	(1x1)	3-fold fcc	2.57	LEED/30/
Ti (0001)-Cd	(1x1)	3-fold fcc	2.63	LEED/31/
Т	wo Cd layers, Co	l-Cd distance 2.81 Å	, Cd-Ti 2.63 A	A Contraction of the second se

TABLE VII	(continued)	).
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Adsorption system	Overlayer Unit Cell	Adsorption Site	Adsorbate Spacing	Method	
Ti (0001)-N	(1x1)	sub-surface tetrahedral	-1.22±0.05	LEED/32/	
W (100)-H	c(2x2)	4-fold	1.32	LEED/33/	
W (100)-2H	(1x1)	short bridge		HREELS/34/	
W (100)-2H	(1x1)	short bridge	1.74	HREELS/35/	
W (100)-2H	(1x1)	2-fold	$1.17 \pm 0.04$	LEED/36/	
	top layer	-1.3%	$1.56\pm0.02$	•	
W (100)-N	c(2x2)	4-fold	0.49±0.06	LEED/37/	
•	top layer	+1.3%	1.60±0.06		

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149

TABLE VIII. Semiconductor Surface Structures

Substrate	Unit Cell	Structure Method
AlP (110)	(1x1)	Surface reconstructed with 25 ° bond an- LEED/1/
(zincblende)		gle rotation preserving bond lengths.
	· ,	Top layer buckled with P +0.06 Å, Al
		-0.57Å and layer spacing contracted to
	• . •	1.33 Å (bulk 1.927 Å). Second layer
		buckled P -0.035 Å, Al +0.035 Å, layer
	• • • •	expanded to 1.92 Å. First layer in-plane
		displacements of $\sim 0.25$ Å to preserve
	<i>"</i>	bond lengths.
CdTe (110)	(1x1)	Te is buckled out from the top layer by $LEED/2/$
(zincblende)		0.82±0.05 Å. Top layer Cd atoms con-
		tract by $\sim 0.5$ Å, and there are lateral
		motions of $\sim 0.4$ Å to conserve bond
•		lengths.
GaAs (110)	(1x1)	As is buckled out from the top layer by $LEED/3/$
(zincblende)	÷	0.70 Å. Top layer Ga atoms contract by
	. •	$\sim 0.5$ Å, and there are lateral motions of
		$\sim 0.4$ Å to conserve bond lengths. The
		lateral motions may be reduced by $\sim$
		3/4 to give a better agreement with
		MEIS results without significantly wor-
		sening the LEED fit.
GaAs (110)	(1x1)	As is buckled out from the top layer by $LEED/4/$
(zincblende)		0.69 Å. Top layer Ga atoms contract by
		$\sim 0.5$ Å, and there are lateral motions of
		$\sim$ 0.3 Å to conserve bond lengths.

Substrate	Unit Cell	Structure	Method
GaAs (110) (zincblende)	(1x1)	As is buckled out from the top layer by $0.40\pm0.30$ Å. Top layer Ga atoms contract by $\sim 0.20\pm0.30$ Å, with no lateral motions.	HEIS/5/
GaAs (111) (zincblende) (Ga ter- minated)	(2x2)	One quarter of the top layer Ga atoms are missing, and the remaining atoms are almost co-planar with the first As layer, within 0.20 Å. Ga bonding is $sp^2$ rehybridized, instead of the normal $sp^3$ configuration. There are first bi-layer lat teral motions of ~ 0.2 Å, and some buckling in the third layer to maintain	LEED/6/
GaP (110) (zincblende)	(1x1)	optimum bond-lengths and angles. Surface reconstructed with 27.5° bond angle rotation preserving bond lengths. Top layer buckled with Ga +0.09 Å, As -0.54Å and layer spacing contracted to 1.39 Å. Second layer spacing expanded to 1.93 Å.	LEED/7/

Substrate	Unit Cell	Structure	Method
GaP (111)	(2x2)	One quarter of the top layer Ga atoms.	LEED/6/
(zincblende)		are missing, and the remaining atoms	
(Ga ter-		are almost co-planar with the first P	
minated)		layer. Ga bonding is $sp^2$ rehybridized,	
		instead of the normal $sp^3$ configuration.	÷ .
	1. s. s.	There are lateral motions up to $\sim 2$ Å,	۰.
		and some buckling in the third layer to	
	1 <u>1</u>	maintain optimum bond-lengths and an-	. ·
		gles.	
GaSb (110)	(1x1)	Sb is buckled out from the top layer by	LEED/8,9/
(zincblende)	. · · · ·	$0.77 \pm 0.05$ Å. Top layer Ga atoms con-	
	•	tract by $\sim 0.5$ Å, and there are lateral	
		motions of $\sim$ 0.4 Å to conserve bond	
		lengths.	
GaSb (110)	(1x1)	Consistent with LEED results (above)	MEIS/10/
(zincblende)		for layer displacements and lateral mo-	•
	, * I	tions.	•
GaSb (110)	(1x1)	Bond-length conserving rotations of	MEIS/11/
(zincblende)		$28.5\pm2.6$ ° bring Sb atoms up, Ga atoms	
		down.	
Ge (100) (di-	(2x1)	The top layer buckles, with one Ge aton	
amond)		moving out by $0.62\pm0.04$ Å and the oth-	-
		er moving in by $0.66\pm0.04$ Å. There are	•
		lateral displacements of $\sim 0.9$ Å in the	
		first layer and $\sim 0.1$ Å in the second	
		layer.	
	2	$\sum_{i=1}^{n-1}   f_i   \leq \frac{1}{2} \sum_{i=1}^{n-1}  f_i   <\frac{1}{2} \sum_{i=1}$	

(continued)

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Substrate	Unit Cell	Structure	Method
InAs (110) (zincblende)	(1x1)	The top layer has As buckled outward by $\sim 0.8$ Å with lateral motions of $\sim 0.6$ Å in the first three layers to conserve	LEED/13/
		bond lengths.	
InAs (110) (zincblende)	(1x1)	Bond-length conserving rotations of $30.0\pm2.4$ ° bring As atoms up, In atoms down.	MEIS/11/
InSb (111) (zincblende)	(2x2)	One quarter of the top-layer In atoms are missing in the "vacancy buckling" model. Top layer is not buckled, in plane Sb atoms expand radially by	X-Ray Diffraction/14/
		$0.45\pm0.04$ Å from their normal positions and In atoms contract radially by $0.23\pm0.05$ ag from their normal positions. No data on layer spacing changes.	
InP (110) (zincblende)	(1x1)	Preliminary results show layer buckling with the P atom buckled out, and lateral and vertical shifts in the top layer $\sim 0.4$ Å. Second and deeper layer shifts were not investigated.	, ,
InP (110) (zincblende)	(1x1)	Top layer buckling with the P atom buckled out by $0.69\pm0.10$ Å, and lateral and vertical shifts in the top layer $\sim 0.4$ Å. The second layer spacing is contract- ed by $0.41\pm0.10$ Å with a slight buckling of $0.07\pm0.10$ Å. Only first layer lateral displacements were investigated.	LEED/16/

Substrate	Unit Cell	Structure Method
Si (100) (di-	(2x1)	Buckled dimer model is best fit to data. MEIS/17/
amond)		Surface atoms dimerize to take up dan-
	· ·	gling bonds, surface buckles for best
		bond angles. There are lateral and verti-
		cal ion-core motions for at least 4 layers
	َلَحَةٍ <b>(</b>	into the bulk crystal. Authors conclude
	· . ·	that $(2x1)$ , $(2x2)$ and $c(4x2)$ buckled di-
· · · · · ·		mer domains may exist on the surface.
Si (100) (di-	(2x1)	LEED analysis considering vertical and LEED/18/
amond)		lateral displacements in the top three
	. *	atomic layers supports a buckled dimer
		model.
Si (111) (di-	(1x1) laser an	n-The first two layers are almost co- LEED/19/
amond)	nealed	planar, instead of the normal 0.78 Å
		separation. The first layer spacing is
		$0.08\pm0.02$ , a contraction of 90%, and the
		second layer spacing is $2.95\pm0.20$ Å, a
. •		25.5% expansion from 2.35 Å.
Si (111) (di-	(2x1)	The top layer is buckled by $0.30\pm0.05$ Å, LEED/20/
amond)		the second layer spacing is $0.70\pm0.05$ , a
,		change of $+2.9\%$ , and the third layer
		spacing is contracted by $3.4\%$ to
		2.27±0.02 from 2.35 Å. There are
	* * * *	second-layer lateral shifts of $\sim 0.12$ Å.
	· · · · · ·	(More recent results favor the " $\pi$ -bonded
		chain'' model, see below.)

Substrate	Unit Cell	Structure	Method
	(2x1)	Analysis of LEED data supports a " $\pi$ -	LEED/21/
amond)		bonded chain" model for the (2x1) recon	-
		struction. Trial geometries based on	
		strain-minimization calculations for the	•
		model, involving vertical motions four	
		layers deep with lateral motions along	
	•.	the long side of the unit cell.	
Si (111) (di-	(2x1)	Best fit to " $\pi$ -bonded chain" model.	MEIS/22/
amond)		This model involves buckling in layers 2	
	• •	to 6 of up to 0.27 Å and small lateral	
		shifts in the first six layers.	•
GaP (110)	(1x1)	Surface reconstructed with 28.0° bond	LEED/7/
(zincblende)	•	angle rotation preserving bond lengths.	
		Top layer buckled with Zn +0.08 Å, S	
		-0.51Å and layer spacing contracted to	
		1.40 Å. Second layer spacing expanded	
		to 1.91 Å.	
ZnSe (110)	(1x1)	Two different models were consistent	LEED/23/
(zincblende)		with LEED data. First; Se is buckled	
		outward by $\sim 0.70$ Å and the second	
		layer spacing is contracted by $\sim 0.60$ Å,	
		with lateral motions of $\sim 0.7$ Å. Second	
		Se buckled out by 0.10 Å and the second	
		layer spacing contracted by 0.09 Å, with	
•		lateral motions of $\sim 0.07$ Å.	

. 155

TABLE VIII (continued)

Substrate	Unit Cell	Structure	Method	
ZnTe (110) (zincblende)		Te is buckled out from the top layer by $0.71\pm0.05$ Å. Top layer Zn atoms contract by $\sim 0.5$ Å, and there are lateral motions of $\sim 0.4$ Å to conserve bond lengths.		
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TABLE XI. Carbon Monoxide, Di-Nitrogen and Nitric Oxide Chemisorption on Metals

(In all the listed structures the CO or NO molecule is believed to adsorb perpendicular to the surface with the oxygen end away from the surface. For CO structures with multiple non-equivalent adsorption sites these are listed on consecutive lines. If the metal layer spacing has been investigated this is listed after the adsorbate information.)

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Substrate Face	Overlayer Ad Unit Cell	•	C-Metal Spacing	C-O Bon Length	
Cu (100)	c(2x2)-CO	top	1.90±0.10	1.13±0.10	LEED/1/
Cu (100)	c(2x2)-CO	o top	$1.92 \pm 0.05$		NEXAFS/2/
Ni (100)	c(2x2)-CO	top	1.72	1.15	LEED/3/
Ni (100)	c(2x2)-CO	top	$1.80\pm0.10$	1.15±0.05	ARXPS/4/
Ni (100)	c(2x2)-CO	top	$1.80\pm0.10$	$1.15 \pm 0.05$	LEED/5/
Ni (100)	c(2x2)-CO	top	$1.70\pm0.10$	$1.13\pm0.10$	LEED/6/
Ni (100)	c(2x2)-CO	top	$1.71\pm0.10$	1.15±0.10	LEED/7/
Ni (100)	c(2x2)-CO	top	$1.80\pm0.04$	1.13	NPD/8/
Ni (111)	(√3x√3)R30°-CO	bridge	$1.27\pm0.05$	$1.13 \pm 0.05$	NPD/8/
Ni (100)	disordered-CO	top	,		NEXAFS/9/
	molecula	r axis⊥to :	surface $\pm 10^{\circ}$	<b>o</b>	
Ni (100)	disordered-NO	top			NEXAFS/9/
	molecula	$r axis \perp to$	surface $\pm 10^{\circ}$	<b>o</b> .	
Ni (100)	disordered-N $_2$	top		,	NEXAFS/9/
	molecula	$r \operatorname{axis} \bot to$	surface $\pm 10$	0	•
Pd (100)	$(2\sqrt{2}x\sqrt{2})$ R45 °-2CO	bridge	$1.36\pm0.10$	$1.15 \pm 0.10$	LEED/10/
• .	· · · · · · · · · · · · · · · · · · ·	top layer	1.945±0.10	+0.4%	
Pd (111)	(√3x√3)R30°-2CO	3-fold fcc	1.29±0.05	$1.15 \pm 0.05$	LEED/11/
Pd (111)	(3x3)-2CO <sup>*</sup>	3-fold fcc	$1.30\pm0.05$	$1.17\pm0.05$	LEED/12/
Pt (111)	c(4x2)-2CO	top	$1.85\pm0.05$	$1.15 \pm 0.10$	LEED/13/
	· · · · · · · · · · · · · · · · · · ·	bridge	$1.55\pm0.05$	$1.15 \pm 0.10$	
				•	

Substrate Face	Overlayer Unit Cell	Adsorption Site	C-Metal L Spacing	C-O Bond Length	Method
		top layer	$2.26 \pm 0.025$	0.0%	
Pt (111)	$(2\sqrt{3}x4)$ rect-4CO	bridge	1.45	1.15	LEED/14/
Rh (111)	(3x3)-2CO <sup>*</sup>	3-fold hep	1.30	1.17	LEED/15/
Rh (111)	$c(2\sqrt{3}x4)$ rect-CO	3-fold fcc	$1.50\pm0.05$	1.21±0.10	LEED/16/
Rh (111)	$c(4x2)-CO^*$	3-fold hcp	$1.30 \pm 0.05$	1.17±0.05	LEED/17/
Rh (111)	$c(4x2)-NO^{\bullet}$	3-fold fcc	$1.30\pm0.05$	1.17±0.05	LEED/17/
Rh (111)	(2x2)-3CO	quasi-top	1.87±0.10	1.15±0.10	LEED/18/
	· .	quasi-top	$1.87 \pm 0.10$	1.15±0.10	
•		bridge	$1.52 \pm 0.10$	1.15±0.10	
Rh (111)	$(\sqrt{3}x\sqrt{3})R30^{\circ}-CC$	) top	1.95±0.10	1.07±0.10	LEED/19/
- · · ·		top layer	2.19±0.10	0.0%	
Ru (0001)	(√3x√3)R30°-CC	) top	$2.00\pm0.10$	1.09±0.10	LEED/20/

\* These structures involve carbon monoxide co-adsorbed with other molecules. See table XII for more details.

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Unit Cell Substrate Structure Method C (111) (1x1)Terminated bulk diamond, no relaxa- LEED/1/ (diamond) tion in layer spacing. C (111)-H (1x1)Hydrogen terminated diamond, sur-MEIS/2/ (diamond) face layer spacing relaxed by -0.05±0.05 Å. C (111)-H (1x1)Hydrogen in (1x1) arrangement. Helium (diamond) Determined to be in top site, asdiffraction/3/ sumed 1.09 Å H-C bond length. Evidence for " $\pi$ -bonded chain reecon- MEIS/2/ C(111) (2x2)struction. (diamond) C (0001) (1x1)Normal graphite layer stacking, first LEED/4/ layer contracted 1.4% to 3.30 Å from (graphite) bulk spacing of 3.35 Å. C (0001)-K intercalated When K is adsorbed on C(0001) it is LEED/5/(graphite) intercalated between layers, changing the carbon stacking sequence from ABAB... to AAAA... and increasing the layer spacing to 5.35 Å from 3.35 Å. C (0001)-Ar incomensurate Ar forms an incomensurate hexago- LEED/6/ (graphite) nal overlayer on graphite  $3.2\pm0.10$  Å

above the graphite surface.

TABLE X. Insulator and other Compound Surface Structures

## TABLE X (continued)

Substrate	Unit Cell	Structure	Method
C (0001)-Kr	(√3x√3)R30°	Kr adsorbs in 6-fold hollow sites on	LEED/7/
(graphite)	: . ·	the graphite basal plane $3.35\pm0.01$ Å	
	、	above the graphite surface. No	
		nearest neighbor sites are occupied.	
		At higher coverages next-nearest	
		neighbor sites are occupied.	
CaO (100)	(1x1)	Top layer contracts by $1.2\%$ to $2.38$	LEED/8/
(rocksalt)		from 2.41 Å. No top-layer buckling.	
CoO (111)	(1x1)	Oxygen termination with fcc stack-	LEED/9/
(rocksalt)		ing, top layer contraction of $17\%$ to	
		1.06 Å from bulk 1.27 Å.	
CoO (100)	(1x1)	Terminated bulk structure, top layer	LEED/10/
(rocksalt)		spacing is $2.85\pm0.08$ Å.	· · ·
MgO (100)	(1x1) ,	Top-layer oxygen buckled out by	LEED/11/
(rocksalt)	2. <sup>1</sup>	$0.04\pm0.05$ , and top layer contracted	,
		by 0.02±0.07 Å. Bulk layer spacing	<b>,</b> ', ', ', ', ', ', ', ', ', ', ', ', ',
		2.10 Å.	
MgO (100)	<b>(1x1)</b> .	Terminated bulk structure, no	LEED/12/
(rocksalt)		change from bulk layer spacing of	
	· · ·	2.10 Å.	×*
MoS <sub>2</sub>	<b>(1x1)</b>	Normal stacking, S-Mo-S termina-	LEED/13/
(0001)		tion, top layer contraction by $5\%$ to	
(layer		1.51 Å from bulk 1.59 Å. No second	
compound)		layer contraction.	
$Na_{2}O(111)$	(1x1)	Oxidation of epitaxial Na(110) on	LEED/14/
(fluorite)		Ni(100) substrate. Determine fluorite	;
ŕ		lattice with Na-O-Na termination.	

TABLE X	(continued	)

Substrate	Unit Cell	Structure	Method
NbSe <sub>2</sub>	(1x1)	Normal layer stacking with Se-Nb-Se	LEED/13/
(0001)		termination, no evidence for relaxa-	
(layer		tion of first two layer spacings.	
compound)	,		
Nil <sub>2</sub> (0001)	(1x1)	Bulk $NiI_2$ is a layer compound with	SEXAFS/15/
		hexagonal metal layers and oc-	•
		tohedral coordination in a cubic unit	
. <i>К</i>		cell. At the surface the bulk Ni-I	
· ·	•	bond length of 2.78 Å decreases by	
	•	$0.036\pm0.010$ Å and the I-I seperation	
	•	of 3.89 Å decreases by -0.48 $\pm$ 0.010.	
NiO (100)	(1x1)	Top layer unbuckled, contracted $2\%$	LEED/16/
(rocksalt)		to 2.04 Å from bulk value of 2.08 Å.	
${ m Sb}_2{ m Te}_2{ m Se}$	(1x1)	This is an elemental layer compound	ARUPS/17/
(0001)		with Te-Sb-Se-Sb-Te stacking. The	
(layer com-	· •	Te-Te interfaces are clevage planes.	
pound)	a	At the surface the bulk Te-Sb layer	
		spacing of 1.733 Å is contracted by $\sim$	· · · · ·
	· · ·	3% to 1.683±0.05 Å.	
TiS <sub>2</sub> (0001)	(1x1)	This is an elemental layer compound	LEED/18/
(layer com-		with Ti-S-Ti stacking. The Ti-Ti in-	
pound)		terfaces are clevage planes. At the	
		surface the bulk Ti-S layer spacing is	
		contracted by $\sim 5\%$ and the first	
		Van der Waal spacing (Ti-S-Ti   Ti-	
		S-Ti) is also contracted by 5%.	

TABLE X (continued)

Substrate	Unit Cell	Structure Method
$TiSe_2$ (0001)	(1x1)	This is an elemental layer compound LEED/18/
(layer com-		with Ti-Se-Ti stacking. The Ti-Ti
pound)	· · · · ·	interfaces are clevage planes. At the
	5 .e	surface the bulk Ti-Se layer spacing
		is expanded by $\sim 5\%$ and the first
		Van der Waal spacing (Ti-Se-Ti
, ,	· · ·	Ti-Se-Ti) is contracted by 5%.
ZnO (0001)	(1x1)	Zn termination, top layer spacing LEED/19/
(wurtzite)		$0.60\pm0.10$ Å, a $25\%$ contraction from
		the bulk value of 0.80 Å.
ZnO (1010)	(1x1)	Oxygen buckled outward by $\sim 0.8$ Å LEED/20/
(wurtzite)	a a chuir an tha gaile.	and Zn contracted by 1.2 Å in the
	ана страна на селото на селото Селото на селото на с Селото на селото на с	first layer. Bulk layer spacing 1.88
	• •	Å.
$ZnO(11\overline{2}0)$	(1x1)	Terminated bulk structure, no evi- LEED/20/
(wurtzite)		dence for reconstruction or relaxa-
		tion in layer spacings.

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TABLE IX. Atomic Adsorption on Semiconductor Surfaces

(Where substrate relaxations or reconstructions have been investigated this information is listed in the table after the adsorbate information.)

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Adsorption System	Overlayer Cell	Adsorbate Site	Layer Spacing	Method
GaAs (110)-Sb	(1x1)	2-fold	note 1	LEED/1/
GaAs (110)-Al	(1x1)	sub surface	note 2	LEED/2/
Ge (111)-Cl	(2x8)	top	$2.07\pm0.03$	SEXAFS/3/
Ge (111)-I	(1x1)	top	$2.50\pm0.04$	SEXAFS/4/
Ge (111)-Br	undetermined	top	$2.10\pm0.04$	X-ray reso-
		an a	i Serie and an	nance/5/
Ge (111)-Te	(2x2)	hcp hollow	$\chi^2$ , $\omega$	SEXAFS/4/
Si (111)-Au	$(\sqrt{3}x\sqrt{3})$	note 3	0.30	ALICISS/6/
Si (111)-Br	undetermined	top	$2.18\pm0.06$	X-ray reso-
	· · ·		ана стана Алана стана стана Алана стана стан	nance/7,8/
Si (111)-Ag	(7x7)	top	0.70±0.04	SEXAFS/9/
Si (111)-Ag	$(2\sqrt{3}x2\sqrt{3})$	subsurface	-0.68±0.15	SEXAFS/9/
	layer 1-2		$1.36\pm0.30$	
	layer 2-3		-0.30	·
Si (111)-Cl	$(\sqrt{19x}\sqrt{19})$	top	1.98±0.04	SEXAFS/3/
Si (111)-Cl	(7x7)	top	$2.03 \pm 0.03$	SEXAFS/3/
Si (111)-I	(7x7)	top	2.44±0.03	SEXAFS/4/
	top layer	+15%	$0.90 \pm 0.05$	n an
Si (111)-NiSi <sub>2</sub>	(1x1)	tetrahedral	note 4	LEED/10/
Si (111)-NiSi <sub>2</sub>	(1x1)	tetrahedral	note 5	MEIS/11/
Si (111)-Se	undetermined	4-fold	1.68	X-ray reso-
· · ·	,			1 nance/12/
Si (111)-Te	(7x7)	2-fold	1.51	SEXAFS/4/

Note 1 -- Sb atoms fill As and Ga type.sites in a slightly buckled (0.10 Å) first layer spaced 2.3 Å above the GaAs surface, with lateral distortions to form a  $sp^3$  bonded chain.

Note 2 -- Aluminum substitutes for sub-surface Ga atoms. For 0.5 monolayers second layer Ga atoms are replaced, for 1.0 monolayers second and third layer Ga atoms are replaced. Above 1.5 monolayers all near surface Ga atoms are replaced by Al, forming an epitaxial AlAs(110) surface. In all cases the first interlayer spacing contracts by  $\sim 0.10$  Å.

Note 3 -- Modified triplet cluster model - Au triplets substituted for Si atoms with a 2.9 Å Au-Au bond length between the triplet Au atoms.

Note 4 -- Structure of NiSi<sub>2</sub>, grown on Si(111) substrate. Forms fluorite structure layer compound Si-Ni-Si with nickel in tetrahedral sites. Silicon layer terminates crystal, with a first-layer contraction of  $\sim 25\%$ .

Note 5 -- Ion scattering investigation of  $NiSi_2$  - bulk Si interface. Determine Si-Ni-Si layer is  $3.06\pm0.08$  Å above the next non-collinear Si atom (the bulk value is 0.77 + 2.35 = 3.12). Of the two possible terminations this most closely matches the bulk silicon structure.

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TABLE XII. Other Molecular Adsorption Structures

System	Structure	Method
Cu (100) HCO <sub>2</sub>	The formate radical is in a plane $\perp$ to the	NEXAFS/1/
lisordered	surface with the two oxygens closest to the	
	surface, and a formate O-C-O bond angle of	
	125° is assumed. The O atoms are slightly	
	off-center above two adjacent 4-fold hollow	
. •	sites. The O atoms are 1.54 Å above the Cu	
	surface and separated by 2.17 Å. The C	
	atom is 2.11 Å above the surface.	
Cu (110) HCO <sub>2</sub>	The formate radical is in a plane $\perp$ to the	NEXAFS/2/
lisordered	surface along the [001] direction. The oxy-	•
	gen atoms are closest to the surface, slightly	•
	off-center from two adjacent bridge sites,	•
• •	1.51 Å above the surface and 2.29 Å apart.	· ·
	The O atom is 2.04 Å above the Cu atom.	
Ni (111) $C_2 H_2$	The acetylene molecules are adsorbed with	LEED/3/
(2x2)	the C-C bond parallel to the surface and the	
	center of the C-C bond is over a bridge site.	
	The C-C bond is perpendicular to the Ni-Ni	
	, bridge. The C-C bond length is 1.50 Å and	
	the carbon atoms are $2.1\pm0.10$ Å above the surface.	
Pd (111)	One benzene and two CO's per unit cell. CO	LEED/4/
C <sub>6</sub> H <sub>6</sub> +2CO	is $\perp$ to the surface, adsorbed 1.30 Å above 3-	
3x3)	fold fcc sites. Benzene is parallel to the sur-	
,	face, centered 2.25 Å over a 3-fold hcp site.	
Pt (111) C <sub>2</sub> H <sub>2</sub>	Acetylene bonded parallel to surface with	NEXAFS/5/
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168

TABLE XII	(continued)	ł
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System	Structure	Method
Pt (111) C <sub>2</sub> H <sub>3</sub>	Ethylidyne (CCH <sub>3</sub> ) bonded $\perp$ to surface	NEXAFS/6/
disordered	with C-C bond 1.47±0.03 Å.	•
$Pt (111) C_2 H_3$	Ethylidyne (CCH <sub>3</sub> ) bonded $\perp$ to surface	NMR/7/
disordered	with C-C bond 1.49±0.02 Å.	
Pt (111) C <sub>2</sub> H <sub>3</sub>	Ethylidyne (CCH <sub>3</sub> ) bonded $\perp$ to surface in	LEED/8/
(2x2)	3-fold fcc sites, C-C bond $1.50\pm0.05$ Å	
	and C-surface $\perp$ distance $1.20\pm0.05$ Å.	,
Pt (111) C <sub>2</sub> H <sub>4</sub>	Ethylene bonded parallel to surface with C-	NEXAFS/5/
disordered	C bond length $1.49\pm0.03$ Å.	
Pt (111) 2C <sub>6</sub> H <sub>6</sub>	Benzene ring parallel to surface, C-C bond	NEXAFS/9/
disordered	length 1.40±0.02 Å.	··· .
Pt (111)	Benzene ring parallel to surface over bridge	LEED/10/
2C <sub>6</sub> H <sub>6</sub> +4CO	sites, 2.10 Å above surface, with two ben-	
$(2\sqrt{3}x4)$ rect	zenes and four CO's per unit cell. CO also	
	over bridge sites, 1.45 Å above the metal	
	surface. Benzene ring is expanded with	
• •	small in-plane distortions consistent with lo-	1. j
	cal symmetry.	
Rh (111) C <sub>2</sub> H <sub>3</sub>	Ethylidyne $(CCH_3)$ is adsorbed with the C-C	LEED/11/
(2x2)	axis $\perp$ to the surface with a 1.45 $\pm$ 0.10 Å	
	bond length. The terminal carbon atom is	-
	$1.31\pm0.10$ Å above a 3-fold hcp hollow site.	

System	Structure	Method
Rh (111)	Ethylidyne (CCH <sub>3</sub> ) is adsorbed in 3-fold fcc	LEED/12/
C <sub>2</sub> H <sub>3</sub> +CO ·	sites with a 1.30 $\pm$ 0.05 Å metal-terminal car-	
c(4x2)	bon distance. The C-C axis is $\perp$ to the sur-	
	face with a $1.45\pm0.05$ Å bond length. CO	
	molecules are adsorbed $\perp$ to the surface in 3-	
	fold hcp sites, carbon atom down, with a	
	carbon-metal bond length of $1.30\pm0.05$ Å	
	and a C-O bond length of $1.17\pm0.05$ Å.	·
Rh (111)	Ethylidyne (CCH <sub>3</sub> ) is adsorbed in 3-fold hcp	LEED/12/
C <sub>2</sub> H <sub>3</sub> +NO	sites with a $1.30{\pm}0.05$ Å metal-terminal car-	
c(4x2)	bon distance. The C-C axis is $\perp$ to the sur-	
,	face with a $1.45\pm0.05$ Å bond length. NO	i.
	molecules are adsorbed $\perp$ to the surface in 3-	
	fold hcp sites, nitrogen atom down, with a	
	nitrogen-metal bond length of $1.30\pm0.05$ Å	
	and a N-O bond length of $1.17\pm0.05$ Å.	
Rh (111)	One benzene and two CO's per unit cell. CO	LEED/13/
$C_6H_6+2CO$	is $\perp$ to the surface, adsorbed 1.30 Å above 3-	
(3x3)	fold hcp sites. Benzene is parallel to the sur-	•
	face, centered 2.20 Å over a 3-fold hcp site.	
	Slight in-plane Kekulé distortion of the ben- zene molecule.	
		· · ·

(continued)

System	Structure	Method	
Rh (111)	Benzene is coadsorbed with CO, each with	LEED/14/	
C <sub>6</sub> H <sub>6</sub> +CO	one molecule per unit cell, both centered	$\{ (x_i)_{i \in I} : i \in I\}$	
$c(2\sqrt{3}x4)$ rect	over 3-fold hcp sites, benzene is parallel to	19 - A. K.	
	and $2.25\pm0.05$ Å above the surface. CO is $\perp$	r 1	
	to the surface and the metal-carbon spacing	n <sub>B</sub> ay	
	is 1.50±0.05 Å. The benzene molecule has	en andre in de	
е. 1917 г. – С	an in-plane Kekulé distortion, with alternat-	. ÷	
×	ing long and short bonds.	ina Ang ang ang ang ang ang ang ang ang ang a	

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#### FUTURE NEEDS AND DIRECTIONS OF SURFACE STUDIES

6.

It is our hope that this review conveys the rapid developments in surface structural chemistry during the past decade. We have attempted to describe the various techniques that are employed and the types of structural information that has been obtained from experiment.

The theories of surface structure and bonding have been reviewed. It should be clear to the reader that surface structural chemistry is indeed a frontier area for both theorists and experimental researchers. From an experimentalists viewpoint the data base of atomic and molecular surface structures is very small at present. Most investigations have been carried out on flat, low Miller index surfaces of monatomic solids, either clean or with atomic or small molecules as adsorbates.

The structure of clean surfaces of polyatomic solids (alloys, halides, oxides, sulfides, etc.) should be explored along with molecular solid surfaces (organic systems). More open, rough surfaces with high Miller indices should be investigated, including the structure of atoms and molecules bonded to steps and kinks on surfaces. Such sites are known to be key for some important surface chemical processes, but little is known of their structure.

Molecular adsorbates of increasing size should be a fertile area of research. Such research could lead to the study of biological surfaces. The surface structure at solid-gas, solid-liquid, and solid-solid interfaces should be explored and compared with the results for the solid-vacuum interface. Structural properties of thin films, electrodes, and composite materials can be obtained in this way.

Time resolved surface structure analysis can be employed for studies of order-order and order-disorder surface phase transitions, growth, and evaporation. Surface structures and their alterations could then be explored under extreme conditions of high temperature and irradiation by photons or particles.

Once bond distances and angles become available for a large number of systems with diverse chemistry, correlation should lead to a deeper understanding of the nature of the surface chemical bond.

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